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THE HALL EFFECT IN FERROMAGNETIC METALS AND SEMICONDUCTORS

By
Jerome M. Lavine

March 10, 1956
Technical Report No. 225

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Harvard University
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Technical Report
on
The Hall Effect in
Ferromagnetic Metals and Semiconductors
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Jerome M. Lavine

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# Table of Contents

<table>
<thead>
<tr>
<th>Section</th>
<th>Page</th>
</tr>
</thead>
<tbody>
<tr>
<td>Abstract</td>
<td>i</td>
</tr>
<tr>
<td>I. Introduction</td>
<td>1</td>
</tr>
<tr>
<td>II. The Measurement Problem</td>
<td>8</td>
</tr>
<tr>
<td>III. The Experimental Apparatus and Techniques</td>
<td>27</td>
</tr>
<tr>
<td>IV. The Ordinary Hall Measurements on Grade A Ni and 70 Ni-30 Cu</td>
<td>38</td>
</tr>
<tr>
<td>V. The Ordinary Hall Measurements on the Ferrites</td>
<td>49</td>
</tr>
<tr>
<td>VI. The Extraordinary Hall Measurements on Ni, Ni Alloys, and the Ferrites</td>
<td>59</td>
</tr>
</tbody>
</table>

Appendix A

Discussion of Errors                                               | 72   |

Appendix B

The Change of Magnetization above Technical Saturation in \( \text{Fe}_3\text{O}_4 \) and \( (\text{NiO})_{0.75}(\text{FeO})_{0.25}(\text{Fe}_2\text{O}_3) \) | 81   |

References                                                          | 88   |
Abstract

Hall measurements on Ni were made between room temperature and 568°C using an a-c measurement technique. The ordinary Hall coefficient of Ni is roughly constant between room temperature and 300°C. The data suggest that the extraordinary Hall effect persists into the paramagnetic region. The strong temperature dependence of the observed effect does not exhibit a temperature dependence similar to the susceptibility and hence there is ambiguity in the determination of the ordinary Hall coefficient above the Curie temperature. Hall measurements on a 70 Ni - 30 Cu alloy also suggest the presence of the extraordinary Hall effect above the Curie temperature, but in this alloy, the observed effect possesses a 1/T-0 temperature dependence. The ordinary Hall coefficient of the 70 Ni - 30 Cu alloy is smaller in absolute value above the Curie temperature than at liquid air temperature. These data are discussed using Pugh’s two-band and four-band models.

Hall measurements at room temperature were made on a synthetic crystal of Fe₃O₄ and on a synthetic single crystal of (Ni0.75(Fe0.25(Fe₂O₃)). The ordinary Hall measurement on Fe₃O₄ suggests that the number of conduction electrons at room temperature is large, in rough agreement with Verwey’s hypothesis. The ordinary Hall coefficient of (Ni0.75(Fe0.25(Fe₂O₃) also suggests a large carrier concentration. The conductivities of (Ni0.75(Fe0.25(Fe₂O₃) and of a synthetic single crystal of (Ni0.56(Zn0.14(Fe0.30(Fe₂O₃) are compared with the conductivity of Fe₃O₄ employing a simple model for the mobility and associating the activation energy obtained from resistivity data with the number of conduction electrons. The observed data are in good agreement with the simple model.

Extraordinary Hall measurements were made on Grade A Ni (99.4 Ni), 499 Alloy (99.9 Ni), and R-63 Alloy (95 Ni, 4 Mn, 1 Si) between liquid air temperature and their Curie temperatures, and on the 80 per cent Ni-Fe alloys, Superalloy, Mumetal, and Carpenter Hymu 80 between liquid air temperature and room temperature. The extraordinary Hall coefficients of these materials do not generally exhibit the resistivity dependence predicted by Karplus-Luttinger theory, but they do suggest that the essential features of the theory are probably correct. The extraordinary Hall coefficients of
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Fe₃O₄ and (Ni0)₀.₇₅(Fe0)₀.₂₅(Fe₂O₃) between -100°C and their Curie temperatures indicate no resistivity dependence, and their magnitude, temperature dependence, and sign reversal have not been explained.

Auxiliary measurements of resistivity as a function of temperature, for all samples, and the thermoelectric power of Fe₃O₄ against Cu are also reported.
THE HALL EFFECT IN
FERROMAGNETIC METALS AND SEMICONDUCTORS

by
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I.
INTRODUCTION

1. 1 The Hall Effect in Ferromagnetics

The Hall effect in the ferromagnetic metals Fe, Co, and Ni was first investigated by E. H. Hall [1] in 1881. In 1885 measurements in the temperature region near room temperature were made by Hall [2,3] and over a wider range of temperature by Clough and Hall [4] in 1892. In 1893 Kundt [5] performed measurements on Fe, Co, and Ni which indicated that the Hall effect in ferromagnetics was proportional to the intensity of magnetization (M) rather than to the induction (B). In 1910, A. W. Smith [6] made Hall measurements on Fe, Co, and Ni over a wide range of temperature and with relatively high fields, and correlated the temperature dependence of the saturation effect in the Hall voltage with the temperature dependence of the magnetization. In 1929, Smith and Sears [7] found it possible to separate the Hall voltage in Permalloy into two components, one of which they attributed to the intensity of magnetization, and the other to the H-field in the material. In 1930 Pugh [8] and in 1932 Pugh and Lippert [9] showed conclusively that the Hall voltage was a linear single-valued function of the intensity of magnetization at low fields, in K. S. magnet steel, in hardened high-carbon steel, in electrolytic Fe, in a 50Fe-50Co alloy, and in a 70Fe-30Ni alloy. Following the suggestion of Smith and Sears [7], Pugh [8] proposed that the Hall voltage for ferromagnetics, normalized with respect to geometry and current, be written
where \( e_H \) is the normalized Hall voltage, 
\( M \) is the intensity of magnetization, 
\( H \) is the field in the material, 
\( R_0, R_1 \) are constants.

In 1950, Pugh, Rostoker, and Schindler [10] made careful high-field measurements on Ni near room temperature which suggested that \( R_0 \) had the magnitude of the ordinary Hall coefficient of a metal. Their analysis of Smith's [6] data on Ni indicated that \( R_0 \) was relatively temperature-independent, supporting their suggestion that \( R_0 \) was the ordinary Hall coefficient. They called the coefficient of \( M \) the extraordinary Hall coefficient and further suggested that Eq. (1.1) be written

\[
e_H = R_0(H + 4\pi aM), \tag{1.2}
\]

where \( \alpha = \frac{R_1}{4\pi R^0} \). They characterized \( h = H + 4\pi aM \) as the effective uniform field acting on the conduction electrons.

The speculation of an effective field acting on the conduction electrons required a value of \( \alpha \approx 10 \) at room temperature to account for the extraordinary Hall effect in Ni. Analysis of Smith's [6] data by Pugh, Rostoker, and Schindler [10] indicated that \( \alpha \) in Ni increased from a value near 2 at liquid air temperature to a value near 60 at the Curie temperature. The temperature dependence of \( \alpha \) in Ni was confirmed by Jan [11] who also showed that \( \alpha \) in Fe increased from a value near \( 1/2 \) at liquid air temperature to a value near 500 at \( 800^\circ \text{K} \). Thus, the effective field formulation indicated that at room temperature a field 10 times larger than the B-field in Ni and 25 times larger than the B-field in Fe was present at the location of the conduction electrons, and, further, that this field increased with increasing temperature. On the basis of known magnetic interactions, neither the magnitude nor the temperature dependence of \( \alpha \) could be explained.

On the other hand, the recognition that \( R_0 \) could be derived from precise high-field measurements seemed to afford an opportunity to examine the 3d and 4s band electrons of the fourth period transition elements. From saturation magnetization measurements and from considerations that the 3d
electrons provide the major contribution to the saturation magnetization, it had been previously concluded that there are approximately 0.6 holes/atom in the 3d band of Ni, and an equal number of electrons/atom in the 4s band. Since specific heat data indicate that the 0.6 3d holes/atom have a relatively large effective mass, one would expect a negligibly small contribution to the conductivity, and hence to the Hall coefficient, from these carriers. The value of $R_o$ deduced by Pugh [10] required that the 3d holes contribute about one third of the conductivity of Ni. This large contribution from the 3d holes was not in accord with the expected result and cast some doubt on the information derived from the ordinary Hall measurements.

In 1954, Karplus and Luttinger [13] presented a theory which explained the unusually large magnitude and strong temperature dependence of the extraordinary Hall coefficient, $R_1$, as the effect of the spin-orbit interaction of polarized conduction electrons. They showed that the interband matrix elements of the applied electric potential energy combined with the spin-orbit perturbation to give a current perpendicular to both the applied electric field and the magnetization. This current, $J_y$, is related to the magnetization $M_z$, and the applied electric field $E_x$ in the following way:

$$J_y = r M_z E_x,$$

where $r$ should depend only weakly upon temperature and impurity content. The strong temperature dependence of the experimentally observed effect comes about as a consequence of the manner in which the effect is measured. Since

$$\rho J_y = E_y,$$  \hspace{1cm} (1.4)

provided that we make the measurement with a high-impedance device, then,

$$E_y = \rho r M_z E_x = \rho^2 r M_z J_x.$$ \hspace{1cm} (1.5)

Therefore, the observed voltage is proportional to the square of the resistivity simply as a consequence of the measurement of a current-dependent field instead of a field-dependent current.

We must still take into account the fact that the conduction electrons see a field which is larger than the H-field in the material. Wannier [14]
has shown that this field is of the form

\[ H_{\text{effective}} = H + 2\pi(1 + p)M, \quad (1.6) \]

where \( p \) is the probability of coincidence of a conduction electron with the magnetic dipoles contributing to the magnetization. Wannier has estimated that \( p \ll 1 \) for most electrons in a metal. Equation (1.1) now becomes

\[ e_H = R_0[H + 2\pi(1 + p)M] + R_1 M, \quad (1.7) \]

where

\[ R_1' = \rho^2 x \]

and

\[ R_1 = 2\pi(1 + p)R_0 + R_1' \quad (1.8) \]

Analysis of Jan's [11] data, ignoring the \( 2\pi(1 + p)R_0 \) term which is significant only at low temperatures, indicated that the Karplus-Luttinger theory did indeed account for the order of magnitude of \( R_1 \) in both Fe and Ni, and did provide a mechanism for the observed temperature dependence. \( R_1 \) in Fe was proportional to \( \rho^{1.94} \), in good agreement with Eq. (1.8). However, \( R_1 \) in Ni was proportional to \( \rho^{1.40} \).

### 1.2 The Ferrites

Over 2500 years ago the ancient Greeks observed the properties of specimens of magnetite found in Magnesia, a district in Thessaly. Available in the form of natural single crystals, \( \text{Fe}_3\text{O}_4 \) has played an important part in the experimental investigations of the phenomenon of ferromagnetism. In 1909, Hilpert [15] showed that a series of ferromagnetic ferrites could be obtained by replacing the FeO in \( \text{FeO} \text{Fe}_2\text{O}_3 \) with other bivalent metal oxides.

The ferrites crystallize in the spinel structure (MgOAl\(_2\)O\(_3\)). The unit cell of the structure contains 32 oxygen ions in an almost cubic close-packed arrangement, plus 24 metallic ions, 8 bivalent and 16 trivalent, distributed on two types of sites. In the normal spinel structure (nonmagnetic) the 8 bivalent ions occupy 8 tetrahedral sites and the 16 trivalent ions occupy 16 octahedral sites. In the inverse spinel structure (magnetic) the 8 bivalent ions plus 8 of the 16 trivalent ions are distributed at random over the 16 occupied octahedral sites. The remaining 8 trivalent ions occupy 8 tetrahedral sites.
The value of the saturation magnetization of Fe$_3$O$_4$ corresponds to four Bohr magnetons per Fe$_3$O$_4$ group. If all of the iron ions contribute to the magnetization, we would expect 14 Bohr magnetons, 4 from the bivalent (ferrous) and 5 each from the trivalent (ferric) ions. This phenomenon has been explained by Néel [16] on the basis of a negative exchange coupling between the ions in the octahedral and in the tetrahedral sites. This exchange coupling results in an antiparallel alignment of the spins, and has been confirmed by neutron diffraction studies [17]. Thus, only the bivalent ions contribute to the net magnetization. This type of behavior, observed in all the inverted spinels, has been called ferrimagnetic by Néel.

The ferrites possess a negative temperature coefficient of resistivity, and hence they are classified as semiconductors. Fe$_3$O$_4$ has the lowest room temperature resistivity (10$^{-2}$ ohm-cm), and a behavior not characteristic of the other ferrites. In particular, at -153.8°C, Fe$_3$O$_4$ goes through a transition causing marked changes in its physical characteristics [18]. In the case of stoichiometric Fe$_3$O$_4$, the conductivity increases by a factor of 100 in passing through the transition. Verwey [19] has proposed that the high conductivity of Fe$_3$O$_4$ above the transition is due to the free exchange of electrons between equivalent ions with different valence in the octahedral sites. The inverted spinel structure of Fe$_3$O$_4$ has one Fe$^{2+}$ and one Fe$^{3+}$ ion per Fe$_3$O$_4$ group located in octahedral sites. This may be alternatively described as two Fe$^{3+}$ ions plus one electron. Since all occupied octahedral sites are equivalent in the absence of any order, Verwey has proposed that these extra electrons are distributed at random on the Fe$^{3+}$ ions in the octahedral sites. This random distribution is then connected with a continuous interchange of the extra electrons of the Fe$^{2+}$ ions.

Verwey [20] has further proposed that the low temperature transition in Fe$_3$O$_4$ is due to the ordering of ferrous and ferric ions in the octahedral sites resulting in a reduction of the free exchange of electrons and hence in a reduced conductivity. Verwey has also postulated that the effect of ordering would be to change the crystal symmetry and produce an anisotropy in the conductivity. This has been observed by Calhoun [18].
Because of their unusual electric and magnetic behavior, the ferrites in general and magnetite in particular have been the subject of many physical investigations through the years. More recently, the usefulness of the ferrites in electronic technology has initiated extensive studies of their properties [21, 22, 23].

1.3 The Purpose of the Experiment

At the time this research was undertaken, it seemed desirable to test the effective field formulation in a class of materials (ferrites) in which the density of conduction electrons, and hence \( R_0 \), varied strongly with temperature. With the presentation of the Karplus-Luttinger theory, it became even more desirable to test the basic hypothesis of a \( \rho^2 \) dependence of \( R_1 \) in these materials, especially in \( \text{Fe}_3\text{O}_4 \), which displayed a 100-fold change of resistivity at the transition temperature.

The mechanism proposed by Verwey to explain the room temperature conductivity of \( \text{Fe}_3\text{O}_4 \) suggests that approximately one electron per \( \text{Fe}_3\text{O}_4 \) group contributes to the current. This then implies that the number of conduction electrons in \( \text{Fe}_3\text{O}_4 \) is very nearly equal to the number of electrons in a metal, while the conductivity is three orders of magnitude smaller. An ordinary \( R_0 \) Hall measurement, verifying the high carrier concentration, could then attribute the low conductivity to a low electron mobility. Furthermore, measurements made on ferrites in which other bivalent metal ions were substituted for some of the \( \text{Fe}^{2+} \) ions in octahedral sites might yield additional information about the Verwey model and the conductivity of the ferrites. For example, if one expects that electrons will exchange only between octahedral ions belonging to \( \text{Fe}_3\text{O}_4 \) molecules, then in a material such as \( (\text{NiO})_{0.75}(\text{FeO})_{0.25}(\text{Fe}_2\text{O}_3) \) one would expect approximately one quarter the carrier concentration. Thus, it seemed desirable to make ordinary Hall measurements on this material as well.

The ordinary Hall measurement on Ni near room temperature made by Pugh [10] and his extrapolations from the old temperature data of Smith pointed out the desirability of repeating the room temperature \( R_0 \) data on Ni and extending the observation over a range of temperature. These measurements were carried out to temperatures above the Curie temperature and led
to an investigation of $R_o$ both above and below the Curie temperature in the 70 Ni - 30 Cu alloy.

The deviation of $R_1$ from a $\rho^2$-dependence in Ni indicated that the mechanism provided by the Karplus-Luttinger theory did not accurately describe the effect in Ni. Since Jan's was the only temperature data taken with a simultaneous measurement of resistivity, it seemed worth while to repeat the $R_1$ measurement on Ni. The results of the measurement on Grade A Ni differed somewhat from those of Jan[11] and led to an investigation of the extraordinary Hall effect in Ni with varying impurity concentrations and in some Ni-Fe alloys.
II.

THE MEASUREMENT PROBLEM

2.1 The Experimental Arrangement

If we denote by $I$, the total current in the x direction flowing through the sample (Figure 2-1) of thickness $t$, and $H$, the magnetic field in the z direction, normal to the plane of the current and the Hall leads, then the Hall voltage for a non-magnetic metal observed in the y direction is given by

$$V_H = R_o H \frac{I}{t} \quad (2.1)$$

where $V_H$ is in units of practical volts, $H$ is in oersteds, $I$ is in amperes, and $t$ is in cm.

In the case of ferromagnetics, the Hall voltage is composed of two parts; one part is due to $R_1 M$, which we call the extraordinary Hall voltage, and superposed on this is a much smaller voltage due to $R_o H$ which we call the ordinary Hall voltage. We propose to measure this smaller voltage in the region of $H$ where $M$ is a constant, as suggested by Pugh [10]. Thus for ferromagnetics,

$$V_H = (R_o H + R_1 M) \frac{I}{t} \quad (2.2)$$

and if we differentiate this expression with respect to $H$, above technical saturation where $M$ is constant we obtain

$$\Delta V_H = R_o \Delta H \frac{I}{t} \quad (2.3)$$

where $\Delta V_H$ is the increment of Hall voltage due to the change of field, $\Delta H$.

Technical saturation is obtained at a value of applied field determined by both the magnetization of the material and the demagnetizing factor of the shape of the sample. Technical saturation is achieved in thin strips of Ni at an applied field of the order of 6500 oersteds, and in the cylindrical sample of $\text{Fe}_3\text{O}_4$ at an applied field of the order of 3000 oersteds. Therefore, in the case of ferromagnetics we must work at relatively high fields.

We are then concerned with the magnitude of the voltage measured for
MAGNETIC FIELD IN THE Z DIRECTION

\( H_z \)

FIG. 2-1 A BLOCK DIAGRAM OF THE EXPERIMENTAL HALL CIRCUIT
fields readily obtained in the laboratory. We compare the voltage observed in Ni with that observed in Fe$_3$O$_4$ for values of $\Delta H = 5000$ oersteds above technical saturation. In the case of Ni, $R_o \approx -6 \times 10^{-13}$ volt-cm/amp-oersted.$^1$ I = 1 amp., and $t = 1.2 \times 10^{-2}$ cm, we obtain

$$\Delta V_H \approx \frac{(6 \times 10^{-13})(5 \times 10^3)(1)}{1.2 \times 10^{-2}} \approx 2.5 \times 10^{-7} \text{ volts} \quad (2.4)$$

In the case of Fe$_3$O$_4$, $t = 0.5$ cm, with a current limited to 300 ma for reasons explained below, and $R_o \approx -1.8 \times 10^{-11}$ volt-cm/amp-oersted, we obtain

$$\Delta V_H \approx \frac{(1.8 \times 10^{-11})(5 \times 10^3)(3 \times 10^{-1})}{5 \times 10^{-1}} \approx 5 \times 10^{-8} \text{ volts} \quad (2.5)$$

Thus, we note that the determination of the ordinary Hall coefficient in these materials requires the measurement of relatively small voltages. Moreover, these small voltages must be measured in the presence of large voltages. We have already pointed out the existence of the large extraordinary Hall voltage. In addition, due to the unavoidable asymmetry in the positioning of the probes, we have a voltage present even in the absence of a magnetic field and even with the sample in a demagnetized state. This voltage is due to the positioning of the Hall probes on different equipotential lines, and can be many times larger than the ordinary Hall voltage. Voltages also occur across the Hall probes due to unavoidable thermal gradients in the sample. These voltages are field-and temperature-dependent and impose certain requirements upon the system used to make the ordinary Hall measurement. In the following sections we discuss these effects in greater detail, and describe the methods of eliminating or overcoming the difficulties they present.

2.2 The Interfering Effects

(A) The Other Transverse Effects

Sommerfeld and Frank [24] have given an explanation of the galvanomagnetic and thermomagnetic effects in metals. Using the Boltzmann equation and the free electron theory of metals, they have discussed two types of effects; (1) isothermal effects subject to the condition that the
the temperature in the y direction (perpendicular to the primary current and magnetic field) is constant, i.e., \( \frac{\partial T}{\partial y} = 0 \), and (2) adiabatic effects in which no heat is allowed to flow in the y direction, i.e., \( w_y = 0 \), where \( w_y \) is the y-directed thermal current. The equations describing the electrical and thermal current densities, due to Sommerfeld and Frank, have recently been altered by Johnson and Shipley [25] to include the lattice contribution to the thermal conductivity. The equations below describe the electrical and thermal current densities.

\[
\begin{align*}
    j_x &= L_{11} E_x + L_{12} H_z E_y + L_{13} \frac{\partial T}{\partial x} + L_{14} H_z \frac{\partial T}{\partial y} \\
    j_y &= -L_{12} H_z E_x + L_{11} E_y - L_{14} H_z \frac{\partial T}{\partial x} + L_{13} \frac{\partial T}{\partial y} \\
    w_x &= L_{31} E_x + L_{32} H_z E_y - (L_{33} + K_L) \frac{\partial T}{\partial x} + L_{34} H_z \frac{\partial T}{\partial y} \\
    w_y &= -L_{32} H_z E_x + L_{31} E_y - L_{34} H_z \frac{\partial T}{\partial x} - (L_{33} + K_L) \frac{\partial T}{\partial y}
\end{align*}
\]

where \( j_x, j_y \) are electric current densities \\
\( w_x, w_y \) are thermal current densities \\
\( \frac{\partial T}{\partial x}, \frac{\partial T}{\partial y} \) are temperature gradients \\
\( E_x, E_y \) are electric fields \\
\( H_z \) is the magnetic field \\
\( K_L \) is the lattice contribution to the total thermal conductivity and the \( L_{ij} \) are integrals (involving products of the electron velocity, mean free path, electron distribution function, and derivatives over the volume of momentum space and) which need not be known exactly for the purpose of the following argument. They are, in general, different from zero.

The four common transverse effects may now be defined by means of Eqs. (2.6) to (2.9) plus the appropriate conditions.

Isothermal effects:

(1) The Hall effect is defined as

\[
E_y = R_0 j_x H_z
\]

subject to the conditions \( j_y = \frac{\partial T}{\partial x} = \frac{\partial T}{\partial y} = 0 \).

(2) The Nernst effect is defined as

\[
E_y = Q H_z w_x
\]
subject to the conditions $j_x = j_y = \frac{\partial T}{\partial y} = 0$.

Adiabatic effects:

(3) The Ettingshausen effect is defined as

$$\frac{\partial T}{\partial y} = PH j_x$$

subject to the condition $w_y = i = \frac{\partial T}{\partial x} = 0$.

(4) The Righi-Leduc effect is defined as

$$\frac{\partial T}{\partial y} = SH w_x$$

subject to the condition $j_x = j_y = w_y = 0$.

Since we are primarily concerned with the measurement of the isothermal Hall effect, and since introduction of the adiabatic Hall and Nernst effects does not amplify the following argument, they are not considered here.

If we insert the conditions for the Hall effect, i.e., $\frac{\partial T}{\partial x} = \frac{\partial T}{\partial y} = j_y = 0$ into Eqs. (2.6) and (2.7) we obtain

$$j_x = L_{11} E_x + L_{12} H z E_y$$

(2.14)

$$0 = -L_{12} H z E_x + L_{11} E_y$$

(2.15)

whence to the first order in $H_z$

$$E_y = \begin{vmatrix} L_{11} & j_x \\ -L_{12} H z & 0 \\ L_{11} & L_{12} H z \\ -L_{12} H z & L_{11} \end{vmatrix} = \frac{L_{12} H z}{L_{11}^2} j_x = R o j_x H z$$

(2.16)

In the case of metal measurements, the conditions $\frac{\partial T}{\partial x} = \frac{\partial T}{\partial y} = 0$ may be fulfilled by immersing the sample in a temperature bath. Thus, contributions to $\frac{\partial T}{\partial x}$ and $\frac{\partial T}{\partial y}$ from contact resistances and Peltier heat can be excluded by virtue of the high thermal conductivity of metals and the thermal capacity of the bath. However, where the sample cannot be immersed in a temperature bath, and especially in the case of semiconductors where large $\frac{\partial T}{\partial x}$ can be generated due to unequal resistances at the current contacts and to large Peltier heat, the isothermal conditions of the Hall measurement are not fulfilled.
In such cases Eqs. (2.6) and (2.7) must be solved subject only to the condition \( j_y = 0 \), and \( \frac{\partial T}{\partial x}, \frac{\partial T}{\partial y} \) must be known. An examination of the solution of the above set of equations subject to these conditions shows that:

1. \( E_y \neq R_0 j_x H_z \) and the effects superposed are not directly relatable to the transverse effects defined above, as is usually stated in the literature.

2. The Hall field can be separated out in such cases by suitable combinations of electric \((E_x)\) and magnetic field reversals provided that \( \frac{\partial T}{\partial x} \) and \( \frac{\partial T}{\partial y} \) remain constant during the field reversal. The Peltier and Thomson effects [26] usually exclude this possibility.

3. If the electric field \( E_x \) is made to alternate with frequency \( f_0 \), while \( H_z \) is kept fixed, then even with the conditions \( \frac{\partial T}{\partial x} \neq 0, \frac{\partial T}{\partial y} \neq 0 \) the Hall field may be separated out by a suitable filtering device which is tuned to the frequency \( f_0 \). While the effects due to \( \frac{\partial T}{\partial x} \) and \( \frac{\partial T}{\partial y} \) will still be present, they occur at zero frequency.

4. If the magnetic field \( H_z \) is made to alternate with frequency \( f_1 \), while \( E_x \) is kept fixed, then \( E_y \neq R_0 j_x H_z \) as may be seen by examination of Eqs. (2.6) and (2.7).

In order to estimate the magnitude of the deviation of the field \( E_y \) from the Hall field in the case where \( \frac{\partial T}{\partial x} \neq 0, \frac{\partial T}{\partial y} \neq 0 \), the \( L_{ij} \) must be known. In principle, they cannot be obtained by measurement of the transverse effects, nor can they be calculated exactly. We may speculate upon the order of magnitude of the deviation by supposing that we do have superposed on the Hall field, fields due to the other transverse effects. In the case of ferromagnetic metals, even this approximation is denied, since no high-field measurements of these effects have been made. In the ferrites investigated in this research, the Hall voltage was of the same order of magnitude as in metals, and nothing was known of the other transverse effects. However, with a thermo-electric power of the order of 40 micro-volts/\( ^\circ C \), a transverse temperature gradient of \( 10^{-3} ^\circ C \) would be sufficient to totally obscure the Hall voltage in the \( Fe_{3}O_{4} \) sample. Therefore, it is necessary to insure that \( \frac{\partial T}{\partial x} = \frac{\partial T}{\partial y} = 0 \), or to use an alternating \( E_x \) to make the Hall measurement in this material.

(B) The Magneto-resistance Effect

The second-order change of resistance with magnetic field is usually
small in most metals and semiconductors. However, in ferromagnetics, it is a complicated function of $M$ and $H$ and can be several tenths of a percent per kilogauss in the region above technical saturation. Due to the unavoidable asymmetry in the position of the Hall probes, a magneto-resistance voltage equal to or greater than the Hall voltage can be generated in ferromagnetics.

For example, in a Ni sample with thickness $t = 0.005''$, width $w = 0.750''$, $\rho \approx 10^{-5}$ ohm-cm., the uncertainty in the alignment of the soldered Hall probes can be as large as $0.010''$. The IR drop between probes is given by

$$\text{IR} = I\rho \frac{\Delta l}{w \cdot t}$$

where $\Delta l$ is the uncertainty in the probe alignment. For a current of 1 ampere,

$$\text{IR} \approx \frac{(1)(10^{-5})(10^{-2})}{(0.75)(5 \times 10^{-3})} \approx 10^{-5} \text{ volts}$$

(2.17)

For a field of 5,000 oersteds above saturation Bozorth [12, p. 749] indicates that the change of resistance with magnetic field is

$$\frac{\Delta R}{\rho} \approx 10^{-2}$$

(2.18)

Therefore,

$$\frac{I\Delta R}{\text{IR}} = \frac{\Delta R}{\rho} \approx 10^{-2}$$

(2.19)

where $\Delta R$ is the increase of $R$ due to $H$, and

$$I \Delta R \approx 10^{-7} \text{ volts.}$$

(2.20)

The ordinary Hall voltage for this sample is estimated in Eq. (2.4) to be

$$\Delta V_H \approx 2.5 \times 10^{-7} \text{ volts.}$$

(2.21)

Therefore,

$$\frac{\Delta V_H}{I\Delta R} \approx \frac{2.5 \times 10^{-7}}{10^{-7}} \approx 2.5$$

(2.22)

In the case of $\text{Fe}_3\text{O}_4$, the measurement was made on a cylindrical sample, $d = 0.250''$. Since $\rho \approx 10^{-2}$ ohm-cm., care was taken in the probe alignment to minimize the IR drop. Nevertheless, $\Delta l$ was probably not much less than $0.005''$. Therefore, the IR drop between the probes for a current of 300 ma. is
(C) The Extraordinary Effect

The ordinary Hall voltage is superposed on the extraordinary voltage as given by the expression for the normalized Hall voltage in Eq. (1.1)

\[ e_H = R_0 H + R_1 M \] (2.26)

The ratio of the ordinary Hall effect to the extraordinary Hall effect in Ni is given by

\[ \frac{R_0 \Delta H}{R_1 M_s} \approx 6 \times 10^{-2} \] (2.27)

for \( \Delta H = 5000 \) oersteds, at room temperature.

In the case of \( \text{Fe}_3\text{O}_4 \):

\[ \frac{R_0 \Delta H}{R_1 M_s} \approx 6 \times 10^{-3} \] (2.28)

for \( \Delta H = 5000 \) oersteds, at room temperature. Therefore, if the ordinary effect in \( \text{Fe}_3\text{O}_4 \) is to be measured with an accuracy of 1 per cent, the two effects must be separated by a system with a resolution of at least 6 parts in \( 10^5 \).
(D) The Change in Magnetization above Technical Saturation

Having proposed that the Hall voltage in ferromagnetics be written
\[ e_H = R_o H + R_1 M \]  
(2.29)
Pugh, Rostoker, and Schindler [10] then suggested that \( R_o \) be obtained from the slope above technical saturation where \( M \) is constant
\[ \frac{\Delta e_H}{\Delta H} = R_o \]  
(2.30)

where \( \Delta e_H, \Delta H \) denote increments in \( e_H \) and \( H \).

If \( M \) is not exactly constant over the region in which \( R_o \) is measured, we must write Eq. (2.30) as
\[ \frac{\Delta e_H}{\Delta H} = R_o + R_1 \frac{\Delta M}{\Delta H} = R_o (1 + \frac{R_1}{R_o} \frac{\Delta M}{\Delta H}) \]  
(2.31)

Then, in the case of Ni where \( \frac{R_1}{R_o} \approx 2 \times 10^2 \), a change in \( M \) of the order of 1/4 gauss in 5000 oersteds results in a 1 per cent error in \( R_o \). In the case of Fe\(_3\)O\(_4\), where \( \frac{R_1}{R_o} \approx 2 \times 10^3 \), a similar change in \( M \) produces a 10 per cent error.

Although \( M \) displays a saturation effect, the approach to saturation is given by [ref. 12, p. 486]
\[ M = M_s(1 - \frac{a}{H} - \frac{b}{H^2} - \cdots) + K_0 H, \]  
(2.32)

where \( H \) is the field inside the material. The term in \( \frac{a}{H} \) has been explained by Néel [28] as due to nonmagnetic cavities or inclusions in the material. The term in \( \frac{b}{H^2} \) depends upon the magnetic anisotropy and the elastic state of the crystal. In the case of single crystals, the term in \( \frac{b}{H^2} \) is strongly dependent upon orientation of the crystal axes with respect to the magnetic field. In the case of polycrystalline material, the term in \( \frac{b}{H^2} \) has been obtained by Akulov [29] and Gans [30] by averaging over all crystal orientations. The \( K_0 \) term which may be crudely described as the field alignment of temperature-disoriented spins has been calculated by Holstein and Primakoff [31] in good agreement with the values observed for Fe and Ni.

In the case of polycrystalline Ni, typical values of the coefficients are \( a \approx 1/3 \), and \( b = \frac{8K_2}{105M_s} \) provided that the sample is not severely strained,
where $K$ is the first-order anisotropy constant and $K = -59,000$ ergs/cm$^3$ at room temperature. Thus, fields of the order of 1000 oersteds are required to eliminate any appreciable changes in $M$ over the region in which $R_o$ is measured. This means that in the case of Ni sheet, where the demagnetizing factor is very nearly $4\pi$, applied fields greater than 7000 oersteds must be used to measure $R_o$. In the case of Ni, we still have a small change in $M$ due to $K_o$, which is estimated to be about 0.5 gauss for a field of 5000 oersteds.

In the case of $\text{Fe}_3\text{O}_4$ these effects caused considerable difficulty and they are treated more fully in Appendix B.

(E) Temperature Stability

Temperature variation of the resistivity $\rho$, and hence of the IR drop between the Hall probes can cause error in the determination of $R_o$ since the IR drop must be subtracted from the total voltage present in order to measure $R_o$.

As pointed out in Eq. (2.18), the IR drop in Ni is of the order of $10^{-5}$ volts.

\[
\frac{1}{\rho} \frac{\partial \rho}{\partial T} \approx 5 \times 10^{-3}/^\circ C
\]  
(2.33)

in Ni at room temperature [32].

\[
\frac{1}{\text{IR}} \frac{\partial \text{IR}}{\partial T} \approx 5 \times 10^{-3}/^\circ C
\]  
(2.34)

and

\[
\frac{\partial \text{IR}}{\partial T} \approx (5 \times 10^{-3})(10^{-5}) \approx 5 \times 10^{-8} \text{ volts/}^\circ C
\]  
(2.35)

The ordinary Hall voltage for Ni is estimated in Eq. (2.4) to be $\Delta V_H \approx 2.5 \times 10^{-7}$ volts and

\[
\frac{\partial \text{IR}}{\Delta V_H} \approx \frac{5 \times 10^{-8}}{2.5 \times 10^{-7}} \approx 2 \times 10^{-1}/^\circ C.
\]  
(2.36)

Therefore, temperature stability of the order of 0.05$^\circ C$ is required in a room temperature measurement of $R_o$ in Ni.

The IR drop in $\text{Fe}_3\text{O}_4$, as pointed out in Eq. (2.23), is of the order of $10^{-4}$ volts.
at room temperature, and

\[ \frac{8 \rho}{\Delta T} \approx 5 \times 10^{-3}/^\circ C \]  

(2.37)

Since the ordinary Hall voltage estimated in Eq. 2.5 is \( \Delta V_H \approx 5 \times 10^{-8} \) volts,

\[ \frac{8 \rho}{\Delta T (IR)} \approx (10^{-4})(5 \times 10^{-3}) \approx 5 \times 10^{-7} \text{ volts/}^\circ C \]  

(2.38)

Therefore, temperature stability of the order of \( 10^{-3}^\circ C \) is needed to keep the uncertainty in \( R_0 \) less than 1 per cent.

The temperature stability problem in Ni at room temperature is negligible. In the case of Fe\(_3\)O\(_4\), thermal instability arises mainly from the large amount of heat generated at the current contacts and the poor thermal conductivity of the material. Although electrical contact is made at large area, Cu-plated, spring-loaded contacts, nevertheless, the resistance across the contacts is 5 to 100 times the body resistance in Fe\(_3\)O\(_4\) and in the other ferrite sample. Therefore, in order to minimize heat generation and to assure temperature stability, the sample current must be limited to low values.

**Noise**

The measurement of voltages below 0.1 microvolt is fundamentally concerned with noise in both the detection system and in the system under investigation. Techniques are available for noise minimization in both ac and dc detection systems [33,34]. Provided that the amplifier noise has been minimized, the noise problems occur in the sample.

Certain classes of semiconductors evidence noise power greater than that found in a metal resistor. The mean square voltage of this excess noise is roughly proportional to the current squared and inversely proportional to the frequency, down to very low frequencies. Rollin and Templeton [35,36] report that the \( I^2 \) and \( \frac{1}{f} \) dependence occurs down to \( 2.5 \times 10^{-4} \) cps in carbon resistors and Ge. While the noise in ferrites has not been examined in detail, the samples investigated in this research evidenced noise power which
TR225 -18-

appeared to possess the above characteristics.

The mean square noise voltage present in a metallic resistance $R$, at the absolute temperature $T$, in the bandwidth $\Delta f$ is given by

$$\overline{e^2} = 4kTR\Delta f \quad (2.40)$$

where $k$ is the Boltzmann constant. To take account of the excess noise in semiconductors, an effective noise temperature $T'$ is defined such that the mean-square noise voltage in a semiconductor of resistance $R$ over the bandwidth $\Delta f$ is given by

$$\overline{e^2} = 4kT'R\Delta f \quad (2.41)$$

Then,

$$t = \frac{T'}{T} \quad (2.42)$$

where $T$ is the absolute temperature of the semiconductor, and $t > 1$ for a semiconductor.

If we substitute the value of the resistance between the point contacts in the $Fe_3O_4$ sample (~10 ohms) and assume $\Delta f = 4$ cps then for $t = 1$ (no excess noise) we obtain

$$\overline{e^2} = (4)(1.38) \times 10^{-23}(300)(10)(4) = 66.2 \times 10^{-20} \text{volts}^2 \quad (2.43)$$

$$\overline{e^2}^{1/2} \approx 8 \times 10^{-10} \text{volts} \quad (2.44)$$

Therefore, in the case of metal samples in which no excess noise exists, sample noise poses no problem. In the case of semiconductors in which values of $t$ at low frequencies of the order of $10^4$ have been reported [37] sample noise can cause serious difficulty in a low-level Hall measurement.

Since the mean square excess noise voltage is proportional to $I^2$ in semiconductors, then

$$\overline{e^2}^{1/2} \sim I \quad (2.45)$$

and no increase in signal-to-noise ratio can be obtained by increasing the current, because the Hall voltage is also linear in $I$.

Furthermore, if we assume that the excess noise power is due to conductivity modulation, then the excess noise power, which varies as $\frac{1}{T}$
about the current frequency has its maximum value at the current frequency. This means that if we reduce $\Delta f$ in Eq. (2.41), we increase $T'$ in such a manner that $e^2$ remains practically constant. This can be shown in the following manner.

$$e^2 = K' I^2 \frac{df}{f} = K \frac{df}{f} \quad (2.46)$$

Suppose we reduce the bandwidth over which we examine the noise from 4 cps to 1 cps. In the case of a metallic resistance, Eq. (2.40) shows that we decrease the mean-square noise voltage by a factor of 4. In the case of a semiconductor from Eq. (2.46) we obtain the following:

$$\frac{e^2}{e_1} = K \int_{\varepsilon}^{4} \frac{df}{f} \quad (2.47)$$

is the excess noise present in a bandwidth of 4 cps where $\varepsilon$ is a very small positive number.

$$\frac{e^2}{e_2} = K \int_{\varepsilon}^{1} \frac{df}{f} \quad (2.48)$$

is the excess noise present in a bandwidth of 1 cps. The ratio of the two mean-square excess noise voltages is then

$$\frac{\frac{e^2}{e_2}}{\frac{e^2}{e_1}} = \frac{K \int_{\varepsilon}^{4} \frac{df}{f}}{K' \int_{\varepsilon}^{1} \frac{df}{f}} = \frac{\int_{\varepsilon}^{1} \frac{df}{f}}{\int_{\varepsilon}^{1} \frac{df}{f} + \int_{4}^{4} \frac{df}{1}} \quad (2.49)$$

$$\frac{\frac{e^2}{e_2}}{\frac{e^2}{e_1}} = \frac{1}{1 + \frac{\ln 4}{\ln \varepsilon}} \quad (2.50)$$

In the limit as $\varepsilon \rightarrow 0$
\[
\lim_{\varepsilon \to 0} \frac{\delta n_4}{\tan \frac{1}{\varepsilon}} = 0
\]

(2.51)

and

\[
\frac{\sigma_2}{e_2} = 1
\]

(2.52)

Although this calculation has been carried out about zero frequency, the same conclusions obtain in the case of a semiconductor excited at the frequency \(f_0\).

In this case, the noise power is concentrated at the frequency \(f_0\) and varies as \(\frac{1}{|f_0 - f|}\). Thus, no reduction in excess noise power is achieved until the bandwidth is reduced almost to zero, since most of the excess noise power is concentrated in a very narrow bandwidth.

Fortunately, the Fe\textsubscript{3}O\textsubscript{4} sample possessed a very low effective noise temperature, with a value of \(t\) of the order of 200 for the current used, and hence the measurement could be made with a 4 cps bandwidth.*

2.3 The Choice of an AC or DC System

One of the more important decisions made in the course of this research was the changeover from a dc to an ac system. In retrospect, the advantages of the ac system far outweigh the dc system. However, since the literature abounds in misstatements concerning the efficacy of both, the choice of the type of system to be used in the measurements is worthy of consideration under the topic of measurement problems.

An ac system is one in which either the electric field \(E_x\), or the magnetic field \(H_z\), or both are made to alternate. The discussion of section 2-2A shows that the alternation of the magnetic field only, does not insure complete separation of the Hall voltage from the other transverse effects. We therefore restrict our discussion to the cases where only \(E_x\), or both \(E_x\) and \(H_z\) are made to alternate.

*Recently, Van Vliet, Van Leeuwen, Blok, and Ris [38] have reported that the noise in high resistivity ferrites is down by a factor of \(10^3\) over the value in a carbon resistor, and that there are in some cases deviations from an \(f^{-1}\) spectrum (\(f^{-1.1}\)). Furthermore, they report an \(I^{1.2}\) current dependence of excess noise. However, their measurements were made at very low current values.
As early as 1900, Des Coudres [39] made a Hall measurement on bismuth by passing the same alternating current through the sample and the magnet. The output was then read with a dc galvanometer. Such a system offers little advantage since the measurement is still subject to the difficulties which inhere in a low-level dc measurement. Furthermore, unless \( \frac{\partial T}{\partial x} = \frac{\partial T}{\partial y} = 0 \), the measurement is susceptible to uncertainty in the measured field, as can be seen by examination of Eqs. (2.6) and (2.7). A superior technique is to use a frequency \( f_0 \) for the electric field \( E_x \), and a frequency \( f_1 \) for the magnetic field \( H_z \). Then, at the Hall probes of a nonmagnetic material, there exist the following voltages:

\[
(V_y)_{\text{total}} = I_x R + I_x \Delta R(H_z^2) + V_H(I_x H_z) + V_1(H_z, \frac{\partial T}{\partial x}) + V_2(H_z, \frac{\partial T}{\partial y}) + V_{dc} \tag{2.53}
\]

where \( I_x R \) is the voltage drop due to the misalignment of the probes, \( I_x \Delta R(H_z^2) \) is the voltage due to the magnetoresistance effect, which is an even-valued function of the field. \( V_H(I_x H_z) \) is the Hall voltage. \( V_1(H_z, \frac{\partial T}{\partial x}) \) and \( V_2(H_z, \frac{\partial T}{\partial y}) \) are voltages which arise from the terms in \( H_z \frac{\partial T}{\partial x}, H_z \frac{\partial T}{\partial y} \) in Eqs. (2.6) and (2.7). \( V_{dc} \) includes all terms in Eqs. (2.6) and (2.7) which do not vary at the frequency \( f_0, f_1 \) or combinations of these frequencies in addition to the usual contact potential, and thermoelectric potentials which occur in any low-level dc system. If we assume \( E_x = E_0 \cos \omega_0 t \) and hence \( I_x = I_0 \cos \omega_0 t \) and \( H_z = H_0 \cos \omega_1 t \), then provided that \( \frac{\partial T}{\partial x} \) and \( \frac{\partial T}{\partial y} \) do not vary at the frequency \( f_0 \), a condition which can be obtained by making \( f_0 \) sufficiently large, we may write

\[
(V_y)_{\text{total}} = I_0 R \cos \omega_0 t + I_0 \Delta R \cos \omega_0 t \cos^2 \omega_1 t + V_H \cos \omega_0 t \cos \omega_1 t + V_1 \cos \omega_1 t + V_2 \cos \omega_1 t + V_{dc} \tag{2.54}
\]

By trigonometric substitution,

\[
(V_y)_{\text{total}} = I_0 R \cos \omega_0 t + \frac{I_0 \Delta R}{2} \left\{ \cos \omega_0 t + \frac{1}{2} \cos (\omega_0 + 2\omega_1) t + \frac{1}{2} \cos (\omega_0 - 2\omega_1) t \right\} + V_1 \cos \omega_1 t + V_2 \cos \omega_1 t + V_{dc} \tag{2.55}
\]
Thus, if the detector is tuned to $\omega_o + \omega_1$ or $\omega_o - \omega_1$, only $V_H$ is observed. In Des Coudres' experiment, since $\omega_o = \omega_1$, a measurement at $2\omega_o$ would have excluded the unwanted effects.

An additional advantage to the above scheme accrues in semiconductor measurements where the maximum excess noise power occurs at the frequency $f_o$. Measurements made at $f_o \pm f_1$ encounter a noise power reduced by a factor of $\frac{1}{|f_o - f_1|}$.

Such techniques have been used recently. Russell and Wahlig [40] have used a 70 cps current, a 60 cps magnetic field, and a detector tuned at 10 cps. Pell and Sproull [41], have used a 24 cps current and a magnetic field which reverses every six seconds ($f_1 = \frac{1}{12}$ cps). Because $\omega_o + \omega_1 \approx \omega_o$, the IR drop must be cancelled out by other means, and the advantage of reduction in noise power is lost. However, since much larger magnetic fields are available with this technique, the signal-to-noise ratio need not be decreased.

In the case of ferromagnetics, an additional term proportional to $R_1 M(H_z) I_x$ must be added to Eq. (2.53). In order to resolve the $R_0 H_z I_x$ term from the $R_1 M(H_z) I_x$ term advantage must be taken of the saturation effect of $M$, and hence the alternating magnetic field must be superimposed upon a static field $H_0$, such that

$$H_z = H_0 + H_1 \cos \omega_1 t$$

where $H_0 - H_1$ is sufficient to saturate the material. Since it is very difficult to obtain large alternating fields (Russell and Wahlig reported a field of 2000 oersteds), the additional requirement of a large static field precluded the use of such a technique in this research.

The important advantages of an ac system are the elimination of spurious contact potentials, thermoelectric potentials and their drifts with time and temperature, the exclusion of other transverse effects, and the ease with which signals may be amplified.

On the other hand, classical techniques using dc potentiometers and galvanometers are very adequate in making Hall measurements on low impedance samples where adequate precautions may be taken to exclude
the transverse effects, provided that voltages of the order of 50 microvolts or larger are to be measured. In this range, contact and thermoelectric potentials and their drifts do not pose too serious a problem. Furthermore, standard cells provide an absolute voltage reference, stable and accurate to one part in $10^5$. Current and voltage stabilization may be readily accomplished by the use of dry or storage batteries, or by systems employing them as reference standards. Laboratory voltmeters and ammeters are readily available with an accuracy of 1/4 of 1 per cent. In addition, voltages greater than 10 millivolts can be read to one part in $10^4$ and voltages up to 10 millivolts can be read to one microvolt.

While dc techniques can be employed in the submicrovolt range by calibrating the deflection of a galvanometer or by using a chopper-type dc amplifier, in addition to serious contact and thermoelectric potential problems, there are problems of galvanometer vibration and 60 cps pickup in dc amplifiers. Furthermore, although dc chopper-type amplifiers can achieve a sensitivity of $10^{-18}$ watts, this sensitivity may be obtained only with ideal experimental conditions. On the other hand, ac amplifiers can readily achieve a sensitivity of $10^{-19}$ watts under any normal experimental conditions. In comparison with the dc amplifier, a high sensitivity galvanometer matched to a low impedance sample, can have a sensitivity of the order $10^{-17}$ watts.

There are also very definite disadvantages to an ac measurement. One of the more serious difficulties is the effect of vibrations set up by the alternating current in the magnetic field. This induces a spurious voltage in the Hall loop which is not an even-valued function of the magnetic field and which can be large compared to the Hall voltage. In addition, absolute calibration of an ac system is difficult. Thermal meters provide about 1 per cent accuracy at impedance levels which are not usually optimum for the measurement. Nevertheless, these problems are much less severe than those encountered with a low level dc system.

2.4 Statement of the Problem

As evidenced in the previous sections, the measurement of the Hall voltage in Fe$_3$O$_4$ is a more difficult problem than the measurement in Ni.
Therefore, the equipment design must be predicated upon the Fe₃O₄ measurement. The detector must be capable of detecting a Hall voltage of the order of 5 x 10⁻⁸ volts in the presence of 1/2 type noise. While increase of sample current I results in an increase of the Hall voltage, there is no gain in signal-to-noise ratio since the mean square noise voltage is proportional to I², as previously noted. Furthermore, the attendant thermal instability with increase of current makes the IR subtraction more difficult. In order to eliminate the magneto-resistance effect, a field-reversal technique must be used since the required alternating magnetic field cannot be obtained. Equation (2.53) then shows that the IR drop estimated in Eq. (2.23) to be of the order of 10⁻⁴ volts, must be subtracted from the total voltage present at the Hall probes. Since the ratio of the IR drop to the Hall voltage estimated in Eqs. (2.23) and (2.5) is

\[
\frac{IR}{AVH} \approx \frac{10^{-4}}{5 \times 10^{-8}} \approx 2 \times 10^3
\]  

(2.57)

both the current, I, and the voltage used to buck out the IR drop must be stable to at least 2 parts in 10⁵ if the two effects are to be separated with an accuracy of 1 per cent. The transverse effects must be eliminated, or suitable provision must be made to insure that their effects are small. The R₀ΔH term must be separated from the RₓMₓ term. Since the ratio of these two effects estimated in Eq. (2.28) is \( \frac{R₀ΔH}{RₓMₓ} \approx 6 \times 10^{-3} \), the system must possess a voltage resolution of at least 6 parts in 10⁵, if the Hall voltage is to be determined to 1 per cent.

These were the design criteria for the equipment used in this research.

2.5 The Solution

An ac system using a 1000 cps current and a dc magnetic field was employed. The use of 1000 cps effectively eliminated the transverse effects, the spurious dc potentials, and simplified the amplification problem. A high-gain amplifier (160 db) tuned at 1000 cps was fed into a narrow-band (4 cps) detector providing an adequate noise level (3 x 10⁻⁹ volts). With currents of approximately 300 ma, through the Fe₃O₄ sample, the noise level increased only by a factor of 3-4. Amplification problems are simple at 1000 cps;
60 cps pickup poses no problem. The field reversal technique and the method of resolving the ordinary Hall voltage from the extraordinary effect are outlined below. Sample current and bucking voltage were maintained stable by means of voltage and frequency regulation and large amounts of feedback.

Figure 2-2 Shows a block diagram of the equipment

Figure 2-3 Shows a typical curve of the Hall voltage in ferromagnetic.

Figure 2-4 Shows the field-reversal technique of making the ordinary Hall measurement.

The #1 bucking voltage was used to buck out all pick-up voltages, the IR drop due to misalignment of Hall contacts, and both the Hall and magneto-resistance voltages for one direction of the field at a point above saturation called $H_1$ down on the diagram. The field was then reversed, and the #2 unit switched into the circuit. The output voltage $2V_{H_1}$ for the value of the field $H_1$ was then stored in the #2 bucking voltage unit with its phase reversed. With the #2 bucking unit switched out, and the field at the point $H_2$ down, the #1 bucking unit was used to buck out the voltages added to those already present, namely, the ordinary Hall voltage and the magneto-resistance for the increment of field $H_2 - H_1 = \Delta H$. With the field reversed, i.e., point $H_2$ up on the diagram, the voltage stored in the #2 unit was inserted, performing the operation $2V_{H_2} - 2V_{H_1} = 2 \Delta V_H$, where $\Delta V_H$ is the ordinary Hall voltage for the increment of field $\Delta H$.

A vector diagram of the measurement technique with no attempt to retain the relative scale of the vectors since they may be of the order of $10^4:1$ is shown in Fig. 2-5.

Since the signal-to-noise ratio at the output of the amplifier was low, the sign of $\Delta V_H$ and hence $R_0$ was obtained in the following indirect manner: the sign of the extraordinary effect $V_{H_1}$ was compared with the known sign of the extraordinary effect in Ni on the phase comparator oscilloscope. The sign of $\Delta V_H$ determined by the slope of the curve above saturation was then given by $V_{H_2}/V_{H_1} \geq 1$, or alternatively stated, whether $2V_{H_2}$ was greater than or less than the voltage stored in the #2 unit. This was most readily determined by increasing or decreasing the magnitude of the #2 bucking voltage and observing the output of the narrow-band detector.
The system possessed an important means of checking for the presence of spurious signals of the same order of magnitude as $\Delta V_H$, which were $H$-dependent and not in phase with the current. As may be readily ascertained from the vector diagram, the addition of an $H$ dependent voltage not in phase with the current results in $2V_H$ being of a different phase from $2V_{H1}$, the voltage stored in the $#2$ bucking unit. Even if the spurious voltage is linear in $H$, this result obtains because the voltage $V_{H1}$ is proportional to $R_1M$ and the voltage $V_{H2}$ is proportional to $R_1M + R_0 \Delta H$ and hence not linear in $H$. Thus, a voltage larger than the true Hall voltage would be observed on the output meter. Its presence could be determined by minimizing the output voltage with a phase adjustment of the $#2$ unit. This technique was used to assure that all effects of vibration were removed from the system.

In order to determine the extraordinary Hall coefficient, $R_1$, a field-reversal measurement was made at $H_1$ and the output voltage $2V_{H1}$ was read directly. At the value of applied field $H_1$, it was assumed that the sample was saturated and that the field $H$ inside the material was small. Hence Eq. (2.2) was approximated by

$$V_{H1} \approx R_1 M_s \frac{I}{t}$$

Therefore, with a value of $M_s$ appropriate to the temperature and the material, $R_1$ may be determined.
FIG. 2-3 A TYPICAL CURVE OF THE HALL VOLTAGE AS A FUNCTION OF THE APPLIED MAGNETIC FIELD IN A FERROMAGNETIC MATERIAL

FIG. 2-4 THE FIELD REVERSAL TECHNIQUE OF MAKING THE ORDINARY HALL MEASUREMENT
FIG. 2-5 A VECTOR DIAGRAM OF THE MEASUREMENT TECHNIQUE
III.
THE EXPERIMENTAL APPARATUS AND TECHNIQUES

3.1 The Measuring Equipment

(A) The 1000 cps Source

In order to subtract out the IR drop in Fe$_3$O$_4$, it was necessary that the sample current and bucking voltage remain stable to 2 parts in $10^5$. The bucking system employed R-C phase shifters in order to obtain the necessary resolution in phase angle. Since the phase angle $\theta$ is proportional to $\frac{2}{\omega}$, the frequency stability requirement was of the order of one part in $10^5$.

The 1000 cps source was obtained from a 100 kc oscillator maintained by the Wave Propagation Group at Harvard [42] and reduced by a 5-2-5-2 division. The oscillator with temperature controlled crystal, compensated for aging, was stable to at least one part in $10^9$.

The output of the divider stages was passed through a low-pass filter, a high-$Q$ stage of amplification and transmitted 350 feet over RG 58/U coaxial cable to the location of the experiment.

(B) The Power Amplifier Chassis

The 1000 cps signal was fed into the power amplifier chassis, Fig. 3-1, where the remaining high-frequency components of the source and 60 cycle pickup were removed by appropriate low-pass filters and twin-tees. The 0.5 volt delivered at the input was amplified in 6 single-ended stages and one push-pull stage to drive a pair of 807's in push-pull. The output transformer (U. T. C. LS6L4) was capable of handling 55 watts. Negative feedback was provided in the loop from the output transformer to the cathode of the fifth stage. The power amplifier was a standard 20-watt design with the exception of a bias control potentiometer for the 807's, to insure equal and opposite direct currents in the two halves of the split primary of the output transformer. The low-impedance secondary winding of the output transformer provided the sample current; the high-impedance (500 ohms) winding provided the voltage for bucking purposes. This scheme had the advantage of permitting...
both the sample current and the bucking voltage to change by a small amount without upsetting the IR subtraction. The plate voltages of all stages of voltage and power amplification were regulated with standard supplies designed for the system. While capable of delivering 5 amperes into low-impedance samples (1 ohm), 1 ampere was standardized upon for all metal measurements. This provided adequate signal and optimum stability. The harmonic content of the sample current was of the order of 1 per cent, concentrated in the second and third harmonics.

One half of a 6 SL7, in a transformer-coupled stage, was used to drive a General Radio Microvolter for calibration purposes, and to provide a reference signal for phase comparisons.

The sample current was read by a 0-1 ampere, panel mounted meter calibrated with a laboratory standard. Provision was made for inserting an external meter into the circuit to read larger or smaller currents.

(C) The Detector

The detector consisted of two standard laboratory devices. The TAA-16EA Twin-Tee Amplifier designed at the M. I. T. Radiation Laboratory [43] and built by the Electronic Corporation of America provided a gain of 160 db. With the transformer input to the amplifier shown in Fig. 3-2 (impedance ~50 ohms) the noise level of the amplifier was of the order of 0.1 microvolt. The bandwidth of the detector system was further reduced by feeding the output of the amplifier into a General Radio-Wave Analyzer with a 4-cycle bandwidth. This provided the system with a noise level of $3 \times 10^{-9}$ volts. The system linearity is shown in Fig. 3-3.

It was quite important in using a high gain amplifier in a system with large ground currents, that no closed ground loops exist between output and input of the amplifier.

(D) The Bucking, Adding, and Calibrating Circuits

The bucking units provided voltages of the proper amplitude and phase to cancel out specified signals. The units comprised only passive elements such as General Radio wire-wound potentiometers and U. T. C. LS X-type transformers, in order to take advantage of the effective stability provided by
FIG. 3-2 THE BUCKING, ADDING AND CALIBRATING CIRCUITS
ZERO LEVEL OUTPUT ~ 40 MV CORRESPONDING TO 3 x 10^{-9} VOLTS NOISE LEVEL
SYSTEM GAIN ~ 2 x 10^9

FIG. 3-3 THE SYSTEM LINEARITY
obtaining both the sample current and the bucking voltage from the same transformer. Furthermore, the stability requirement of 2 parts in $10^5$ precluded the use of amplifying stages. The $\#1$ and $\#2$ units were similar but not identical because the required range of voltage and resolution was greater for the $\#1$ unit. For example, in the $\text{Fe}_3\text{O}_4$ measurement, the $\#1$ unit was used to buck out the IR drop of the order of $10^{-4}$ volts plus other smaller voltages, while the $\#2$ unit was used to buck out the voltage due to the extraordinary effect of the order of $10^{-5}$ volts. Both units employed R-C phase shifters. In order that the output amplitude be insensitive to phase angle, the R-C phase shift network must work out of a low impedance and into a high impedance. As a consequence, considerable voltage loss occurs in these units, requiring voltages of the order of 100 volts at the input of the $\#1$ unit. It was verified by test that after the appropriate cycling of voltages, there was no interaction between the $\#1$ and $\#2$ units. Figure 3-2 shows the bucking circuits as well as the adding and calibrating circuits.

The sample voltage and the $\#2$ bucking unit voltage were added by the LS 31-X transformer. The $\#1$ bucking unit voltage was added to the system by inserting the secondary of the LS 14-X transformer in series with the secondary of the LS 31-X transformer.

In order to calibrate the system for samples with a wide range of impedance, including values greater than the impedance of the input transformer, the calibrating signal was fed into a one-ohm wire-wound resistor in series with the sample input. The General Radio Microvolter was calibrated as well as the voltage transformation ratio of the LS 12-X coupling transformer. Since this ratio was $1.07 \times 10^{-3}$:1, voltages between $10^{-9}$ volts and 1 millivolt were provided for calibration purposes.

(E) The Electromagnet

The electromagnet, of laboratory design, consisted of a U-shaped section 19 inches high by 20 inches long of 6 inches square Armco iron. The poles were 7 inches in diameter. Four coils, each consisting of 980 turns of No. 12 copper wire, provided the excitation field. The end plates of the coils were water cooled. A field of 8900 oersteds was provided by 2200 watts in a 2-inch gap and 12,400 oersteds in a 1-inch gap.
The magnet supply consisted of 8 selenium rectifiers in two parallel full-wave bridge circuits. The output was smoothed with a heavy-duty L-C filter. Maximum power available was 2200 watts.

The magnetic field was calibrated with proton and lithium resonance lines and fill-in points were obtained with a flip coil and ballistic galvanometer. A Weston Model 430, 1/4 of 1 per cent ammeter was used both to calibrate the magnet and to set the magnetic field during measurements. The homogeneity, as evidenced by the proton lines, was much better than needed in this measurement.

Although magnet hysteresis causes no concern because of the method of measurement, it may be stated that negligible hysteresis existed in this magnet. Healy [44] has reported a 4-oersted hysteresis in the field at 3000 oersteds when the magnet was cycled around the 4000-gauss hysteresis loop.

Figure 3-4 is a photograph of the equipment used in this research.

3.2 Discussion of Errors

The determination of \( R_0 \) requires the measurement of the sample current, the output voltage, the magnetic field, and the sample thickness. The determination of \( R_1 \) requires the measurement of the sample current, the output voltage, the saturation magnetization, and the sample thickness. All of these measurements are subject to random error of measurement as well as to systematic error in the calibration and reading of the instruments used to make the measurements. For example, the output meter of the General Radio Wave Analyzer could be read to about 1 per cent. Therefore, with each reading of output voltage we have a 1 per cent random error. On the other hand, the ammeter used to determine the sample current was calibrated against a laboratory standard with an accuracy of 3/4 of 1 per cent. Therefore, the values of current measured with this ammeter may be in error by 3/4 of 1 per cent but the same error will systematically occur in every determination of current. Random errors may be minimized by using the average value of several observations. Systematic errors can be reduced only by improved calibration or improved accuracy of the measuring system. However, the net effect of two or more systematic errors which are completely
independent is random. For example, if we have a 1 per cent systematic error in determining the current, and a 2 per cent systematic error in measuring the sample thickness, the probability that these two errors add is equal to the probability that they subtract. Therefore, we estimate their net effect by taking the square root of the sum of their squares. Random errors are compounded in the same way, and hence, with a few exceptions, we treat all errors in this manner.

In addition to the errors of measurement, error may occur because of the presence of large voltages which are temperature- and field-dependent. For example, in the measurement of $R_0$, a large IR drop and a large extraordinary Hall voltage are produced across the Hall probes. Because of the uncertainty in setting the magnetic field at each of four values in the differential measurement and because of temperature fluctuations during the time of the measurement, voltages different from the ordinary Hall voltage may be observed. However, these effects give rise to small errors (2 per cent or less), except in the case of the $\text{Fe}_3\text{O}_4$ measurement, which are inherently random and which can be minimized by repeated observations.

In the case of the $R_0$ measurements on Grade A-Ni, we have 1 per cent error in determining the sample current, 1 per cent error due to the harmonics present in the current, 1.5 per cent error in reading the output voltage, 1.7 per cent error due to the signal-to-noise voltage ratio, 2.5 per cent error in the calibrating voltage, and 2 per cent error in the sample thickness. The uncertainty in the measurement of the magnetic field, along with the other errors which occur because of uncertainties in setting the magnetic field, total about 2.3 per cent. We assume about 1 per cent random error due to temperature fluctuations over the time of measurement. We estimate the total error in $R_0$ by calculating the rms value of all the errors except the 1 per cent due to harmonics in the current. Since this is known to decrease the value of the current at 1000 cps, we prefer to add this error algebraically. The total error in $R_0$ is then 5.7 per cent. To this we must add the uncertainty in $R_0$ due to the change of $M$ above saturation.

We estimate that this causes about 3 per cent error at room temperature and about 5 per cent error at 140°C. Above the Curie temperature the signal-to-noise voltage error is reduced to about 1 per cent, and because
the magneto-resistance effect is small in this region, the error due to
the magnetic field is reduced to about 1 per cent. The error above the
Curie temperature is estimated to be 5.1 per cent.

The errors estimated for the $R_0$ measurements of Grade A Ni typify
the error in the other $R_0$ measurements, with the exception of Fe$_3$O$_4$. In
the case of the 70 per cent Ni-30 per cent Cu alloy we estimate 5.7 per cent
error below the Curie temperature and 5.1 per cent above. In the case of
the $R_0$ measurement of (Ni0)$_{.75}$(Fe0)$_{.25}$(Fe$_{2}$O$_{3}$) at room temperature, we
estimate about 6.3 per cent error.

In the case of the $R_0$ measurement of Fe$_3$O$_4$, the error is larger.
Because of the very large IR drop and the large extraordinary Hall voltage,
uncertainties in setting the magnetic field and temperature fluctuations
produced large random errors. The very small signal-to-noise ratio also
produced large random errors. We estimate the effect of these random
errors by calculating the standard deviation of the mean value of 31
observations and dividing by the mean value. The error estimated in this
manner is 5.5 per cent. To this we add 4.5 per cent error in determining
the electrical quantities and the sample thickness. We conservatively total
this error to 10 per cent. However, the change of $M$ above saturation, which
is discussed more fully in Appendix B, can provide a large uncertainty in $R_0$.

In the case of the $R_1$ measurements on Grade A Ni, certain of the
random errors are negligible. For example, because relatively large
voltages were observed, the signal-to-noise voltage error is negligible,
and the uncertainties caused by the magnetic field and temperature
fluctuations are very small. The uncertainties in determining the output
voltage, the sample current, and the sample thickness are the same as in
the $R_0$ measurement. However, in the $R_1$ measurements, additional error
occurs because of the uncertainty in $M_s$ and because of the error in applying
corrections to $R_1$. In the case of Grade A-Ni, we estimate less than 1 per cent
uncertainty in $M_s$ and about 1 per cent uncertainty in the corrections. There-
fore, the error in $R_1$ is about 5.0 per cent at all temperatures.

In the case of the other metals, the uncertainties in $M_s$ are somewhat
larger and the correction errors are larger in certain cases. However, in no case is error greater than 6.0 per cent estimated. In the case of Fe₃O₄, Ms is known fairly accurately and the estimated error is also less than 6.0 per cent. However, in the case of (NiO)₀.₇₅(Fe₂O₃)ₐ.₂₅(Fe₂O₃), a calculated value of Ms was used and no estimate of error can be assigned. However, all other errors in this measurement total about 6.0 per cent.

According to the Karplus-Luttinger theory, R₁ is proportional to \( p^2 \). In order to determine the observed proportionality, we have calculated the slope of the curve of log \( R₁ \) versus log \( p \). The slope of this curve is quite sensitive to the values of \( R₁ \) and especially \( p \), and hence error in the measurement of these quantities will cause marked departure from the true value. However, virtually all of the random errors are averaged out, and the systematic errors do not alter the slope of the curve. One of the more serious sources of error in this determination was the comparison of \( R₁ \) with values of \( p \) measured in zero magnetic field. The value of \( p \) which occurs in the measurement of \( R₁ \) may differ by a few per cent, because of magneto-resistance. However, it can be shown [84] that error cannot account for the observed departure from a \( p^2 \) dependence in the case of the high Ni concentration alloys. In the case of the 80 per cent Ni-Fe alloys, both \( R₁ \) and \( p \) are fairly insensitive functions of temperature, and errors in the observation of these quantities may account for some of the observed departure from a \( p^2 \) dependence.

### 3.3 The Sample Holders

As indicated in Section 2-3, and pointed out by Kevane, Levgold, and Spedding [45], the most serious difficulty in the use of an ac system is the presence of spurious voltages due to vibrations. The vibration troubles occur when the high current leads or the sample vibrate in the magnetic field, or when the vibrations of the sample holder cause relative motion between the Hall loop and the high current carriers. These were eliminated by mechanical design of the sample holder.

(A) **For Metals**

The method of eliminating the difficulty in the case of metal samples, dimensions of the order of 0.75" x 3.0" x 0.005", is shown in Fig. 3-5 and
Fig. 3-6, views of the high-temperature metal sample holder. The sample current was led through the magnetic field in a rigid coaxial cable. In order to prevent vibration of the sample, and in order to prevent relative motion between the sample and the Hall leads in the vicinity of the sample, both the sample and the Hall leads were clamped to the base plate by stainless flat sections, mica-insulated. Thus, although vibrations of the sample holder itself might not be eliminated, there was no voltage induced in the Hall loop. No special precautions were taken in running the Hall leads out of the magnetic field. The field due to the current was small in this region because of the use of the coaxial line and the distance from the sample.

The solid coaxial line consisted of two #304 stainless steel tubes. The outer one, 0.319 inch I.D., was spaced from the inner one, 0.125 inch O.D., by Stupakoff (Stupakoff Ceramic and Manufacturing Company, Latrobe, Pennsylvania) steatite insulating beads 0.312 inch O.D., 0.125 inch I.D. No. 78 Sauereisen (Sauereisen Cements Company, Pittsburgh 15, Pennsylvania) was used to cement the insulating beads to one another and to the inner and outer conductors. Stainless steel was used throughout the sample holder, since in the region of temperature gradient its low thermal conductivity minimized losses, and in the region of high temperature, its high-temperature structural properties were needed. Three leads were silver-soldered to all metal samples; one end of the sample was grounded to the sample holder. The holder shown in the photograph, Fig. 3-7, was used up to 500°C.

In the case of low-temperature metal measurements, similar techniques were employed. Variations were made only to conform to the requirements of the temperature range and to the space limitations imposed by the Dewar flask. Figure 3-8 shows a photograph of the low-temperature metal sample holder. The large brass rings served as clamps, in the absence of room to sink threads in the base plate, and provided a large thermal mass for the holder. The entire sample area was enclosed by a cylindrical brass case, liquid-air-tight.

(B) For Ferrites

The technique of mounting the sample in a sample block shown in the exploded view of Fig. 3-9 was used at both low and high temperatures. For
FIG. 3-5 A CUT-AWAY VIEW OF THE HIGH TEMPERATURE SAMPLE HOLDER AND FURNACE FOR METALS.
FIG. 3-7 THE HIGH TEMPERATURE SAMPLE HOLDER FOR METAL SAMPLES OUTSIDE OF THE FURNACE

FIG. 3-8 THE LOW TEMPERATURE SAMPLE HOLDER FOR METAL SAMPLES
FIG. 3-9 AN EXPLODED VIEW OF THE SAMPLE BLOCK FOR THE \((\text{NiO})_{0.75} \,(\text{FeO})_{0.25} \,(\text{Fe}_2\text{O}_3)\) SAMPLE

FIG. 3-10 PHOTOGRAPH OF THE SAMPLE BLOCK FOR THE \((\text{NiO})_{0.75} \,(\text{FeO})_{0.25} \,(\text{Fe}_2\text{O}_3)\) SAMPLE
low-temperature work, the sample block was made of bakelite (linen-base) or formica. Pointed 0.040-inch tungsten rods backed by flat phosphor bronze springs provided the Hall contacts. The current contacts were also flat phosphor bronze springs applied to the upper end surface of the sample, and served to clamp the sample to the block, as well. The ends of the sample, extending back about 0.10-inch on four sides, were plated, first with rhodium and then with copper. The sample block and the Hall leads were solidly clamped to the base plate of the holder. Connections from the current contacts to the coaxial line and ground were made by a short, heavy copper rod and a screw passing through the sample block to the base plate.

For high temperatures, the sample blocks were machined from Grade A Lava (American Lava Corporation, Chattanooga 5, Tennessee) and fired at 1000°C. Similar tungsten points were used, and flat springs were made of 0.006 inch tungsten sheet. Figure 3-10 shows a typical ferrite sample mounting.

3.4 Temperature Techniques

Figure 3-5 shows a cut-away view of the high-temperature metal sample holder and furnace. About 8 feet of No. 26 chromel wire was wound in a bifilar winding around two supporting mica sheets, notched at the ends to space the wire. A 0.020-inch stainless steel reflector was placed around the windings and insulated from them by sheet mica. A box made of 1/2 inch transite, clamped tightly to reflector, windings, and sample holder, provided thermal insulation. Six hundred watts (dc) was adequate to raise the sample temperature to 600°C. Stabilities of the order of 0.05°C were obtained for periods of several minutes, adequate for measurements of the extraordinary effect, $R_I$. When $R_0$ measurements were made, a regulated power supply was used for additional stability.

For low-temperature measurements of $R_I$ in metals, the low-temperature holder shown in Fig. 3-8, was inserted in a glass dewar. Temperatures between room temperature and liquid-air temperature were obtained by adding small quantities of liquid air to the dewar, and measurements were made at the equilibrium temperature. Since the system approached equilibrium
exponentially in time, and since the sample was well lagged, a period of at least two minutes was available for each run.

Similar techniques were used for the $R_1$ measurements on the ferrites at both high and low temperatures. For the $R_0$ measurements on the ferrites, made only at room temperature, it was found preferable to place the sample in a metal can in contact with the large thermal mass of the magnet. Thermal isolation, as, for example, by inserting in a dewar, did not enhance the thermal stability due to the small but finite amount of power supplied to the sample.

Temperatures were measured with chromel-alumel (high-temperature range) and copper-constantin (low-temperature range) thermocouples and a Leeds and Northrup K-2 Potentiometer. The chromel-alumel thermocouple was calibrated at the melting point of Al(659.7°C), Zn(419.45°C), Cd(320.9°C), Sn(231.85°C) and at the transition point of $\text{Na}_2\text{SO}_4:10\text{H}_2\text{O}$ (32.384°C). The copper-constantin thermocouple was calibrated at the boiling point of liquid $\text{O}_2$(-183.00°C), at the $\text{CO}_2$(-78.51°C) point and compared at other points with a thermocouple calibrated at the National Bureau of Standards. Total error in absolute temperature measurements due to all uncertainties was less than 0.5°C for all points.

3.5 Samples

Ferrites have been made for many years by a sintering process which produces a material with a large number of grain boundaries. The grain boundaries produce excess noise, and inhomogeneity of electrical properties. The samples used in this research were single or nearly-single crystals of known composition. The writer is grateful to Professor A. R. von Hippel and Mr. J. Smiltens [46] of the Laboratory for Insulation Research, M. I. T., for the $\text{Fe}_3\text{O}_4$ sample supplied and to Dr. G. W. Clark and The Linde Air Products Company for the other single crystal ferrite samples measured in this work.

The impurities present in $\text{Fe}_3\text{O}_4$, sample 18, were Pt 1.4 parts in $10^6$, Si and Al less than 0.001 per cent. The value of $r$, where $r$ is the ratio of total Fe to Fe$^{+++}$ was $r = 3.012 \pm 0.012$. Stoichiometric $\text{Fe}_3\text{O}_4$ has a value of $r = 3.000$. 
The Linde nickel iron ferrite sample 8/18/52 A was composed of 19.1 per cent Ni and 52.5 per cent Fe by weight. Assuming stoichiometric proportions for oxygen, this calculated out to be \((\text{NiO})_{0.75}(\text{FeO})_{0.25}(\text{Fe}_2\text{O}_3)\).

Linde crystal 6/12/53 D, Ni Zn Fe ferrite, contained 14 per cent Ni, 4 per cent Zn, 55 per cent Fe and was calculated to be \((\text{NiO})_{0.56}(\text{ZnO})_{0.14}(\text{FeO})_{0.30}(\text{Fe}_2\text{O}_3)\).

The writer is also grateful to Mr. R. J. Pastine and the Driver-Harris Company for many of the Ni alloys provided for this research, and to Dr. R. M. Bozorth of the Bell Telephone Laboratories for the samples of Mumetal.

The following metals were obtained from the Driver-Harris Company (Harrison, New Jersey): 499 Alloy with purity of the order of 99.95 per cent; Grade A Ni, purity of the order of 99.4 per cent, with 0.2 per cent Mn, 0.15 per cent Fe, 0.1 per cent Cu, 0.1 per cent C, 0.05 per cent Si, 0.005 per cent S, given as nominal composition by the Metals Handbook \[32\]; R-63 alloy consisting of 95 per cent Ni, 4 per cent Mn, and 1 per cent Si; Lucero, with composition 70 per cent Ni - 30 per cent Cu.

The samples obtained from the Bell Telephone Laboratories were Mumetal, with composition 77 per cent Ni, 5 per cent Cu, 2 per cent Cr, remainder Fe and impurities, and Supermalloy, with composition 79 per cent Ni, 5 per cent Mo, remainder Fe and impurities.

The Carpenter Hymu 80, obtained from the Carpenter Steel Company (Reading, Pennsylvania) contained 79 per cent Ni, 4 per cent Mo, remainder Fe and minor constituents.
IV.
THE ORDINARY HALL MEASUREMENTS ON
GRADE A Ni AND 70 Ni-30 Cu

4.1 The Experimental Results

(A) Ni

Although Hall measurements on Ni over a wide range of temperature and at high fields had been reported by Smith [6] in 1910, no precise data concerning the variation of the ordinary Hall coefficient, \( R_o \), could be extracted from his published curves because of the need for high resolution in the region above saturation. Therefore, in order to examine the behavior of \( R_o \) as a function of temperature, in order to verify the existing temperature data on \( R_I \), and in order to ascertain that the measurement technique described in Chapter II and the equipment described in Chapter III would perform satisfactorily on the simpler metal measurements, the Hall measurements on Driver-Harris Grade A Ni were undertaken.

Figure 4-1 shows the curve of Hall voltage as a function of the applied magnetic field, \( H \), at room temperature for a Grade A Ni (99.4) sample, 0.005 inch thick. The sample current was 1 ampere. It is to be noted that the demagnetizing factor for a thin sheet, perpendicular to the plane of the sheet, is \( 4\pi \), and although saturation should be attained at a value of external field close to \( 4\pi M_s \) or 6100 oersteds for this case, the sample does not show complete saturation, or linear increase of voltage with applied field, until 7500 oersteds. This effect has been discussed in section 2-2D. The differentially measured values of voltage above 9000 oersteds are shown in the enlarged section of Fig. 4-1. From the slope of this curve, the value of the ordinary Hall coefficient, \( R_o \), is obtained.

The value of \( R_o \) deduced from Fig. 4-1 is \( R_o = -6.02 \times 10^{-13} \text{ volt-cm} \). This compares favorably with the value \( R_o = -6.11 \times 10^{-13} \text{ volt-cm} \) obtained by Pugh, Rostoker, and Schindler [10] at room temperature on Ni (99.6) and a value of \( R_o = -6.07 \times 10^{-13} \text{ volt-cm} \) obtained by Schindler and Pugh [47] on Ni (high purity) at room temperature, both measured with dc systems.

Figure 4-2 shows a representative group of curves of Hall voltage as
FIG. 4-1 THE HALL VOLTAGE AS A FUNCTION OF APPLIED MAGNETIC FIELD FOR GRADE A Ni. SAMPLE THICKNESS, t = .005 INCHES; I = 1 AMP; T = 27°C.
FIG. 4-2 THE HALL VOLTAGE AS A FUNCTION OF APPLIED MAGNETIC FIELD FOR GRADE A Ni AT TEMPERATURES BETWEEN 71°C AND THE CURIE TEMPERATURE. SAMPLE THICKNESS, t = 0.005 INCHES; I = 1 AMP; T_c = 358°C
a function of applied magnetic field with temperature as a parameter.

From these curves it can be seen that the voltage proportional to $R_1M_s$ increases with temperature to within $100^\circ C$ of the Curie temperature ($358^\circ C$), although $M_s$ decreases with increase of temperature. The decrease of $M_s$ is directly evidenced by the shift of the knee of the curve to lower values of applied field, indicating decreasing values of $4\pi M_s$. The increase of the slope above saturation with increase of temperature cannot be directly attributed to a change in $R_o$. The change of magnetization with applied field above saturation due to the $K_o$ term discussed in section 2-2D, increases with increase of temperature and provides the major contribution to the slope of the curve in the vicinity of the Curie temperature. This effect may be described in the following manner. When technical saturation has been reached, at temperatures different from absolute zero, some of the spins are not oriented in the direction of the applied field because of thermal agitation. The $K_o$ term may then be ascribed to the progressive alignment of the temperature-disoriented spins by the increasing magnetic field. Although Holstein and Primakoff [31] have calculated the order of magnitude of this effect, in good agreement with experiment, by explicit consideration of the dipole-dipole interactions between spins, their theory is essentially a low-temperature theory applicable only where $M_o-M_s$ is small. $M_o$ is the $0^\circ K$ saturation magnetization. Since $\frac{M_s}{M_o} = 0.78$ at $200^\circ C$ for Ni, the effect of the $K_o$ term upon $R_o$ cannot be calculated at this temperature with the Holstein and Primakoff formulation. Furthermore, $K_o$ has been measured for Ni only to $140^\circ C$ [ref. 12, p. 487]. Therefore, the $K_o$ effect cannot be adequately subtracted from the total slope of the curve, and hence no significant $R_o$ information can be obtained from these curves above $200^\circ C$.

The measurements on Grade A Ni were carried well into the paramagnetic region to observe the behavior of $R_o$ above the Curie temperature. Figure 4-3 shows the curves of Hall voltage as a function of applied magnetic field for temperatures above the Curie temperature. Since the extraordinary Hall effect probably still exists in this region, the strong paramagnetism of Ni in this temperature range probably contributes to the observed slope. However, the paramagnetic susceptibility obeys Curie's law, and we would expect that the contribution of the
extraordinary effect would vary as $\frac{1}{T-\theta}$, where $\theta$ is the paramagnetic Curie temperature, and disappear at sufficiently high temperature. Analysis of the data above the Curie temperature by plotting the observed values of $R_o$ as a function of $\frac{1}{T-\theta}$, where $\theta = 374^\circ$C, shown in Fig. 4-4, indicates the predicted behavior over a portion of the temperature range. However, between $528^\circ$C and $568^\circ$C the values of $R_o$ do not vary with temperature. The value of $R_o$ observed in this region is $R_o = -8.40 \times 10^{-13}$ volt-cm/amp-oersted. The value of $R_o$ deduced by extrapolating the linear portion of the curve of $R_o$ versus $\frac{1}{T-\theta}$ to infinite temperature is $R_o \to 5.5 \times 10^{-13}$ volt-cm/amp-oersted. However, since $R_1$ has an unknown temperature dependence in this region, the slope of the curve will be altered by this dependence and the extrapolated value of $R_o$ will probably be smaller in absolute value. Therefore, we may only infer that in the temperature range $528^\circ$C to $568^\circ$C the value of $R_o$ is approximately equal to the room temperature value not to be excluded.

Figure 4-5 shows the observed values of $R_o$ over the temperature range from room temperature to $568^\circ$C. Between room temperature and $200^\circ$C the values of $R_o$ are constant within experimental error. Rough estimates indicate that between $200^\circ$C and $300^\circ$C the apparent increase of $R_o$ is due entirely to the change of magnetization. In the region between the Curie temperature and $528^\circ$C, the extraordinary effect undoubtedly influences the observed values of $R_o$. In the region between $528^\circ$C and $568^\circ$C, as indicated above, we cannot assign an exact value to $R_o$, but we may only place an upper bound on the absolute value.

Listed below in Table 4-1 are some of the physical properties of Grade A Ni to be used in the following discussions.

(B) 70 Ni - 30 Cu

In order to observe the behavior of $R_o$ both above and below the Curie temperature in another ferromagnetic metal, measurements were made on Driver-Harris Lucero, a 70 Ni-30 Cu alloy. The choice of this alloy was suggested by its availability in thin sheet (0.005 inch) permitting reasonably large voltages to be observed with the available current, its low saturation magnetization permitting the linear region of the $V_H$, $H$ curve to be examined with the available magnetic field (12,400 oersteds), and its relatively
FIG. 4–3 THE HALL VOLTAGE AS A FUNCTION OF APPLIED MAGNETIC FIELD FOR GRADE A NL AT TEMPERATURES ABOVE THE CURIE TEMPERATURE. SAMPLE THICKNESS, $t = .005$ INCHES; $I = 1$ AMP.; $T_c = 358^\circ$C
FIG. 4-4 THE VALUES OF $R_o$ OBSERVED ABOVE THE CURIE TEMPERATURE AS A FUNCTION OF $\frac{1}{T-\theta}$ FOR GRADE A Ni. $\theta = 374^\circ C$
**TABLE 4-1**

**SOME PHYSICAL PROPERTIES OF GRADE A Ni**

**At 27°C**

<table>
<thead>
<tr>
<th>Property</th>
<th>Value</th>
</tr>
</thead>
<tbody>
<tr>
<td>The density</td>
<td>$d = 8.885 \text{ gm/cm}^3$</td>
</tr>
<tr>
<td>The number of atoms/cm$^3$</td>
<td>$n_o = 9.12 \times 10^{22}/\text{cm}^3$</td>
</tr>
<tr>
<td>The ordinary Hall coefficient</td>
<td>$R_o = -6.02 \times 10^{-13} \text{ volt-cm/amp-oersted}$</td>
</tr>
<tr>
<td>The effective number of electrons/cm$^3$</td>
<td>$N^* = 1.04 \times 10^{23}/\text{cm}^3$</td>
</tr>
<tr>
<td>The effective number of electrons/atom</td>
<td>$n^* = 1.14/\text{atom}$</td>
</tr>
<tr>
<td>The extraordinary Hall coefficient (corrected)</td>
<td>$R'_1 = -1.23 \times 10^{-10} \text{ volt-cm/amp-gauss}$</td>
</tr>
<tr>
<td>The saturation magnetization</td>
<td>$M_s = 474.5 \text{ gauss}$</td>
</tr>
<tr>
<td>The resistivity</td>
<td>$\rho = 8.88 \times 10^{-6} \text{ ohm-cm}$</td>
</tr>
</tbody>
</table>

**At 568°C**

<table>
<thead>
<tr>
<th>Property</th>
<th>Value</th>
</tr>
</thead>
<tbody>
<tr>
<td>The density</td>
<td>$d = 8.68 \text{ gm/cm}^3$</td>
</tr>
<tr>
<td>The number of atoms/cm$^3$</td>
<td>$n_o = 8.91 \times 10^{22}/\text{cm}^3$</td>
</tr>
<tr>
<td>The ordinary Hall coefficient (observed)</td>
<td>$R_o = -8.40 \times 10^{-13} \text{ volt-cm/amp-oersted}$</td>
</tr>
<tr>
<td>The effective number of electrons/cm$^3$ deduced from the observed value of $R_o$</td>
<td>$N^* = 7.44 \times 10^{22}/\text{cm}^3$</td>
</tr>
<tr>
<td>The effective number of electrons/atom deduced from the observed value of $R_o$</td>
<td>$n^* = 0.84/\text{atom}$</td>
</tr>
<tr>
<td>The atomic weight</td>
<td>$W = 58.69 \text{ gm/mole}$</td>
</tr>
<tr>
<td>The saturation magnetization at 0°C</td>
<td>$M_o = 508.8 \text{ gauss}$</td>
</tr>
<tr>
<td>The ferromagnetic Curie temperature</td>
<td>$T_c = 358°C$</td>
</tr>
<tr>
<td>The paramagnetic Curie temperature</td>
<td>$\theta = 374°C$</td>
</tr>
<tr>
<td>The number of Bohr magnetons in the ferromagnetic region</td>
<td>$\beta = 0.61/\text{atom}$</td>
</tr>
<tr>
<td>The number of Bohr magnetons in the paramagnetic region deduced from susceptibility measurements</td>
<td>$\beta = 0.87/\text{atom}$</td>
</tr>
</tbody>
</table>
low Curie temperature (42°C) permitting easy access to the paramagnetic region. In order to determine the value of $R_\circ$ below the Curie temperature in this material, a measurement was made at liquid-air temperature, approximately 235°C below $T_c$. Figure 4-6 shows the curve of $V_H$ as a function of applied magnetic field, $H$, for the 70 Ni-30 Cu alloy at liquid-air temperature. The enlarged view shows the high field slope from which a value of $R_\circ = -15.5 \times 10^{-13} \text{ volt-cm/amp-oersted}$ is obtained.

Figure 4-7 shows the $V_H$, $H$ curves in the paramagnetic region for this material. A similar decrease of slope with increase of temperature is observed, as in Ni. The values of $R_\circ$ observed above 115°C are for the most part smaller than the value of $R_\circ$ observed at -195°C. The value of $R_\circ$ observed at 381°C is $R_\circ = -10.9 \times 10^{-13} \text{ volt-cm/amp-oersted}$. Figure 4-8 shows the values of $R_\circ$ observed above the Curie temperature plotted as a function of $\frac{1}{T-\theta}$, where $\theta = 52^\circ$C. The value of $R_\circ$ obtained by extrapolating this curve to infinite temperature is $R_\circ = -9.8 \times 10^{-13} \text{ volt-cm/amp-oersted}$. We note that the unknown temperature dependence of $R_1$ will tend to alter the slope of the curve, and probably tend to decrease the absolute value of $R_\circ$ thus obtained. Therefore, the value of $R_\circ$ deduced above the Curie temperature is only an approximate value, but it is definitely smaller in absolute value than the value observed at -195°C.

The convenient system in which to examine this effect is the Ni-Cu alloy series, because of low saturation magnetization, low Curie temperature, solid solubility without phase change in the entire series, and the existence of a large amount of experimental data on their electric and magnetic properties. At the time this work was performed, it was learned that low-temperature Hall measurements were being made at Carnegie Institute of Technology on this series of alloys. Therefore, in order not to duplicate this work, and because the main purpose of this research was not an examination of the Ni-Cu series, no further measurements were made.

Listed below in Table 4-2 are some of the physical properties of 70 Ni - 30 Cu to be used in the following discussions.
4.2 Discussion of the Experimental Results

(A) The Two-Band Model

(1) Ni. The data are analyzed in terms of the effective number of conduction electrons/atom, $n^*$, where

$$n^* = \frac{N^*}{n_o} \quad (4.1)$$

and $N^*$ is obtained from

$$N^* = \frac{10^{-8}}{R_o e L} \quad (4.2)$$

where $R_o$ is in units of $\text{volt-cm/amp-oersted}$, and $e_L = -1.60 \times 10^{-19} \text{ coulombs}$. The number of atoms/cm$^3$, $n_o$, is obtained from

$$n_o = \frac{A d}{W} \quad (4.3)$$

where $A$ is Avogadros number, $A = 6.025 \times 10^{23} \text{ mole}^{-1}$, $d$ is the density of the material in $\text{gm/cm}^3$, and $W$ is the atomic weight. From the room temperature Ni data, we obtain a value of $n^* = 1.14 \text{ electrons/atom}$.

If we employ a simple band model [49] for Ni, the 10 electrons of the free atom which are in a 3$d^8$4$s^2$ state, are redistributed over four bands, two 3$d$ bands and two 4$s$ bands in the solid state (ref. 12, p.435). The two 3$d$ bands are shifted in energy by an amount proportional to the exchange interaction in such a manner [50] that one 3$d$ band with spins parallel is completely filled with electrons at $0^\circ K$ and the other 3$d$ band with spins antiparallel has 0.6 vacancies or holes/atom. Since each 3$d$ band holds five electrons/atom, there is an excess of 0.6 spins/atom in the parallel direction, providing 0.6 Bohr magnetons/atom in Ni$^+$. Figure 4-9 shows a simple picture of this band scheme with no attempt made to draw the correct band shape or energy separation. Mott [51] was the first to suggest such a band arrangement, and Slater [52], has made semiquantitative calculations on this model.

Since there are 9.4 electrons/atom in the two 3$d$ bands, the remaining 0.6 electrons/atom are distributed equally in the 4$s$ bands. Both the 0.6 4$s$ electrons/atom and the 0.6 3$d$ holes/atom can contribute to the electric

*In this simple model we neglect a 10 per cent correction of the orbital motion to the total magnetic moment and hence the number of d holes is about 10 per cent too large.
FIG. 4-7 THE HALL VOLTAGE AS A FUNCTION OF APPLIED MAGNETIC FIELD FOR 70 Ni-30 Cu AT TEMPERATURES ABOVE THE CURIE TEMPERATURE. SAMPLE THICKNESS, t=.0055 INCHES; I=1 AMP; $T_c=42^\circ$C
FIG. 4-8 THE VALUES OF $R_0$ OBSERVED ABOVE THE CURIE TEMPERATURE AS A FUNCTION OF $\frac{1}{T-\theta}$ FOR 70 Ni–30 Cu. $\theta \approx 52^\circ$C.
<table>
<thead>
<tr>
<th>Physical Property</th>
<th>Value</th>
</tr>
</thead>
<tbody>
<tr>
<td><strong>Table 4-2</strong>&lt;br&gt;SOME PHYSICAL PROPERTIES OF 70 Ni - 30 Cu&lt;br&gt;<strong>At -195°C</strong>&lt;br&gt;The density</td>
<td>$d = 8.99 \text{ gm/cm}^3$</td>
</tr>
<tr>
<td>The number of atoms/cm$^3$</td>
<td>$n_o = 9.00 \times 10^{22} \text{ /cm}^3$</td>
</tr>
<tr>
<td>The ordinary Hall coefficient</td>
<td>$R_o = -15.5 \times 10^{-13} \text{ volt-cm/amp-oersted}$</td>
</tr>
<tr>
<td>The effective number of electrons/cm$^3$</td>
<td>$N* = 4.03 \times 10^{22} \text{ /cm}^3$</td>
</tr>
<tr>
<td>The effective number of electrons/atom</td>
<td>$n* = 0.45/\text{atom}$</td>
</tr>
<tr>
<td>The extraordinary Hall coefficient</td>
<td>$R_1 = -3 \times 10^{-10} \text{ volt-cm/amp-gauss}$</td>
</tr>
<tr>
<td><strong>At 381°C</strong>&lt;br&gt;The density</td>
<td>$d = 8.79 \text{ gm/cm}^3$</td>
</tr>
<tr>
<td>The number of atoms/cm$^3$</td>
<td>$n_o = 8.80 \times 10^{22} \text{ /cm}^3$</td>
</tr>
<tr>
<td>The ordinary Hall coefficient (observed)</td>
<td>$R_o = -10.9 \times 10^{-13} \text{ volt-cm/amp-oersted}$</td>
</tr>
<tr>
<td>The effective number of electrons/cm$^3$ obtained from the observed value of $R_o$</td>
<td>$N* = 5.73 \times 10^{22} \text{ /cm}^3$</td>
</tr>
<tr>
<td>The effective number of electrons/atom obtained from the observed value of $R_o$</td>
<td>$n* = 0.65/\text{atm}$</td>
</tr>
<tr>
<td>The extrapolated value of $R_o$ above the Curie temperature</td>
<td>$R_o = -9.8 \times 10^{-13} \text{ volt-cm/amp-oersted}$</td>
</tr>
<tr>
<td>The effective number of electrons/cm$^3$ obtained from the extrapolated values of $R_o$</td>
<td>$N* = 6.5 \times 10^{22} \text{ /cm}^3$</td>
</tr>
<tr>
<td>The effective number of electrons/atom obtained from the extrapolated value of $R_o$ and the value of $n_o$ at 381°C</td>
<td>$n* \approx 0.7/\text{atom}$</td>
</tr>
<tr>
<td>The atomic weight</td>
<td>$W = 60.15 \text{ gm/mole}$</td>
</tr>
<tr>
<td>The ferromagnetic Curie temperature obtained from resistivity data [see Fig. 6-1]</td>
<td>$T_c = 42°C$</td>
</tr>
<tr>
<td>The paramagnetic Curie temperature</td>
<td>$\theta \approx 52°C$</td>
</tr>
<tr>
<td>The number of Bohr magnetons in the ferromagnetic region</td>
<td>$\beta \approx 0.3/\text{atom}$</td>
</tr>
</tbody>
</table>
A SIMPLE BAND MODEL FOR Ni,

FIG. 4-9
current. However, specific heat measurements [see 26, p. 157] indicate that the 3d holes have a large effective mass compared to the 4s electrons, and hence a low mobility. We would expect, therefore, that the major contribution to the current, and hence to the ordinary Hall coefficient, \( R_d \) would come from the 0.6 4s electrons. The value of \( n^* = 1.14 \text{ electrons/atom} \) is approximately twice the number we expect. A value of \( n^* \) greater than 0.6 can be explained by assuming that the 0.6 3d holes contribute to the electric current and hence to \( R_o \).

In order to take account of the hole contribution to \( R_o \), we utilize the two-band formula for the Hall coefficient [see 10] normalized with respect to \( n_o \), the number of atoms/cm\(^3\), and obtain

\[
\frac{1}{n^*} = \frac{1}{n_s} \left( \frac{\sigma_s}{\sigma} \right)^2 - \frac{1}{n_d} \left( \frac{\sigma_d}{\sigma} \right)^2
\]

(4.4)

where \( n_s = \frac{N_s}{n_o} \) is the number of s electrons/atom, and \( n_d = \frac{N_d}{n} \) is the number of d holes/atom. If we assume that both 0.6 4s electrons and 0.6 3d holes contribute to \( n^* \), and substitute \( n_s = n_d = 0.6 \) into Eq. (4.4) and make use of the fact that

\[
\sigma = \sigma_s + \sigma_d,
\]

(4.5)

we obtain

\[
\frac{\sigma_s}{\sigma_d} = 3.2 \quad \text{and} \quad \frac{\sigma_d}{\sigma} = 0.24,
\]

(4.6)

a result which has been previously obtained by Pugh, Rostoker, and Schindler [10].

From the observed value of \( R_o \) at 568°C a value of \( n^* = 0.84 \) electrons/atom is deduced. If we analyze these data using Eq. (4.4) and retain \( n_s = n_d = 0.6 \), we obtain

\[
\frac{\sigma_s}{\sigma_d} = 6.0 \quad \text{and} \quad \frac{\sigma_d}{\sigma} = 0.14
\]

(4.7)

The simple band model discussed above and shown in Fig. 4-9 provides a means of accounting for the distribution of electrons in the Ni-Cu alloy series consistent with magnetization results. Cu with 29 electrons/atom has 1 more electron/atom than Ni. As the percent Ni in Cu increases from zero to 40 per cent, the number of 4s electrons/atom, \( n_s \), decreases from 1.0 to 0.6. There are no 3d holes throughout this
range and hence ferromagnetism is not observed. As the Ni content is increased beyond 40 per cent, the 3d band with antiparallel spins begins to empty while the number of 4s electrons remains constant at 0.6. Between 40 per cent Ni and 100 per cent Ni, there is a linear increase in Bohr magneton number corresponding to the linear decrease of 3d antiparallel electrons. For each 0.1 electrons removed, an increase of 0.1 Bohr magnetons is observed. We therefore expect that the 70 Ni - 30 Cu alloy with 0.3 Bohr magnetons and with 10.3 electrons/atom outside of the closed Argon configuration will have 0.3 3d holes/atom and 0.6 4s electrons/atom. Thus, on the basis of this simple model, at temperatures well below the Curie temperature, we would expect that \( n^* \) would have a minimum value of approximately 0.6 or a value somewhat larger if hole contributions were present. From the liquid-air temperature data, we obtain a value of \( n^* = 0.45 \) electrons/atom. Equation (4.4) cannot be used to explain this departure from 0.6 electrons/atom.

From the value of \( R_o \) observed at 381°C, we obtain a value of \( n^* = 0.65 \) electrons/atom and from the value of \( R_o \) extrapolated at infinite temperature, we obtain a value \( n^* \approx 0.7 \) electrons/atom. These values of \( n^* \) are approximately the value we expect from the above model.

(B) Pugh's Four-Band Model

Mott [53] has suggested that the major contribution to the resistivity of Ni comes about from s-d scattering. Since electrons are scattered mostly with spin conservation, the 4s electrons with parallel spin can not be scattered into 3d holes at low temperatures, since holes exist only in the antiparallel 3d band. The 4s electrons with antiparallel spin can, on the other hand, be scattered into 3d holes, and it is this scattering which predominates. Thus, at low temperatures, the current is carried mostly by one half of the 4s electrons, those with parallel spin. At higher temperatures, the number of holes in the parallel 3d band increases so that the 4s electrons with parallel spin are increasingly scattered. With this idea, Mott has been able to account for the difference in shape of the \( \rho, T \) curve of Ni compared with a similar nonmagnetic transition metal (Pd).
Using the same hypothesis, Pugh [54, 55] has qualitatively explained the results of low-temperature Hall measurements on the Ni-Cu series made by Cohen [56]. Pugh suggests that as Ni is added to Cu, the value of n* decreases from the value obtained in Cu (n* ≠ 1 in Cu for reasons not very well understood) to a value of n* = 0.6 at 40 per cent Ni. This decrease of n*, corresponding to an increase of the absolute value of R o, has been observed by Cohen and is shown in Fig. 4-10, taken from Pugh's Final Report [54]. The value of n* at 40 per cent Ni is near 0.6 electrons/atom. As the concentration of Ni is increased from 40 per cent, the number of holes in the antiparallel 3d band increases from zero at 40 per cent Ni to 0.6 at 100 per cent Ni. Since the Mott scattering is roughly proportional to the cube root of the number of d holes, Pugh suggests that the increase of scattering with the increase of the number of holes in the antiparallel d-band will result in a decreasing contribution to the conductivity from the 0.3 4s electrons with antiparallel spin. Pugh then proposes a four-band model which treats all four bands independently. With this model, n* is given by

\[ \frac{1}{n^*} = \frac{1}{n_1} \left( \frac{\sigma_1}{\sigma} \right)^2 + \frac{1}{n_2} \left( \frac{\sigma_2}{\sigma} \right)^2 - \frac{1}{n_3} \left( \frac{\sigma_3}{\sigma} \right)^2 - \frac{1}{n_4} \left( \frac{\sigma_4}{\sigma} \right)^2, \]  

(4.8)

where n_1 and n_2 are the number of 4s electrons with spin parallel and antiparallel, and n_3 and n_4 are the number of holes in the parallel and antiparallel 3d band. The \( \sigma_i \) are the corresponding conductivities.

At very low temperatures there are no holes throughout the series in the parallel 3d band and therefore n_3 = \( \sigma_3 = 0 \). In order to account for values of n* less than 0.6, and in particular in order to account for a value of n* = 0.3 at 80 per cent Ni, Pugh assumes that between 40 per cent Ni and 80 per cent Ni in Cu, hole contributions are relatively unimportant. Thus, with the assumption that \( \sigma_3 << 1 \), and \( \sigma_3^3 = 0 \), Eq. (4.8) reduces to

\[ \frac{1}{n^*} = \frac{1}{n_1} \left( \frac{\sigma_1}{\sigma} \right)^2 + \frac{1}{n_2} \left( \frac{\sigma_2}{\sigma} \right)^2, \]  

(4.9)

where n_1 = n_2 = 0.3 for the ferromagnetic Ni-Cu alloys. Now as the Ni...
content is increased from 40 per cent to 80 per cent, the decrease of $n^*$ from 0.6 to 0.3 can be accounted for by assuming that $\sigma_2$ varies from $1/2$ to zero (actually to $\sigma_2 \ll \sigma_1$) as the 4s electrons with antiparallel spin are increasingly scattered. As the temperature is increased, holes appear in the parallel 3d band, i.e., $n_3 \neq 0$. This model then indicates that the ratio $\sigma_1$ will approach $\sigma_2$ at high temperatures with an increase of $n^*$ with increase of temperature. This has been observed by Cohen.

At temperatures above the Curie temperature, there are presumably equal numbers of holes in both 3d bands and we expect $\sigma_1 = \sigma_2$. Under this condition, with no hole contributions, we would expect to obtain a value of $n^* = 0.6$ in the range between 40 per cent and 80 per cent Ni. The value of $n^*$ of the order of 0.6 observed in this research for 70 Ni - 30 Cu at $T > T_C$ fits this model.

The value of $n^* = 0.45$ electrons/atom obtained at liquid-air temperature for 70 Ni - 30 Cu is not in very good agreement with Cohen's data, as is shown in Fig. 4-10. The deviation is considerably greater than the experimental error. However, the value of $n^* = 0.45$ electrons/atom is still allowable with Pugh's model.

Thus, the four-band model can qualitatively account for the observed values of $n^*$ less than 0.6 in the range from 40 per cent to 80 per cent Ni, and does suggest a reason for the observed temperature dependence of $R_o$ in this alloy range. In order to account for the decrease in the absolute value of $R_o$ between 80 per cent and 100 per cent Ni, Pugh suggests that hole contributions become increasingly important in these concentrations. Analysis of the room temperature Ni data using Eq. (4.8) and assuming that only one half of the 4s electrons contribute to the current, and assuming $n_3 = 0$, suggests that $\sigma_d = 0.41$. Thus, the four-band model indicates an even larger d hole contribution to the current than the two-band model.

Furthermore, the relatively constant values of $R_o$ observed by Cohen between 4.2°K and 300°K, and observed in this research between 300°K and 500°K require that the contributions from the d holes compensate the temperature dependence of the s-d scattering which produces a temperature-dependent $R_o$ in the other ferromagnetic Ni-Cu alloys. Above the Curie temperature, the analysis of the Ni data with the four-band model is identical
FIG. 4-10 $R_0$ AS A FUNCTION OF COMPOSITION FOR Ni–Cu ALLOYS. DATA TAKEN FROM PUGH'S FINAL REPORT. VALUES FOR GRADE A Ni AND 70 Ni–30 Cu SUPERPOSED.
to that using the two-band model.

(C) **Concluding Remarks**

The above band models for discussing the 3d transition metals are a very crude picture of the true situation. The main justification for their use here, is that it permits a simple qualitative discussion of the observed effects. A more rigorous treatment of the collective electron or band model of the 3d transition elements has been given by Stoner [57, 58, 59] and improved upon by Wohlfarth [60]. While this treatment permits analysis of magnetization data below \( T_c \), susceptibility data above \( T_c \), and specific heat data, and does correlate much information about the ferromagnetic metals, it offers no simple framework within which to treat the conduction properties of these materials. One aspect of the Stoner-Wohlfarth treatment should be pointed out in connection with the high-temperature Hall data. This concerns the transfer effect described by Wohlfarth [60, 61] for Ni and for Ni-Cu alloys which involves a redistribution of electrons over both the s and d bands such that the number of 4s electrons increases at high temperatures and hence the number of 3d holes also increases. Wohlfarth has used this mechanism to account for the curvature of the reciprocal of the susceptibility-versus-T data observed at high temperatures, especially in Ni. The transfer effect suggests a very small increase in the value of \( n^* \) with increase of temperature.

Analysis of the room-temperature Ni data with either the two-band or four-band model indicates a rather large contribution to the conductivity from the d holes. As pointed out by Wilson [62], the large effective mass of the d holes should result in a small contribution to the current from the d holes compared with that of the s electrons. Thus the analyses presented above are not in complete agreement with the evidence from specific heat data. In this respect, Brooks [63] has suggested the possibility that perhaps one of the degenerate sub-d bands of Ni is a low-density band with a low effective mass for holes and hence a high mobility. A simple analysis then suggests that the contribution of the d holes may be more heavily weighted, perhaps by a factor of 2, in the determination of \( R_0 \) than in the determination of \( \sigma \).
The lack of temperature dependence of $R_0$ in Ni observed from $4.2^\circ K$ to $500^\circ K$ is not by itself surprising. One would expect that a measurement involving the density of electrons in a metal would be fairly temperature-independent. However, the behavior of Ni is completely different from the behavior of the other ferromagnetic Ni-Cu alloys, as observed by Cohen. This may then suggest that fundamental changes in the electronic structure of Ni occur with Cu alloying.

Although an exact value of $R_0$ in Ni above the Curie temperature cannot be deduced from the observed results, the failure of the data above $528^\circ C$ to follow a $1/(T-B)$ dependence may suggest that $R_0$ is changing in this temperature region. If, on the other hand, the value of $R_0$ observed in this region represents the true value of $R_0$, then the value of $n^*$ deduced from $R_0$, $n^* = 0.84$ electrons/atom, is close to the value of 0.87 electrons/atom deduced from susceptibility data [see 12, p. 433].

The data observed for the 70 Ni-30 Cu alloy very definitely indicate different values of the ordinary Hall coefficient above and below the Curie temperature. While the simple model suggested by Pugh does give a qualitative explanation of the data, a more exact analysis awaits a more detailed theoretical examination of the electrical properties of the transition metals.

The ordinary Hall coefficient observed in the ferromagnetic transition elements and alloys may ultimately provide an additional source of information about electron densities in these materials. However, the present state of the theory of the ordinary Hall coefficient in metals does not permit reliable interpretation of these data.
V.

THE ORDINARY HALL MEASUREMENTS ON THE FERRITES

5.1 The Experimental Results

(A) Fe$_3$O$_4$

The sample of Fe$_3$O$_4$ used in this research was grown by J. Smiltens [46], and was one of the first large synthetic ferrite crystals grown. With respect to stoichiometry and impurities, it was substantially better than natural crystals. It was not, however, a single crystal, but was composed of several large grains. Figure 5-1 is a photograph of the sample, after etching in HCl.

It has been shown in Chapter II that the ordinary Hall measurement on Fe$_3$O$_4$ is considerably more difficult than the measurement on Ni. Because of the small signal-to-noise ratio and because of temperature fluctuations, there was a large spread in the observed values of Hall voltage. No resolution of the Hall voltage, as a function of applied magnetic field, was obtained above saturation because the ratio of the spread to the average value of the observed voltage was large. Thus, the value of $R_\circ$ is deduced from a two-point measurement. In addition to the uncertainty in the measured voltage, there may be large uncertainty in the value of $R_\circ$ deduced from this voltage because of the change of magnetization in the region of measurement. This effect is discussed more fully in Appendix B. The effect of the change of magnetization above saturation makes the apparent value of $R_\circ$ too large. Thus the measured value represents an upper limit of the true value of $R_\circ$ and provides a lower limit to the charge carrier density provided that all the carriers are electrons.

The average value of 31 independent voltage measurements on the cylindrical sample, $d = 0.25$ inch, $l = 0.50$ inch, was $\Delta V_H = -5.04 \times 10^{-8}$ volts, for $\Delta H = 5000$ oersteds. The uncertainty in the measured voltage is estimated to be about 10 per cent. The sample current was 300 ma. Taking into account the correction [64] for a length-to-width ratio less than 4, the value of $R_\circ$ deduced from this voltage is $R_\circ = -1.80 \times 10^{-11}$ volt-cm$^4$ amp-oersted.
The value of $N^*$, the effective number of conduction electrons/cm$^3$, obtained from the relation

$$R_o = \frac{10^{-8}}{N^* e \rho_L}$$  \hspace{1cm} (5.1)

where $e_L = -1.60 \times 10^{-19}$ coulombs, is $N^* = 3.47 \times 10^{21}$ electrons/cm$^3$. Thermoelectric power measurements [see Fig. 6-13] also indicate that the sign of the carrier is negative. Figure 5-2 shows the curve of Hall voltage as a function of applied magnetic field at room temperature for this sample.

The upper limit of the room temperature Hall mobility, obtained from the relation

$$\mu_L = R_o \sigma 10^{+8},$$  \hspace{1cm} (5.2)

where $\sigma = 250$ (ohm-cm)$^{-1}$, is $\mu_L = 0.450$ cm$^2$/volt-sec.

Listed below are some of the physical properties of Fe$_3$O$_4$ sample No. 18 grown by J. Smiltens. All temperature-dependent values are room temperature (300$^\circ$K) values unless otherwise stated.

(B) (Ni$_{0.75}$Fe$_{0.25}$)$_{304}$

The sample of (Ni$_{0.75}$Fe$_{0.25}$)$_{304}$ was obtained from the Linde Air Products Company and was a single crystal. The measurements on this sample were subject to less uncertainty than in the case of Fe$_3$O$_4$ because the signal-to-noise ratio was larger. Figure 5-3 shows the curve of the Hall voltage as a function of applied magnetic field at room temperature for this sample. The estimated uncertainty in the values of voltage measured above saturation is 6.3 per cent. The value of $R_o$ deduced from the differential measurement is $R_o = -1.40 \times 10^{-10}$ volt-cm/amp-oersted. The uncertainty in $R_o$ due to the change of magnetization is probably small. The value of $N^*$ obtained from $R_o$ is $N^* = 4.46 \times 10^{20}$ electrons/cm$^3$. The room-temperature Hall mobility is calculated to be $\mu_L = 0.0476$ cm$^2$/volt-sec.

Listed below are some of the physical properties of Linde Air Products Company sample 8/18/52 A, (Ni$_{0.75}$Fe$_{0.25}$)$_{304}$. All temperature-dependent values are room-temperature (300$^\circ$K) values unless otherwise stated.
<table>
<thead>
<tr>
<th>Property</th>
<th>Value</th>
</tr>
</thead>
<tbody>
<tr>
<td>The density (20°C)</td>
<td>$d = 5.185$ gm/cm$^3$</td>
</tr>
<tr>
<td>The molecular weight</td>
<td>$w = 231.55$ gm/mole</td>
</tr>
<tr>
<td>The number of molecules/cm$^3$</td>
<td>$n_0 = 1.35 \times 10^{22}$/cm$^3$</td>
</tr>
<tr>
<td>The conductivity</td>
<td>$\sigma = 250$ (ohm-cm)$^{-1}$</td>
</tr>
<tr>
<td>The activation energy obtained from conductivity data below room temperature</td>
<td>$E = 0.039$ electron volts</td>
</tr>
<tr>
<td>The upper limit of the ordinary Hall coefficient</td>
<td>$R_o = -1.80 \times 10^{-11}$ volt-cm/amp-oersted</td>
</tr>
<tr>
<td>The lower limit of the effective number of electrons/cm$^3$ obtained from $R_o$</td>
<td>$N^* = 3.47 \times 10^{21}$/cm$^3$</td>
</tr>
<tr>
<td>The lower limit of the effective number of electrons/Fe$_3$O$_4$ molecule</td>
<td>$n^* = 0.257$/molecule</td>
</tr>
<tr>
<td>The upper limit of the Hall mobility</td>
<td>$\mu_L = 0.450$ cm$^2$/volt-sec</td>
</tr>
<tr>
<td>The extraordinary Hall coefficient</td>
<td>$R_1 = -3.28 \times 10^{-8}$ volt-cm/amp-gauss</td>
</tr>
<tr>
<td>The saturation magnetization at 0 K</td>
<td>$M_0 = 510$ gauss</td>
</tr>
<tr>
<td>The saturation magnetization</td>
<td>$M_s = 472.3$ gauss</td>
</tr>
<tr>
<td>The Curie temperature</td>
<td>$T_c = 574^\circ$C</td>
</tr>
<tr>
<td>The transition temperature</td>
<td>$T = -153.8^\circ$C</td>
</tr>
</tbody>
</table>
FIG. 5-1  A PHOTOGRAPH OF THE Fe$_3$O$_4$ SAMPLE AFTER ETCHING
Fig. 5-2. The Hall voltage as a function of applied magnetic field for Fe$_3$O$_4$ at room temperature.
FIG. 5-3 THE HALL VOLTAGE AS A FUNCTION OF APPLIED MAGNETIC FIELD FOR \((\text{NiO})_{0.75}(\text{FeO})_{0.25}\) 
\((\text{Fe}_2\text{O}_3)\) AT ROOM TEMPERATURE. SAMPLE THICKNESS, \(t = .100 \text{ INCHES}\); \(I = 200 \text{ MA}\)
TABLE 5-2
SOME PHYSICAL PROPERTIES OF \((\text{NiO})_{0.75}(\text{FeO})_{0.25}(\text{Fe}_2\text{O}_3)\)

<table>
<thead>
<tr>
<th>Property</th>
<th>Value</th>
</tr>
</thead>
<tbody>
<tr>
<td>The density</td>
<td>(d = 5.35 \text{ gm/cm}^3)</td>
</tr>
<tr>
<td>The molecular weight</td>
<td>(w = 233.68 \text{ gm/mole})</td>
</tr>
<tr>
<td>The number of molecules/cm(^3)</td>
<td>(n_o = 1.38 \times 10^{22}/\text{cm}^3)</td>
</tr>
<tr>
<td>The conductivity</td>
<td>(\sigma = 3.40 \text{ (ohm-cm)}^{-1})</td>
</tr>
<tr>
<td>The activation energy obtained from conductivity data below room temperature</td>
<td>(E = 0.078 \text{ electron volts})</td>
</tr>
<tr>
<td>The ordinary Hall coefficient</td>
<td>(R_o = -1.40 \times 10^{-10} \frac{\text{volt-cm}}{\text{amp-oe} \text{rsted}})</td>
</tr>
<tr>
<td>The effective number of electrons/cm(^3) obtained from (R_o)</td>
<td>(N^* = 4.46 \times 10^{20}/\text{cm}^3)</td>
</tr>
<tr>
<td>The effective number of electrons/(\text{Fe}_3\text{O}_4) molecule</td>
<td>(n^* = 0.129/\text{molecule})</td>
</tr>
<tr>
<td>The Hall mobility</td>
<td>(\mu_L = 0.0476 \text{ cm}^2/\text{volt-sec})</td>
</tr>
<tr>
<td>The extraordinary Hall coefficient</td>
<td>(R_1 = -16.4 \times 10^{-8} \frac{\text{volt-cm}}{\text{amp-gauss}})</td>
</tr>
<tr>
<td>The saturation magnetization at 0°K</td>
<td>(M_o = 338 \text{ gauss})</td>
</tr>
<tr>
<td>The saturation magnetization</td>
<td>(M_s = 308 \text{ gauss})</td>
</tr>
<tr>
<td>The Curie temperature</td>
<td>(T_c = 597°\text{C})</td>
</tr>
</tbody>
</table>

(The sample of \((\text{NiO})_{0.56}(\text{ZnO})_{0.14}(\text{FeO})_{0.30}(\text{Fe}_2\text{O}_3)\) was obtained from the Linde Air Products Company and was also a single crystal. No Hall measurements were made on this sample, but the resistivity was measured as a function of temperature. Some of the physical properties of Linde Air Products Company crystal 6/12/53 D, \((\text{NiO})_{0.56}(\text{ZnO})_{0.14}(\text{FeO})_{0.30}(\text{Fe}_2\text{O}_3)\), at room temperature (300°K) are listed below.)
TABLE 5-3

SOME PHYSICAL PROPERTIES OF (NiO)\textsubscript{0.56}(ZnO)\textsubscript{0.14}(FeO)\textsubscript{0.30}(Fe\textsubscript{2}O\textsubscript{3})

<table>
<thead>
<tr>
<th>Property</th>
<th>Value</th>
</tr>
</thead>
<tbody>
<tr>
<td>The density</td>
<td>(d = 5.24 \text{ gm/cm}^3)</td>
</tr>
<tr>
<td>The molecular weight</td>
<td>(w = 234.49 \text{ gm/mole})</td>
</tr>
<tr>
<td>The number of molecules/cm(^3)</td>
<td>(n_o = 1.35 \times 10^{22}/\text{cm}^3)</td>
</tr>
<tr>
<td>The conductivity</td>
<td>(\sigma = 6.67 \text{ (ohm-cm)}^{-1})</td>
</tr>
<tr>
<td>The activation energy obtained from the conductivity data below room temperature</td>
<td>(E = 0.066 \text{ electron volt})</td>
</tr>
</tbody>
</table>

5.2 Discussion of the Experimental Results

(A) \textit{Fe}_3\textit{O}_4

The number of molecules/cm\(^3\) in \textit{Fe}_3\textit{O}_4 at room temperature is \(n_o = 1.35 \times 10^{22}/\text{cm}^3\). On the basis of Verwey's simple picture of one electron per \textit{Fe}_3\textit{O}_4 molecule contributing to the current, we expect a value of \(N^*\) close to \(n_o\). The value of \(N^*\) observed, \(N^* = 3.47 \times 10^{21}/\text{cm}^3\), represents a lower limit of the true value of \(N^*\) and is about 1/4 the value of \(n_o\). Thus, unless the small value of \(R_o\) is due to partial compensation by carriers of opposite sign, the observed value of \(N^*\) suggests a large carrier density roughly in accord with Verwey's hypothesis.

The conductivity of synthetic single crystals of \textit{Fe}_3\textit{O}_4 grown by Smiltens has been measured by Calhoun [18]. Between -100°C and 200°C, the conductivity data have been fitted by the equation

\[
\sigma = AT^{-3/2} e^{-E/kT},
\]

where \(E = 0.039 \text{ electron volts}\). If we rewrite Eq. (5.3)

\[
\sigma = n_o e^{-E/kT} e_L\mu_L(T) = n e_L\mu_L(T)
\]

where \(e_L\) is the charge of the electron, \(\mu_L(T)\) is the temperature-dependent mobility, then \(n\), the number of electrons/cm\(^3\) contributing to the conductivity
is given by

\[ n = n_0 e^{-E/kT} \]  \hspace{1cm} (5.5)

If we insert the value of \( n_0 = 1.35 \times 10^{22}/\text{cm}^3 \) and \( E = 0.039 \) electron volts, at room temperature we obtain \( n = 2.98 \times 10^{21}/\text{cm}^3 \), in good agreement with \( N^* = 3.47 \times 10^{21}/\text{cm}^3 \).

\[ (B) \quad \text{(NiO)}_{0.75}\text{(FeO)}_{0.25}\text{(Fe}_2\text{O}_3) \]

The resistivity of stoichiometric NiOFe\(_2\)O\(_3\) is greater than \( 10^6 \) ohm-cm. In NiOFe\(_2\)O\(_3\) the ions in the octahedral sites are not identical, and hence the distribution of electrons on the octahedral ions is not random. Because of its low conductivity, we may assume that the Ni\(^{2+}\) ion does not readily contribute an electron to the conduction process.

In the sample of (NiO)\(_{0.75}\)Fe\(_0\)\(_{0.25}\)Fe\(_2\)O\(_3\), however, 1/4 of the molecules are Fe\(_3\)O\(_4\) molecules. Therefore, on the basis of the simple Verwey model we would expect a number of electrons equal to the number of Fe\(_3\)O\(_4\) molecules in this sample. The value of \( n_0 \) of this sample is \( n_0 = 1.38 \times 10^{22}/\text{cm}^3 \), and the number of Fe\(_3\)O\(_4\) molecules is \( 3.45 \times 10^{21}/\text{cm}^3 \). The observed value of \( N^* = 4.46 \times 10^{20}/\text{cm}^3 \) is roughly 1/10 of the number of Fe\(_3\)O\(_4\) molecules. However, if we calculate a value of \( n \) using Eq. (5.5) with a value of \( E = 0.078 \) electron volts derived from conductivity data [see Fig. 5.4] we obtain,

\[ n = \frac{n_0}{4} e^{-E/kT} = 1.68 \times 10^{20}/\text{cm}^3, \]  \hspace{1cm} (5.6)

which is roughly 1/3 of the observed value of \( N^* \).

In the case of Fe\(_3\)O\(_4\), we assume that the electron conducts by hopping along Fe\(^{3+}\) ions in the octahedral sites. In the case of (NiO)\(_{0.75}\)Fe\(_0\)\(_{0.25}\)Fe\(_2\)O\(_3\) we expect that the mobility will be reduced because we do not have similar ions in all of the octahedral sites. If we assume that the mobility of (NiO)\(_{0.75}\)Fe\(_0\)\(_{0.25}\)Fe\(_2\)O\(_3\) is about 1/4 the mobility of Fe\(_3\)O\(_4\) because, on the average, each Fe\(_3\)O\(_4\) molecule will be 3/4 surrounded by Ni0Fe\(_2\)O\(_3\) molecules, and compare the ratio of the conductivities of Fe\(_3\)O\(_4\) and (NiO)\(_{0.75}\)Fe\(_0\)\(_{0.25}\)Fe\(_2\)O\(_3\) using the values of \( n \) obtained from Eqs. (5.5) and (5.6), we obtain at room temperatu
\[
\frac{\sigma(\text{Fe}_3\text{O}_4)}{\sigma[(\text{NiO})_{.75}(\text{FeO})_{.25}(\text{Fe}_2\text{O}_3)\text{]}]} = \frac{1.35 \times 10^{22} e^{-\frac{0.039}{kT}} e_{L \mu_L(T)}}{1.38 \times 10^{22} e^{-\frac{0.078}{kT}} e_{L \frac{1}{4} \mu_L(T)}} = 70.8 \quad (5.7)
\]

The observed ratio of the conductivities at room temperature is 73.5.

(C) \((\text{NiO})_{.56}(\text{ZnO})_{.14}(\text{FeO})_{.30}(\text{Fe}_2\text{O}_3)\)

In the case of \((\text{NiO})_{.56}(\text{ZnO})_{.14}(\text{FeO})_{.30}(\text{Fe}_2\text{O}_3)\), we expect the conductivity to be roughly the same order of magnitude as the conductivity of \((\text{NiO})_{.75}(\text{FeO})_{.25}(\text{Fe}_2\text{O}_3)\) since the number of \(\text{Fe}_3\text{O}_4\) molecules is about the same. The conductivity observed at room temperature, \(\sigma = 6.67\) (ohm-cm)\(^{-1}\), is about a factor of 2 larger than the conductivity of \((\text{NiO})_{.75}(\text{FeO})_{.25}(\text{Fe}_2\text{O}_3)\) at room temperature. We then compare the conductivity of \((\text{NiO})_{.56}(\text{ZnO})_{.14}(\text{FeO})_{.30}(\text{Fe}_2\text{O}_3)\) with the conductivity of \(\text{Fe}_3\text{O}_4\) at room temperature. We obtain \(n\) from Eq. (5.5) assuming that \(n_0\) is equal to the number of \(\text{Fe}_3\text{O}_4\) molecules, and we assume that the mobility is \(3/10\) the mobility of \(\text{Fe}_3\text{O}_4\). Using a value of \(E = 0.066\) electron volts derived from the data of Fig. 5-4, we obtain,

\[
\frac{\sigma(\text{Fe}_3\text{O}_4)}{\sigma[(\text{NiO})_{.56}(\text{ZnO})_{.14}(\text{FeO})_{.30}(\text{Fe}_2\text{O}_3)\text{]}]} = \frac{1.35 \times 10^{22} e^{-\frac{0.039}{kT}} e_{L \mu_L(T)}}{1.38 \times 10^{22} e^{-\frac{0.078}{kT}} e_{L \frac{1}{4} \mu_L(T)}} = 31.4 \quad (5.8)
\]

The observed ratio of the conductivities at room temperature is 37.5.

(D) Concluding Remarks

The conduction mechanism of the metal oxides, of which the ferrites are a special case, is presently not very well understood. The conductivity of most transition metal oxides is very low, \(\sigma < 10^{-7}\) (ohm-cm)\(^{-1}\), in contradiction to the normally expected high conductivity of solids with incompletely filled bands. DeBoer and Verwey [65] and Mott [66] have suggested that these
FIG. 5-4 THE RESISTIVITY AS A FUNCTION OF $T^{-1}$ FOR
$(\text{NiO})_{0.75}(\text{FeO})_{0.25}\text{Fe}_2\text{O}_3$ AND $(\text{NiO})_{0.56}(\text{ZnO})_{0.14}\text{Fe}_2\text{O}_3$
materials be treated in a way deviating fundamentally from the Wilson theory \([67,68]\). They have proposed that a suitable approximation to the state of such a system be obtained by starting with atomic wave functions and forming lattice wave functions analogous to the Heitler-London treatment of molecules. The transport of electricity is then associated with certain excited states of the metal ion.

The usual example of this mechanism is the conductivity of NiO. The Ni ion in the normal state is Ni\(^{2+}\). An excited state giving rise to an electric current would be a state in which two Ni\(^{2+}\) are converted to one Ni\(^{3+}\) and one Ni\(^{+}\). As may be expected, such a mechanism results in a negligibly small current, and the conductivity of pure, stoichiometric NiO is of the order of \(10^{-8}\) (ohm-cm\(^{-1}\)). However, if an excess of oxygen is introduced into the lattice, resulting in metallic deficiencies, then around each missing Ni\(^{2+}\) ion, two Ni\(^{3+}\) ions are created. Under these conditions, when a normal Ni\(^{2+}\) ion is excited to an Ni\(^{3+}\) state plus an electron, and if this electron becomes trapped by an Ni\(^{3+}\) ion in the vicinity of the metal deficit, then the electron deficit may propagate through the crystal. This mechanism can then provide a current as well as an activation energy for the process, which is observed. Thus, the presence of identical ions with different valence in identical lattice sites is seen to be a condition for conduction in this oxide.

In the case of Fe\(_3\)O\(_4\), we have a similar but not identical situation. The presence of Fe\(^{2+}\) and Fe\(^{3+}\) ions in octahedral sites occurs as a consequence of the inverted spinel structure. Under these conditions, we would expect that an electron would be free to wander through the crystal with zero activation energy. Thus the presence of a small but finite activation energy in the region above the transition requires explanation, which has not been forthcoming.

With regard to the conductivity of oxide materials, and Fe\(_3\)O\(_4\) in particular, a few of the pertinent papers should be mentioned. Verwey and Haayman [19] have measured the conductivity of sintered bars of Fe\(_3\)O\(_4\) with deviations from stoichiometry resulting in deficiencies of Fe\(^{2+}\) ions in octahedral sites. Their data indicate that above the transition the conductivity of Fe\(_3\)O\(_4\), unlike that of NiO, decreases with increasing number of deficits,
while the activation energy increases. They have associated the increase of activation energy with an increase of the average energy needed to prevent the electrons from being trapped somewhere in the lattice. They suggest that the octahedral holes act as negative charge centers which tend to surround themselves with Fe$^{3+}$ ions and hence disturb the random distribution of the electrons on the octahedral ions.

This may then suggest that in pure stoichiometric Fe$_3$O$_4$ the activation energy may approach zero. While this is a possibility, it is more than likely that Smilten's crystals contain few octahedral ion deficiencies.

Below the transition, the work of Verwey [69], Verwey and Haayman [19,20] supported by the work of Calhoun [18] has indicated that Fe$_3$O$_4$ is in an ordered state. The activation energy observed below the transition may then be associated with the observed order. One may then speculate upon the existence of short-range order in the region above the transition. However, the order of magnitude of the activation energy below the transition does not agree very well with the energy difference between the ordered and disordered state calculated for an ionic crystal, and no calculations have been carried out above the transition.

Morin [70,71] has made measurements on sintered samples of αFe$_2$O$_3$ and NiO with deviations from stoichiometry. His Hall effect measurements were inconclusive, but he has inferred a value of N* from thermoelectric measurements. The thermoelectric and conductivity data then indicate that an activation energy is to be associated with the mobility. At high temperature, this activation energy tends toward 0.1 electron volts for both the αFe$_2$O$_3$ and NiO samples. He has then suggested that the 0.1 electron volts may be the energy required for the fundamental transfer of an electron from the potential well of one cation to the potential well of the next cation.

It may be proper to associate the observed activation energy of Fe$_3$O$_4$ above the transition with the mobility, but no conclusive arguments for doing this have yet been presented. On the other hand, the association of the activation energy with the carrier density is also without supporting argument and was done to best fit the data. In this respect, the measurements reported in this chapter are inconclusive because they have not been made as a function of temperature.
Jonker and Van Santen [72,73] have made measurements on the system \( \text{La}_{1-x}A_x\text{MnO}_3 \) where \( A \) represents Ca, Sr or Ba. They have attributed the good conductivity observed in a limited range of \( x \) to the transfer of electrons from \( \text{Mn}^{3+} \) to \( \text{Mn}^{4+} \) ions. In discussing these data, Zener [74] also suggests the inappropriateness of describing the electronic states in terms of the customary band representation. However, he notes that in the case of the perovskite structure (LaMnO3), unlike the case of the inverted spinel, the Mn ions are sufficiently far apart so as to have no appreciable overlap of wave functions. He then suggests a double exchange mechanism in which an electron is transferred from a \( \text{Mn}^{3+} \) to an \( 0^{2-} \) ion with the simultaneous transfer of an electron from the \( 0^{2-} \) to the \( \text{Mn}^{4+} \) ion. The double exchange will not, however, provide an activation energy. Its applicability to the case of the inverted spinels has not been established, and it requires a collinear array of \( \text{Fe}^{2+}, 0^{2-}, \text{Fe}^{3+} \) ions which does not occur in the inverted spinel. In this paper, however, Zener makes an interesting suggestion concerning the relationship between the conductivity and the ferromagnetism which is observed for a limited range of \( x \). He suggests that the electron will prefer to exchange if the spins of the \( \text{Mn}^{3+} \) and \( \text{Mn}^{4+} \) ion are in the same direction. Thus the mobility and the conductivity are improved by a ferromagnetic alignment of Mn ions. A linear relation between \( p \) and \( T^{-1} \) is developed.

This effect may account for some of the increase of \( p \) of \( \text{Fe}_3\text{O}_4 \) observed by Smith [75] [see Fig. 6-7] between room temperature and 60\(^\circ\)C below the Curie temperature, and may account for some of the \( T^{3/2} \) dependence observed by Calhoun.

These remarks simply point out the lack of a coherent picture of the conductivity of the metal oxides. The condition of similar ions with different valence in identical lattice sites seems to be a rather general condition for an appreciable conductivity, as has been pointed out by Verwey [76], but even the mechanism by which the electron hops has not been clarified.

While the measurements reported in this chapter shed no light upon the problem of the oxides, they do suggest that the number of electrons
involved in the conductivity of Fe₃O₄ is large. While the possibility that
the observed value of R₀ is small because of partial compensation by
positive carriers is not to be ignored, nevertheless, the low conductivity
of Fe₃O₄ with respect to metals is probably due to a low mobility. The
limited data reported in this chapter and the low conductivity of NiOFe₂O₃
may also suggest that the condition of equivalent ions with different valence
in identical sites is obtained in NiOFe₂O₃ by the addition of Fe₃O₄
molecules.
VI.

THE EXTRAORDINARY HALL MEASUREMENTS ON
Ni, Ni ALLOYS, AND THE FERRITES

6.1 The Experimental Results

Measurements of $R_I$ were made by the field reversal technique described in Chapter II. The voltages measured were for the most part much larger than the ordinary Hall voltages observed for Grade A Ni and the ferrites, and therefore the measurements were considerably easier to perform. For example, the lowest value of voltage observed, in the 499 Alloy at $-195^\circ$C, was of the order of $7 \times 10^{-7}$ volts, and comparable with values of the order of $3 \times 10^{-7}$ volts observed in the Grade A Ni $R_O$ measurements, but at higher temperatures in the case of the 499 Alloy and at all temperatures in the case of the other metals, voltages greater than 1 microvolt and in many cases greater than 10 microvolts were observed. The voltages observed in the $R_I$ measurements on the ferrites were, for the most part, also large voltages for the measuring system.

The value of $R_I$ was deduced from the voltage observed at a point slightly above technical saturation. For example, in Grade A Ni (see Fig. 4-1) the value of $R_I$ at room temperature was deduced from the voltage observed at an applied field of about 7500 oersteds. As indicated in Eq. (2.2), the Hall voltage above technical saturation is given by

$$V_H = (R_I M_s + R_O H) \frac{I}{t}$$  \hspace{1cm} (6.1)

When the ratio $\frac{R_O H}{R_I M_s}$ is small, the error in the approximation

$$V_H \approx R_I M_s \frac{I}{t}$$  \hspace{1cm} (6.2)

is small, and the value of $R_I$ may be calculated from Eq. (6.2) with measured values of $I$, $t$, and $M_s$.

In this research, values of $M_s$ were not measured. The values of $M_s$ for 499 Alloy and Grade A Ni were obtained from the known value of
M₀, the saturation magnetization at 0°C K [ref 12, p. 270], and a universal curve of \( \frac{M_s}{M_0} \) vs \( \frac{T}{T_C} \) obtained from Jan's [11] data. The Curie temperature, \( T_C \), was obtained, for the 499 Alloy, the Grade A Ni, and the other metal samples, from the observed resistivity-versus-temperature data, in the manner shown in Fig. 6-1. The value of \( M_0 \) for R-63 Alloy was deduced from data presented by Bozorth [ref 12, p. 317] which indicated a linear increase of \( M_0 \) for small concentration of Mn in Ni, with a value about 10 per cent larger than Ni suggested for R-63 Alloy (95 Ni, 4 Mn, 1 Si). This value was in reasonable agreement with the value deduced from the Vₜₜ curve of this alloy. The temperature dependence of \( M_s \) was obtained from the \( \frac{M_s}{M_0} \) vs \( \frac{T}{T_C} \) curve for Ni. The values of \( M_s \) at room temperature for Supermalloy and Mumetal were obtained from Bozorth [ref 12, p.870] and the value of \( M_s \) at room temperature for Carpenter Hymu 80 was obtained from the Carpenter Steel Company. The temperature dependence of \( M_s \) for these alloys was obtained from the universal curve for Ni.

Since the curves of \( \frac{M_s}{M_0} \) vs \( \frac{T}{T_C} \) for Ni and Fe are very nearly coincident for small values of \( \frac{T}{T_C} \), this procedure probably introduces small error in the values of \( M_s \) between liquid-air temperature and room temperature (\( \frac{T}{T_C} < 0.4 \)). Both the value of \( M_0 \) and the values of \( M_s \) for \( Fe_3O_4 \) were obtained from Pauthenet's [77] data on a natural crystal. In the case of \( (NiO)_7(FeO)_2(Fe_3O_4) \), the value of \( M_0 \) was obtained from the sum of \( \frac{1}{4} \) of the value of \( M_0 \) for \( Fe_3O_4 \) and \( \frac{3}{4} \) of the value of \( M_0 \) for \( Ni0Fe_2O_3 \), both taken from Pauthenet's [77] data. This procedure is somewhat justified by the fact that the net magnetization of the ferrites can be accounted for by the spin of the bivalent metal ion plus a small addition due to orbital contributions (i.e., g-factor greater than 2), or due to failure of some of the bivalent ions to be situated in octahedral sites [78]. In the case of both \( NiFe_2O_3 \) and \( Fe_3O_4 \), the departure of the observed Bohr magneton value from the spin only value of the bivalent ion is small and can be roughly accounted for by the g-factor. Therefore, it is reasonable to assume that in \( (NiO)_75(FeO)_25(Fe_3O_4) \) the effective Bohr magneton value may be deduced from the sum of \( \frac{3}{4} \) of the observed Bohr magneton number of \( Ni0Fe_2O_3 \) and \( \frac{1}{4} \) of the observed Bohr magneton number of \( Fe_3O_4 \). The value of \( M_0 \) for \( (NiO)_75(FeO)_25(Fe_3O_4) \) obtained from the \( M_0 \) values of \( Ni0Fe_2O_3 \) and \( Fe_3O_4 \) is essentially equal to the value deduced
Fig. 6-1 The method of determining the Curie temperature for Grade A Ni

Driver Harris Grade A Ni

$T_C = 360^\circ C$
from the composite Bohr magneton number for the material \((\beta = 2.689)\). The temperature dependence of \(M_s\) for this sample was deduced from a calculated curve of \(\frac{M_s}{M_0} vs \frac{T}{T_c}\) using \(\frac{3}{4}\) of the value of \(M_s\) for Ni0Fe\(_2\)O\(_3\) and \(\frac{1}{4}\) of the value of \(M_s\) for Fe\(_3\)O\(_4\). This procedure is probably not justified since the exchange interactions which determine the temperature dependence probably do not average in this manner. The value of \(T_c\) used was the value for Ni0Fe\(_2\)O\(_3\), but it is noted that \(T_c\) for Fe\(_3\)O\(_4\) lies within 25°C of \(T_c\) for Ni0Fe\(_2\)O\(_3\). Since the \((\text{Ni0})\_{\text{75}}(\text{Fe0})\_{\text{25}}(\text{Fe}^\text{2+3})\) sample is mostly Ni0Fe\(_2\)O\(_3\), it is reasonable to assume that the true \(\frac{M_s}{M_0} vs \frac{T}{T_c}\) curve for this sample lies close to that for Ni0Fe\(_2\)O\(_3\) and is probably displaced in the direction of the universal curve for Fe\(_3\)O\(_4\). Thus, in the absence of apparatus for measuring \(M_s\), the above procedure was used. Therefore, with the exception of \((\text{Ni0})\_{\text{75}}(\text{Fe0})\_{\text{25}}(\text{Fe}^\text{2+3})\), for which case the uncertainty cannot be estimated, the errors in \(M_s\) are estimated to be small.

In the case of the low temperature \(R_1\) measurements on the metals, the ratio \(\frac{R_oH}{R_1M_s}\) was not small, and corrections have been applied by calculating the H field inside the sample from the value of the applied magnetic field and the demagnetizing factor of the sample. In addition to this correction, where \(R_1\) is small, the effective field acting on the conduction electrons must be taken into account in order to compare the observed results with the Karplus-Luttinger theory. As indicated in Eq. (1.7), the Hall voltage above technical saturation may be written

\[
V_H = \left\{ R_o[H + 2\pi(1 + p)M_s] + R_1M_s \right\} \frac{I}{I} \quad (6.3)
\]

where \(H + 2\pi(1 + p)M_s\) is the effective field acting on the conduction electrons, and \(p\) has been estimated by Wannier [14] to be very nearly equal to zero. \(R_1\) is the quantity calculated by Karplus and Luttinger [13]. In those cases where \(R_oH/M_s\) and \(2\pi R_o\) were not small compared with \(R_1\), \(R_1\) has been deduced from the relation

\[
R_1 = R_1 - \frac{R_oH}{M_s} - 2\pi R_o \quad (6.4)
\]

(A) The measurements on Grade A Ni, 499 Alloy, R-63 Alloy, Supermalloy, Mumetal, and Carpenter Hymu 80

\(R_1\) measurements on Grade A Ni above room temperature were made simultaneously with the \(R_o\) measurements. The behavior of \(R_1\) in Grade A...
Ni was sufficiently different from the behavior of $R_1$ in Ni observed by Jan[11], that it seemed worthwhile, in view of the $R_1$ dependence upon $\rho$ suggested by the Karplus-Luttinger theory, to explore the dependence of $R_1$ upon impurity and hence upon resistivity in a small region near pure Ni. Of the several commercial samples available, most possessed a liquid air temperature resistivity fairly close to that of Grade A Ni and hence were not investigated. The resistivities of Driver-Harris 499 Alloy (99.9 Ni) and R-63 Alloy (95 Ni, 4 Mn, 1 Si) were respectively three times smaller and six times larger than the resistivity of Grade A Ni (99.4 Ni) at liquid air temperature. The $\rho$, T curves of these alloys between liquid air temperature and temperatures slightly above their Curie temperatures are shown in Fig. 6-2. Thus, measurements were made on Driver-Harris 499 Alloy and R-63 Alloy from liquid air temperature to temperatures near their Curie temperatures, and measurements on Grade A Ni were extended from room temperature down to liquid air temperature. Figure 6-3 compares the values of $R_1'$ of 499 Alloy, Grade A Ni, and R-63 Alloy with Jan's data. At liquid air temperature, the absolute values of $R_1'$ for 499 Alloy and Grade A Ni are roughly 1/10 and 1/2 the absolute value of $R_1'$ observed by Jan. On the other hand, the absolute value of $R_1'$ (uncorrected) for R-63 Alloy at liquid air temperature, is about seven times larger than the absolute value of $R_1'$ observed by Jan and roughly 65 times larger than the absolute value of $R_1'$ for 499 Alloy at the same temperature. Thus, the magnitude of $R_1'$ for these materials is significantly different at liquid air temperature. The sign of $R_1'$, however, is negative in all of these materials. With increase of temperature, the magnitude of $R_1'$ increases to temperatures near the Curie temperature. At about 140\(^o\)C, the magnitude of $R_1'$ of 499 Alloy and Grade A Ni is roughly the same as that observed by Jan, but only about 1/2 the absolute value of $R_1$ for R-63 Alloy. The difference in the behavior of Grade A Ni and Jan's data in the vicinity of 300\(^o\)C may be due in part to the uncertainty in the determination of $M_s$ in this region. Thus, over most of the observed temperature range, the absolute values of $R_1'$ for these materials are significantly different. These data, listed in Tables 6-1, 6-2 and 6-3 will be compared with the resistivity data in Section 6.2.

While the number of ferromagnetic metals and alloys on which to test the Karplus-Luttinger theory was essentially unlimited, the equipment
FIG. 6-2 THE RESISTIVITY OF 499 ALLOY, GRADE A Ni AND R-63 ALLOY AS A FUNCTION OF TEMPERATURE BETWEEN LIQUID AIR TEMPERATURE AND TEMPERATURES ABOVE THEIR CURIE TEMPERATURES, COMPARED WITH JAN'S DATA.
FIG. 6-3 $R'_1$ OF 499 ALLOY, GRADE A Ni AND R-63 ALLOY AS A FUNCTION OF TEMPERATURE BETWEEN LIQUID AIR TEMPERATURE AND TEMPERATURES NEAR THEIR CURIE TEMPERATURES, COMPARED WITH JAN'S DATA.
### TABLE 6-1

VALUES OF $M_s$, $R_1$, $R_1'$, $\rho$, AND $r$ AS A FUNCTION OF TEMPERATURE FOR GRADE A Ni

<table>
<thead>
<tr>
<th>T °K</th>
<th>$M_s$ gauss</th>
<th>$-R_1$ volt-cm $\times 10^{12}$</th>
<th>$-R_1'$ volt-cm $\times 10^{12}$</th>
<th>$\rho$ ohm-cm</th>
<th>$r$ (ohm-cm)$^{-1}$ gauss</th>
</tr>
</thead>
<tbody>
<tr>
<td>73</td>
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<td>21.3</td>
<td>15.4</td>
<td>2.08</td>
<td>3.56</td>
</tr>
<tr>
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<td>24.9</td>
<td>19.0</td>
<td>2.52</td>
<td>2.99</td>
</tr>
<tr>
<td>113</td>
<td>503.7</td>
<td>29.8</td>
<td>23.9</td>
<td>2.97</td>
<td>2.71</td>
</tr>
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<td>29.9</td>
<td>3.44</td>
<td>2.53</td>
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<td>36.9</td>
<td>3.97</td>
<td>2.34</td>
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<td>45.2</td>
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<tr>
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<td>60.4</td>
<td>54.8</td>
<td>5.12</td>
<td>2.09</td>
</tr>
<tr>
<td>213</td>
<td>493.0</td>
<td>70.9</td>
<td>65.3</td>
<td>5.75</td>
<td>1.97</td>
</tr>
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<td>233</td>
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<td>76.5</td>
<td>6.42</td>
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<tr>
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<td>89.3</td>
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<td>273</td>
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</tr>
<tr>
<td>293</td>
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<td>123.</td>
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<td>1.59</td>
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<tr>
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<td>139.</td>
<td>134.</td>
<td>9.39</td>
<td>1.52</td>
</tr>
<tr>
<td>333</td>
<td>464.5</td>
<td>157.</td>
<td>152.</td>
<td>10.3</td>
<td>1.43</td>
</tr>
<tr>
<td>353</td>
<td>457.4</td>
<td>177.</td>
<td>172.</td>
<td>11.1</td>
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</tr>
<tr>
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<td>193.</td>
<td>12.1</td>
<td>1.32</td>
</tr>
<tr>
<td>393</td>
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<td>221.</td>
<td>216.</td>
<td>13.0</td>
<td>1.28</td>
</tr>
<tr>
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<td>247.</td>
<td>241.</td>
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</tr>
<tr>
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<td>266.</td>
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<tr>
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</tr>
<tr>
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<td>414.</td>
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<td>1.02</td>
</tr>
<tr>
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<td>469.</td>
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<td>560.</td>
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<td>606.</td>
<td>601.</td>
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<tr>
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<td>178.1</td>
<td>709.</td>
<td>704.</td>
<td>28.3</td>
<td>0.875</td>
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</tbody>
</table>

$T_c = 631^\circ K$

$M_o = 508.8$ gauss

$R_1' = R_1 - R_o \left(2\pi + \frac{H}{M_s}\right)$

$r = \frac{R_1'}{2\rho} \left(\text{ohm-cm}\right)^{-1} \text{gauss}$
### TABLE 6-2
VALUES OF $M_s$, $R_1$, $R'_1$, $\rho$, AND $r$ AS A FUNCTION OF TEMPERATURE FOR 499 ALLOY

<table>
<thead>
<tr>
<th>$T$ (K)</th>
<th>$M_s$ (gauss)</th>
<th>$-R_1$ (volt-cm/amp-gauss)</th>
<th>$-R'_1$ (volt-cm/amp-gauss)</th>
<th>$\rho$ (ohm-cm)</th>
<th>$r$ (ohm-cm)$^{-1}$/gauss</th>
</tr>
</thead>
<tbody>
<tr>
<td>73</td>
<td>506.3</td>
<td>8.97</td>
<td>3.01</td>
<td>0.65</td>
<td>7.12</td>
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<td>4.38</td>
<td>0.88</td>
<td>5.66</td>
</tr>
<tr>
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<td>6.27</td>
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<td>1.88</td>
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<td>19.2</td>
<td>1.14</td>
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$T_c = 631^0K$

$M_o = 508.8$ gauss

$R'_1 = R_1 - R_o \left(2\pi + \frac{H}{M_o}\right)$

$r = \frac{R'_1}{\rho} \left(\frac{\text{ohm-cm}}{\text{gauss}}\right)^{-1}$
<table>
<thead>
<tr>
<th>T (°K)</th>
<th>$M_s$ (gauss)</th>
<th>$-R_1$ (volt-cm/amp-gauss x $10^{10}$)</th>
<th>$\rho$ (ohm-cm $x 10^6$)</th>
<th>$-r$ (gauss/(ohm-cm)$^{-1}$)</th>
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</thead>
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<td>1.95</td>
<td>12.1</td>
<td>1.34</td>
</tr>
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<td>12.6</td>
<td>1.33</td>
</tr>
<tr>
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<td>2.29</td>
<td>13.2</td>
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$T_c = 519^\circ K$

$M_o = 552$ gauss

$r = \frac{R_1}{\rho} (\text{ohm-cm})^{-1}$
imposed certain limitations upon the choice of samples. The magnet gap for low-temperature measurements was limited to two inches because of the size of the dewar, and thus samples with a magnetic induction less than 9000 gauss were required. Because the voltages measured were proportional to the current density, thin samples were needed in order to obtain reasonable voltages with the available current supply. The inherent difficulties in alloying and rolling suitable samples called for the use of commercially available products or those available from other laboratories. Thus it was decided to make measurements on some of the high-permeability Ni-Fe alloys with about 80 per cent Ni content because they fulfilled the above requirements and because it was of interest to observe the behavior of \( R_1 \) in alloys in which \( \rho \) was an insensitive function of temperature. As is well known, the resistivity of an alloy is composed of two parts; a residual resistance which is temperature independent and a temperature-dependent part. If the residual resistance, which increases with increase of alloying constituent, is large compared with the temperature-dependent part, then the total resistivity has a fairly insensitive temperature dependence. The resistivity data of the 80 per cent Ni-Fe alloys, Supermalloy, Mumetal, and Carpenter Hymu 80, as a function of temperature between liquid air temperature and temperatures above their Curie temperatures, are shown in Fig. 6-4. Between liquid air temperature and room temperature, the resistivities of these alloys increase by less than 25 per cent compared with changes by factors of 10, 4, and 2 for 499 Alloy, Grade A Ni, and R-63 Alloy, over the same temperature range.

Figure 6-5 shows both the observed values of \( R_1 \) and the corrected values of \( R'_1 \) as a function of temperature, between liquid air temperature and room temperature, for these alloys. The corrections were made using a value of \( R'_0 \) obtained by Foner [79] on 75 Ni - 25 Fe, and therefore may be in error. The values of \( R'_1 \) observed for the 80 per cent Ni-Fe alloys are roughly the same order of magnitude as the value observed for Grade A Ni at room temperature. However, \( R'_1 \) in these alloys is positive, in contrast with the negative values of \( R'_1 \) observed in the high-concentration Ni alloys. The values of \( R'_1 \) increase by less than a factor of 2 from liquid air temperature to room temperature compared with increases by about a factor of 2.
for the R-63 Alloy, and by factors of about 7 and 15 for the Grade A Ni and 499 Alloy over the same temperature range. These data are listed in Tables 6-4, 6-5, and 6-6.

(B) The Measurements on Fe$_3$O$_4$ and (NiO)$_{0.75}$(FeO)$_{0.25}$(Fe$_2$O$_3$)

As suggested in Chapter I, it was significant to observe the behavior of $R_1$ in Fe$_3$O$_4$ because of the $R_1$ dependence upon $\rho$ suggested by the Karplus-Luttinger theory. The resistivity of Fe$_3$O$_4$ is strongly temperature dependent below room temperature, and at the transition temperature, $T = -153.8^\circ$C, there is a 100-fold increase of resistivity. Figure 6-6 shows the resistivity of Fe$_3$O$_4$ as a function of $T^{-1}$. The low-temperature data were obtained from Calhoun [18] and the high-temperature data are due to D. O. Smith [75]. Since the ratio $R_1/R_0$ is large in Fe$_3$O$_4$, neither the $R_0H/M_s$ nor the $2\pi R_0$ correction is significant and the observed values of $R_1$ are reported. Figure 6-7 shows $R_1$ as a function of temperature between -140$^\circ$C and 550$^\circ$C. Values of $\rho$ are plotted on the same graph for comparison. $R_1$ at room temperature is negative and in absolute value roughly 300 times larger than the absolute values observed for both Grade A Ni and 499 Alloy at room temperature. Above room temperature, $R_1$ decreases in absolute value with increasing temperature and passes through zero at about 380$^\circ$C. The sign of $R_1$ above 380$^\circ$C is positive. Below room temperature, the value of $R_1$ is essentially constant between 0$^\circ$C and -60$^\circ$C and increases in absolute value with decrease of temperature between -60$^\circ$C and -140$^\circ$C. The solid data points of Fig. 6-7 were obtained on another sample of Fe$_3$O$_4$ from the same melt, which was somewhat less homogeneous electrically because of grain boundaries. Between -140$^\circ$C and liquid oxygen temperature (-183$^\circ$C), the absolute value of $R_1$ increases by about a factor of 500 while the resistivity increases by about a factor of 10$^5$. Between liquid oxygen and liquid air temperatures, $R_1$ remains essentially constant while the resistivity increases by a factor of 7.

In the case of the measurements on (NiO)$_{0.75}$(FeO)$_{0.25}$(Fe$_2$O$_3$), the corrections are not important and the observed values of $R_1$ are reported. Figure 6-8 shows $R_1$ for (NiO)$_{0.75}$(FeO)$_{0.25}$(Fe$_2$O$_3$) as a function of temperature between -100$^\circ$C and 580$^\circ$C. At room temperature $R_1$ is negative and 5 times
Fig. 6-5 The observed values of $R_1$ and the corrected values of $R'_1$ as a function of temperature for Supermalloy, Carpenter Hymu 80, and Mumetal.
TABLE 6-4
VALUES OF $M_s$, $R_1$, $R_1'$, $\rho$, AND $r$ AS A FUNCTION
OF TEMPERATURE FOR SUPERMALLOY

<table>
<thead>
<tr>
<th>$T^oK$</th>
<th>$M_s$ gauss</th>
<th>$R_1^{\text{volt-cm}}$ $^{\text{amp-gauss}}$ $\times 10^{11}$</th>
<th>$R_1'^{\text{volt-cm}}$ $^{\text{amp-gauss}}$ $\times 10^{11}$</th>
<th>$\rho^{\text{ohm-cm}}$</th>
<th>$r^{(\text{ohm-cm})^{-1}}$ $^{\text{gauss}}$</th>
</tr>
</thead>
<tbody>
<tr>
<td>73</td>
<td>659.1</td>
<td>5.63</td>
<td>6.98</td>
<td>5.20</td>
<td>2.58</td>
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$T_c = 723^0K$

$M_o = 661.8$ gauss

$R_1 = R_1 - R_o \left(2\pi + \frac{H}{M_s}\right)$

$R_o = -18.7 \times 10^{-13}$ volt-cm $^{\text{amp-oersted}}$

$r = \frac{R_1}{\rho^2}$ $^{(\text{ohm-cm})^{-1}}$ $^{\text{gauss}}$
TABLE 6-5

VALUES OF $M_s$, $R_1$, $R_1'$, and $\rho$, AND $r$ AS A FUNCTION OF TEMPERATURE FOR MUMETAL

<table>
<thead>
<tr>
<th>$T\degree K$</th>
<th>$M_s$</th>
<th>$R_1$</th>
<th>$R_1'$</th>
<th>$\rho$</th>
<th>$r$</th>
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<td>volt-cm</td>
<td>volt-cm</td>
<td>ohm-cm</td>
<td>(ohm-cm)$^{-1}$</td>
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<td>$X10^{10}$</td>
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<td>6.23</td>
<td>9.43</td>
</tr>
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$T_c = 725\degree K$

$M_o = 545.1$ gauss

$R_1' = R_1 - R_0 \left(2\pi + \frac{H}{M_s}\right)$

$R_0 = -18.7 \times 10^{-13}$ volt-cm/amp-oersted

$r = \frac{R_1'}{\rho^2} (\text{ohm-cm})^{-1} \text{gauss}$
TABLE 6-6
VALUES OF $M_s$, $R_1$, $R'_1$, $\rho$, AND $r$ AS A FUNCTION
OF TEMPERATURE FOR CARPENTER HYMU 80

| $T$ °K | $M_s$ gauss | $R_1$ volt-cm$^{10}$ | $R'_1$ volt-cm$^{10}$ | $\rho$ ohm-cm$^5$ | $r$ (ohm-cm)$^{-1}$ gauss
<table>
<thead>
<tr>
<th></th>
<th></th>
<th></th>
<th></th>
<th></th>
<th></th>
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</thead>
<tbody>
<tr>
<td>73</td>
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<td>1.24</td>
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</tr>
<tr>
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<td>1.13</td>
<td>1.28</td>
<td>8.07</td>
<td>1.97</td>
</tr>
<tr>
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<td>1.17</td>
<td>1.32</td>
<td>8.14</td>
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<td>1.35</td>
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<tr>
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<td>1.24</td>
<td>1.39</td>
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<td>1.47</td>
<td>8.56</td>
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</tr>
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<td>1.64</td>
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<td>1.72</td>
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</table>

$T_c = 743^0$K

$M_o = 635.3$ gauss

$R'_1 = R_1 - R_o \left(2\pi + \frac{H}{M_s}\right)$

$R_o = -18.7 \times 10^{-13}$ volt-cm$^{13}$ amp-oersted

$r = \frac{R'_1 \rho}{\rho^{Z}} (\text{ohm-cm})^{-1}$ gauss
FIG. 6-6 THE RESISTIVITY OF SYNTHETIC SINGLE CRYSTAL Fe₃O₄ AS A FUNCTION OF T⁻¹
larger in absolute value than \( R_1 \) in \( Fe_3O_4 \). \( R_1 \) decreases in absolute value with increase of temperature somewhat in the same manner as \( R_1 \) in \( Fe_3O_4 \) and passes through zero at about 410°C. Above 410°C the sign of \( R_1 \) is positive. From room temperature to -100°C, \( R_1 \) increases in absolute value with decrease of temperature. Values of \( \rho \) over the same range of temperature are plotted in Fig. 6-8 for comparison (Fig. 5-4 shows the plot of log \( \rho \) versus 1/T for this sample). The data for \( Fe_3O_4 \) and \((NiO)_{0.75}(FeO)_{0.25}(FeO_2)\) are listed in Tables 6-7 and 6-8.

6.2 Discussion of the Experimental Results

(A) The Ni and Ni Alloys

As indicated in Chapter I, the Karplus-Luttinger theory suggests that \( R_1 \) is proportional to the square of the resistivity. In order to observe the \( \rho \) dependence of \( R_1 \), values of log \( R_1 \) are plotted as a function of log \( \rho \), and the \( \rho \) dependence is obtained directly from the slope of the curve. The Grade A Ni data indicate a \( \rho^{1.49} \) dependence over most of the observed range. The corrections discussed in Section 6.1 have small effect in the region above \( \rho = 8.88 \times 10^{-6} \) ohm-cm (room temperature), but in the region around \( \rho = 3 \times 10^{-6} \) ohm-cm (liquid-air temperature) the corrections tend to improve the linearity of the log \( R_1 \) versus log \( \rho \) curve. The \( \rho^{1.49} \) dependence of \( R_1 \) observed in Grade A Ni is similar to the \( \rho^{1.46} \) dependence obtained from Jan's data. Figure 6-9 compares the \( R_1, \rho \) data of the Grade A Ni with Jan's data. The departure of Jan's data from linearity at low values of resistivity may be due in part to the failure to apply the \( R_0H/M_s \) correction. While the slopes of the two curves are approximately the same above \( \rho = 8.88 \times 10^{-6} \) ohm-cm, the curve for Grade A Ni lies about 50 per cent higher than the curve for Jan's sample.

Figure 6-9 also shows the \( R_1, \rho \) data for the 499 Alloy. In the region between \( \rho = 6.95 \times 10^{-6} \) ohm-cm (10°C) and \( \rho = 14.12 \times 10^{-6} \) ohm-cm (160°C), \( R_1 \) is proportional to \( \rho^{1.97} \), in good agreement with the Karplus-Luttinger theory. However, between \( \rho = 6.95 \times 10^{-6} \) ohm-cm(10°C) and \( \rho = 3.65 \times 10^{-6} \) ohm-cm (-80°C), \( R_1 \) is proportional to \( \rho^{1.70} \), and between \( \rho = 2.63 \times 10^{-6} \) ohm-cm (-110°C) and \( \rho = 0.65 \times 10^{-6} \) ohm-cm (-200°C), \( R_1 \) is proportional to \( \rho^{1.10} \). In the case of the 499 Alloy, the corrections indicated in Section 6.1 are necessary in order to obtain the \( \rho^{1.97} \) dependence
in the region above \( \rho = 6.95 \times 10^{-6} \) ohm-cm. However, the corrections do not improve the linearity of the data at low values of \( \rho \) although they are in the right direction. Thus the \( R'_1 \) data for the Grade A Ni, the 499 Alloy, and Jan's sample do not exhibit a general \( \rho^2 \) dependence. However, the data over almost three decades of \( R'_1 \) definitely suggest some dependence on \( \rho \), and the wide spread of values of \( R'_1 \) for these materials at liquid air temperature appears to be related to the values of resistivity observed at this temperature.

The \( R'_1, \rho \) data for the R-63 Alloy are also shown in Fig. 6-9, and they suggest a \( \rho^{1.20} \) dependence for \( R'_1 \) (uncorrected) between \( \rho = 13.2 \times 10^{-6} \) ohm-cm (-160°C) and \( \rho = 22.2 \times 10^{-6} \) ohm-cm (30°C). The observed values of \( R'_1 \) have been used in the analysis of these data because the value of \( R_0 \) was not measured. However, even if the value of \( R_0 \) for R-63 were double the value of \( R_0 \) for Ni, the \( \rho \) dependence would be altered by less than 10 per cent. It is most significant that the liquid air temperature value of \( R'_1 \) for R-63 Alloy which in absolute value is roughly 65 times larger than \( R'_1 \) for the 499 Alloy and roughly 13 times larger than \( R'_1 \) for Grade A Ni at the same temperature is equal to the value of \( R'_1 \) for these materials at \( \rho = 12.1 \times 10^{-6} \) ohm-cm. Thus, the large values of \( R'_1 \) observed at low temperatures for R-63 Alloy appear to be a consequence of the high resistivity of this alloy at low temperatures. Moreover, the relatively small increase of \( R'_1 \) in R-63 over the observed range of temperature is in marked contrast to the large variation observed in the 499 Alloy, yet, both are correlated with the temperature variation of their resistivities.

It is noted that \( R'_1 \) in these materials has been measured with a saturating magnetic field and compared with the resistivity measured at zero magnetic field. In no case, however, will the magneto-resistance alter the \( \rho \) dependence of \( R'_1 \) by more than a few per cent. Thus, it is not at all probable that the deviation from a \( \rho^2 \) dependence in these materials can be attributed to experimental error.

In the Karplus-Luttinger theory, the predicted \( \rho^2 \) dependence of \( R'_1 \) comes about because the physical mechanism leads to a quantity \( r = \frac{J_y E_y}{E_x M} \) whereas the conventional Hall measuring technique gives \( R'_1 = \frac{J_x M}{J_x M} \). Strict \( \rho^2 \) dependence would thus imply a value of \( r \) which is temperature
### Table 6-7

**VALUES OF $M_s$, $R_1$, $\rho$, AND $r$ AS A FUNCTION OF TEMPERATURE FOR Fe$_3$O$_4$**

<table>
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<tr>
<th>$^0$K</th>
<th>$M_s$ (gauss)</th>
<th>$R_1$ (volt-cm/amp-gauss) $\times 10^8$</th>
<th>$\rho$ (ohm-cm) $\times 10^3$</th>
<th>$(\text{ohm-cm})^{-1}$ (gauss) $\times 10^3$</th>
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$T_c = 847^0$K;

$M_o = 510$ gauss;

\[
R_1 (\text{ohm-cm})^{-1} = \frac{r}{\rho^2} \text{ gauss}
\]
# TABLE 6-8
VALUES OF $M_s$, $R_1$, $\rho$, AND $r$ AS A FUNCTION OF TEMPERATURE FOR (NiO)$_{0.75}$(FeO)$_{0.25}$(Fe$_2$O$_3$)

<table>
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<th>T ($^\circ$K)</th>
<th>$M_s$ (gauss)</th>
<th>$R_1$ (volt-cm/amp-gauss) X10$^8$</th>
<th>$\rho$ (ohm-cm)</th>
<th>$r$ ((ohm-cm)$^{-1}$ gauss) X10$^6$</th>
</tr>
</thead>
<tbody>
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<td>-35.6</td>
<td>2.46</td>
<td>-0.059</td>
</tr>
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$T_c = 870^\circ$K

$M_0 = 338$ gauss

$$r = \frac{R_1}{\rho} \left(\frac{\text{ohm-cm}}{\text{gauss}}\right)^{-1}$$
FIG. 6-9 \( R' \) as a function of \( \rho \) for Grade A Ni, 499 alloy and R-63 alloy compared with Jan's data between liquid air temperature and temperatures near their Curie temperatures.
independent. Since \( r \) depends on the manner in which the d levels are populated, it should not be very temperature dependent, especially at low temperatures where the magnetization is nearly constant. However, we cannot make a priori predictions about the behavior of \( r \) without a more detailed knowledge of the d-band structure than is available. Thus, a better test of the theory than a \( \log R'_1 \) vs \( \log \rho \) plot, is a plot of \( r \) as a function of temperature, where \( r = \frac{R'_1}{\rho^2} \). Figure 6-10 compares the values of \( r \) observed for the 499 Alloy, Grade A Ni, and R-63 Alloy with Jan's data. Between liquid air temperature and room temperature \( r \) of 499 Alloy changes by about a factor of 5. However, between room temperature and 240\(^\circ\)C, the magnitude of \( r \) decreases by only 15 per cent. The strong temperature dependence of \( r \) observed at low temperatures in the 499 Alloy (99.9 Ni) appears to decrease with increasing alloy concentration and the R-63 Alloy (95 Ni) indicates a low-temperature behavior similar to that observed at high temperatures. The reason for the observed temperature dependence of \( r \) is at present not clear, especially since most of the variation occurs at low temperatures. Although the largest errors in \( r \) occur at low temperatures, experimental error cannot possibly explain the low-temperature behavior of \( r \).

Figure 6-11 shows the \( \log R'_1 \), \( \log \rho \) data for Supermalloy, Mumetal, and Carpenter Hymu 80 between liquid air temperature and room temperature. The \( \rho \) dependence of \( R'_1 \) is completely different over different portions of the curve for each alloy, and not at all similar for the three alloys. However, because of the very small range of both \( \log R'_1 \) and \( \log \rho \), the slopes of these curves are not very significant and a plot of \( r \) is a much better test of the theory. We note, however, that the magneto-resistance effect may alter the slopes of these curves somewhat, but since the magneto-resistance effect in these alloys is less than 3/4 per cent at liquid air temperature and changes by less than 1/2 per cent between room temperature and liquid air temperature, this effect will not be appreciable. Figure 6-12 compares the values of \( r \) for Mumetal, Carpenter Hymu 80, and Supermalloy between liquid air temperature and room temperature. In the case of Mumetal, \( r \) increases by about 15 per cent between liquid air temperature and room temperature. Over the same temperature range, \( r \) for Carpenter Hymu 80 is constant within 3 per cent. Of these three alloys, only Supermalloy exhibits an appreciable temperatu
dependence, \( r \) increasing by about 50 per cent over the range from liquid air temperature to room temperature. The magnitude of \( r \) which is a more significant measure of the magnitude of the effect is roughly 100 times smaller in these alloys than in the high concentration Ni alloys. With respect to the magnitude of \( r \) it is noted that the magnitude of \( r \) observed in Fe by Jan [11] and more recently in Fe and Fe with 1 per cent to 5 per cent Si concentration, by Kooi [80], is of the order of unity. Thus the magnitude of \( r \) in Fe and Ni does not depart appreciably from unity with alloy concentrations to 5 per cent, but about 20 per cent concentration in Ni reduces \( r \) by a factor of 100. It is noted, however, that this reduction in the magnitude of \( r \) has been observed in a very special case, namely in the case of alloys with a very small magnetic anisotropy, and this reduction of the magnitude of \( r \) may not be general.

(B) The Ferrites

The data of Figure 6-7 suggest very little correlation between \( R_1 \) and \( \rho \) for the Fe\(_{3}\)O\(_4\) sample. Although both the absolute value of \( R_1 \) and \( \rho \) increase with decrease of temperature below \(-100^\circ\)C, \( \rho \) increases more rapidly than \( R_1 \). Above room temperature, \( R_1 \) decreases in absolute value while \( \rho \) increases. The change of sign of \( R_1 \) at \( 380^\circ\)C is also quite unusual. Although both positive and negative values of \( R_1 \) have been observed previously, in only one case, that of 70 Ni - 30 Co, reported by Smit and Volger [81] has a change of sign of \( R_1 \) with temperature been observed. The sign of \( R_1 \) has not been explained by Karplus and Luttinger.

The sign of \( R_1 \) in Fe has been observed to be positive by both Jan [11] and Foner [82], while the sign of \( R_1 \) in Ni has been observed to be negative by many investigators. Foner [82] has reported a positive \( R_1 \) in Co and has observed a transition from a positive \( R_1 \) to a negative \( R_1 \) in the Co-Ni alloy series, with \( R_1 \) passing through zero at about 30 Co - 70 Ni at room temperature. There appears to be no correlation between the sign of \( R_1 \) and the sign of \( R_0 \) in the metals and alloys. For example, although both \( R_1 \) and \( R_0 \) are negative in Ni and positive in Fe, Foner [82] has observed that in Co at room temperature, \( R_1 \) is positive although \( R_0 \) is negative. Similarly, Foner has observed that \( R_1 \) is positive between 70 per cent Ni in Co and 100 per cent Co at room temperature, while \( R_0 \) is negative throughout
FIG. 6-10 COMPARISON OF $r$ AS A FUNCTION OF TEMPERATURE FOR 499 ALLOY, GRADE A Ni, AND R-63 ALLOY WITH JAN'S DATA
Fig. 6-11  \log R_i' as a function of \log \rho for Supermalloy, Mumetal and Carpenter Hymu 80, between liquid air temperature and room temperature.
FIG. 6-12 COMPARISON OF \( r \), AS A FUNCTION OF TEMPERATURE FOR MUMETAL, CARPENTER HYMU 80 AND SUPERALLOY

\[
\frac{\text{Gauss}}{\text{Ohm-Cm}} \times 10^2
\]

\( r \) vs. Temperature (°C)
FIG. 6-13 THE THERMOELECTRIC POWER OF Fe₂O₄ AGAINST Cu AS A FUNCTION OF TEMPERATURE

Q = a + bt
a = 375 μV/°C
b = -0.064 μV/(°C)²
the Ni-Co Alloy series. Smit and Volger [81] have also observed a positive value of $R_I$ and a negative value of $R_O$ in 84 Ni - 16 Fe. In spite of this lack of correlation between the sign of $R_I$ and the sign of $R_O$ in the metals, it was of interest to investigate the sign of the current carrier in Fe$_3$O$_4$ through the region in which $R_I$ changes sign. Because the ordinary Hall measurement on Fe$_3$O$_4$ above room temperature was difficult to perform, a thermoelectric power measurement was made.

From the sign of the thermoelectric voltage [see 62, p. 119] the sign of the current carrier may be inferred. Figure 6-13 shows the thermoelectric power of Fe$_3$O$_4$ against Cu, as a function of temperature. Between room temperature and 430°C, these data indicate that the sign of the carrier is negative. Thus, the sign reversal of $R_I$ in Fe$_3$O$_4$ does not seem to be related to the sign of the current carrier in Fe$_3$O$_4$. It is also noted, that the sign reversal of $R_I$ for Fe$_3$O$_4$ occurs at high temperature, and while a change of sign of the anisotropy constant has been reported [83] at -143°C, no anisotropy measurements have been reported above room temperature.

The values of $r$ for Fe$_3$O$_4$ as a function of temperature between -140°C and 550°C are shown in Fig. 6-14. Above room temperature, $r$ exhibits a temperature dependence not too different from that shown by $R_I$ in Fig. 6-7. It is noted that although $\rho$ increases above room temperature, the increase is only about 25 per cent. Below room temperature, however, the data indicate that the magnitude of $r$ decreases with decrease of temperature unlike the behavior of $R_I$. Thus, if the general features of the Karplus-Luttinger theory apply to the ferrites, the large effect observed below room temperature is to be attributed to the large resistivity in this region. At room temperature the magnitude of $r$ is about 1000 times smaller in Fe$_3$O$_4$ than in Ni, although the observed magnitude of $R_I$ is roughly 300 times larger in Fe$_3$O$_4$ than in Ni. At liquid air temperature, about 41°C below the transition, the value of $r$ is roughly $10^{-10}$ times the value observed in Ni.

In the case of (NiO)$_{75}$(FeO)$_{25}$(Fe$_2$O$_3$), the absolute value of $R_I$ and $\rho$ decrease monotonically with increase of temperature [see Fig. 6-8] between -100°C and 410°C. However, the data do not indicate any unique
dependence upon ρ in this temperature range nor over any portion of this
temperature range. $R_1$ goes through zero at about 410°C and increases
between 410°C and 550°C while ρ continues to decrease. Thus, although
the resistivities of Fe$_3$O$_4$ and (NiO)$_{.75}$(FeO)$_{.25}$(Fe$_2$O$_3$) are not similar
over the range -100°C to 500°C, the shapes of their $R_1$, T curves evidence
some similarity.

Figure 6-15 shows the plot of $r$ as a function of temperature between
-100°C and 560°C for the (NiO)$_{.75}$(FeO)$_{.25}$(Fe$_2$O$_3$) sample. Both the
Fe$_3$O$_4$ and the (NiO)$_{.75}$(FeO)$_{.25}$(Fe$_2$O$_3$) data show a peak for negative values
of $r$, although the peak occurs at about 0°C for Fe$_3$O$_4$ and at about 200°C
for (NiO)$_{.75}$(FeO)$_{.25}$(Fe$_2$O$_3$). The absolute value of $r$ decreases below 0°C
for both ferrites. At room temperature, the magnitude of $r$ in (NiO)$_{.75}$(FeO)$_{.25}$(Fe$_2$O$_3$) is roughly 1000 times smaller than the magnitude of $r$ in Fe$_3$O$_4$,
although $R_1$ is 5 times larger in (NiO)$_{.75}$(FeO)$_{.25}$(Fe$_2$O$_3$) than in Fe$_3$O$_4$. The
magnitude of $r$ in (NiO)$_{.75}$(FeO)$_{.25}$(Fe$_2$O$_3$) at room temperature is roughly
10^6 times smaller than $r$ in Ni and Fe.

(C) Concluding Remarks

The large magnitude and unusual temperature dependence of the extra-
ordinary Hall coefficient had been a puzzle for many years. The attempt
to explain the effect by the effective field formulation proved totally un-
satisfactory because magnetic interactions involving the conduction electrons
could explain neither the magnitude nor the temperature dependence of the
observed effect. Therefore, the contribution of the Karplus-Luttinger theory
in pointing out that spin-orbit interactions can produce a current proportional
to the magnetization and, because of the manner in which the effect has been
observed, a voltage proportional to the square of the resistivity, is indeed
significant. While the measurements on the metals and alloys reported
in this chapter do not generally exhibit a $\rho^2$ dependence, they do suggest that
the essential features of the Karplus-Luttinger theory are probably correct.
However, the unusual temperature dependence of $r$ in the 499 Alloy at low
temperatures, and the marked reduction in the magnitude of $r$ in the 80 per
cent Ni - Fe alloys indicate a need for a better understanding of $r$. The
failure of $R_1$ to exhibit a $\rho$ dependence in the ferrites may not indicate that
the general features of the Karplus-Luttinger theory do not apply to these
FIG. 6-14 PLOT OF $r$ AS A FUNCTION OF TEMPERATURE FOR Fe$_3$O$_4$.
materials as much as it points out our present lack of understanding of both $r$ and the electrical properties of the ferrites.

The Karplus-Luttinger theory will probably stimulate new experimental effort toward this problem, because it has considerably simplified the experimental situation. For example, although the voltages measured in observing the extraordinary Hall effect are by no means large voltages, they are for the most part much larger than the voltages observed in the ordinary Hall measurement, and therefore measurements of $R_1$ may now be undertaken on ferromagnetic metals and semiconductors which were previously excluded because of the difficulties in measuring $R_0$ and the requirement of the effective field formulation that both $R_1$ and $R_0$ be measured. It would be of interest to investigate the extraordinary effect as a function of temperature in Co, and in the Ni-Co alloy series, especially in the region around 70 Ni - 30 Co, where the data of Foner [82] and Smit and Volger [81] indicate that both signs of $R_1$ are observed. Measurements made on the binary alloys of Fe, Co, and Ni may help in our understanding the nature of the 3d electrons. In this respect the measurements reported in this chapter do not present a very comprehensive picture because they were not made on binary alloys nor were they spaced throughout an alloy series. It would also be of interest to explore the behavior of $R_1$ in Ni of even greater purity than 499 Alloy and to extend the measurements to alloy concentrations greater than 5 per cent around both Ni and Fe. At the present, there seems to be no obvious suggestion for future work on the ferrites.

Acknowledgment

The author gratefully acknowledges the assistance of Professor Harvey Brooks and other members of the Gordon McKay Laboratory of Applied Science.
APPENDIX A

Discussion of Errors

It is the purpose of this appendix to supplement the discussion of error of Chapter III and to point out some of the inherent difficulties in the measurement of $R_o$ in both Fe$_3$O$_4$ and Ni. However, for a complete and detailed analysis of the errors involved, the reader is referred to the original thesis [84].

A. 1 Errors in the Measurement of $R_o$

In the measurement of the ordinary Hall coefficient, errors arise because of the temperature and magnetic field dependence of the relatively large voltages that are subtracted in order to deduce the value of $R_o$. In Chapter II we have detailed the field-reversal technique of making the ordinary Hall measurement. We first discuss the errors that arise due to the uncertainty in setting the magnetic field.

If we apply a magnetic field, $H_1$ down, to the sample [Fig. 2-4] we obtain a voltage across the Hall probes

$$V(H_1) = IR + IAR(H_1) + R_1M(H_1)I/t + R_oH_1I/t,$$

(A. 1)

where $IR$ is the voltage due to the misalignment of the Hall probes; $IAR(H_1)$ is the magnetoresistance voltage associated with the resistance between the probes; $R_1M(H_1)I/t$ is the extraordinary Hall voltage; and $R_oH_1I/t$ is the ordinary Hall voltage. The field-reversal technique requires that we reverse the field exactly to $H_1$ up. If we reverse the field to the value $H_1 + \Delta H_1$ up, we obtain

$$V(H_1 + \Delta H_1) = IR + IAR(H_1 + \Delta H_1) - R_1M(H_1 + \Delta H_1)I/t - R_o(H_1 + \Delta H_1)I/t$$

(A. 2)

The error voltage, denoted by $\Delta V(H_1)$, is obtained from the difference in absolute value of each term in Eqs. (A.1) and (A.2).

$$\Delta V(H_1) = \left| \frac{\partial}{\partial H_1} V(H_1) \right| \Delta H_1 + \left| R_1 \frac{\partial M}{\partial H} (H_1) \right| \Delta H_1 + \left| R_o \frac{1}{t} \right|,$$

(A. 3)
where
\[ \frac{\partial}{\partial H} \left[ I \Delta R(H_1) \right] \Delta H_1 = I \Delta R(H_1 + \Delta H_1) - I \Delta R(H_1) \] (A. 4)

and
\[ \frac{\partial M}{\partial H}(H_1) = M(H_1 + \Delta H_1) - M(H_1) \] (A. 5)

In the case of Ni at room temperature, the largest contribution to the error voltage arises from the third term with a relatively large contribution from the first term of Eq. (A.3), the magnetoresistance term. In order to keep the uncertainty in the measurement of \( R_o \) to about 1.0 per cent, the uncertainty in the magnetic field must be less than 0.6 per cent.

In the case of \( Fe_3O_4 \) at room temperature, the largest contribution to the error voltage arises from the magnetoresistance term, and requires that the uncertainty in the magnetic field be less than 0.25 per cent at \( H_1 \), in order that the uncertainty in \( R_o \) be less than 1.0 per cent. At \( H_2 \), [Chap. II] the requirement on the field is relaxed to about 0.6 per cent because the magnetoresistance saturates.

The sources of error contributing to the uncertainty, \( \Delta H_1 \), were the resolution of the ammeter used to read the magnet current, the drift of the magnet current due to the long time constant of the magnet and power supply filter, and the failure of the magnet to effect a complete reversal of magnetic field with reversal of current. At \( H_1 \), these errors, treated as random errors plus an error of about 0.5 per cent due to calibration of the magnet, total about 0.92 per cent and at \( H_2 \) they total about 1.08 per cent. In the case of the \( R_o \) measurement of Ni this error results in about 2.3 per cent error in \( R_o \). It is pointed out, however, that repeated observation plus resolution of the \( V_H \) curve of Ni reduces this error considerably. In the case of \( Fe_3O_4 \), these uncertainties in \( H \) result in about 4.1 per cent error in \( R_o \). In the case of \( (NiO)_{0.75}(FeO)_{0.25}(Fe_2O_3) \), the error is somewhat less than 4.0 per cent since the ratio of magnetoresistance voltage to Hall voltage is smaller.

In the case of the \( R_o \) measurements of Ni above room temperature, the error is somewhat less than at room temperature since the magnetoresistance decreases with increasing temperature except in the vicinity of the Curie temperature.
In the case of the 70 Ni-30 Cu measurement at -195°C, the error is about the same as in Ni at room temperature, since the magnetoresistance is about the same.

Above the Curie temperature, the uncertainty in $H$ will introduce error only in the $R_o H$ term which we estimate to be of the order of 1.0 per cent in both Ni and 70 Ni-30 Cu.

In calculating the errors due to temperature variation, we treat the temperature dependence of each of the contributions to the voltage observed across the Hall probes.

$$V(T_1) = I R(T_1) + I \Delta R(T_1) + R_1(T_1)M_s(T_1)I/t + R_0(T_1)H I/t \quad (A. 6)$$

If, during the time of measurement, the temperature shifts to the value $T_1 + \Delta T_1$, the resultant error voltage is given by

$$\Delta V(T_1) = \left| \frac{\partial}{\partial T} IR(T_1) \Delta T_1 \right| + \left| \frac{\partial}{\partial T} [I \Delta R(T_1)] \Delta T_1 \right| + \left| \frac{\partial}{\partial T} [R_1(T_1)M_s(T_1)] I/t \Delta T_1 \right| + \left| \frac{\partial}{\partial T} R_0(T_1) H I/t \Delta T_1 \right| \quad (A. 7)$$

In section 2-2E we have implied that the major contribution to the thermal error arises from the IR drop, the first term in Eq. (A.7). In the case of Ni at room temperature, the IR contribution is about double the contribution from the third term of Eq. (A.7) and the other two terms contribute negligibly. The temperature requirement for the Ni room temperature measurement is about $4 \times 10^{-2} \text{°C}$ for 1.0 per cent uncertainty in $R_o$.

In the case of Fe$_3$O$_4$, the contribution from the IR term is much larger than the contribution from all other terms and requires a temperature stability of the order of $2 \times 10^{-3} \text{°C}$ in order to limit the uncertainty in $R_o$ to 1.0 per cent.

In the case of the Ni room temperature measurement, temperature stability of the order of 0.01°C was maintained and this error was negligible. In the case of Fe$_3$O$_4$, thermal instability caused appreciable difficulty. As indicated in Section 2-2E, the current through the sample was limited to a value which provided good stability and reasonable signal. Care was taken to place the sample jacket in good thermal contact with the water-cooled magnet. Both sample current and magnet water supply were run for periods
of four to eight hours before measurements were made. Since the allowed
temperature variation was so small, even the energy provided the sample by
cycling the magnetic field through a sample hysteresis loop was sufficient
to perturb the equilibrium condition. Therefore, the magnet was cycled at
a rate conforming to the speed employed in the measurement for a period
in excess of five minutes. During this period, the stability of the system was
observed at the output meter. No measurement was made until the sample
evidenced stability within the noise level of the system. In spite of these
precautions, thermal instability probably provides the largest contribution to
the spread of values observed in the $R_0$ measurement of $Fe_3O_4$. However,
since a temperature variation can add uncertainty to $2VH$, [Sect. 2.5] the
error is random and we are justified in averaging.

In the case of the $R_0$ measurements on Ni above room temperature, all
of the contributing effects increase with increase of temperature. Since the
field dependence of $M_s$ makes the measurement uncertain above $200^\circ$C, we are
concerned only with the temperature requirement between room temperature
and $200^\circ$C. In this region, the third term of Eq. (A.7) involving $\frac{\partial}{\partial T}(R_1M_s)$
provides the largest contribution to the error and requires that the temperature
to be held to $0.02^\circ$C. Temperature stabilities of this order of magnitude were
achieved. It is noted that the chromel-alumel thermocouple could easily detect
temperature changes of $0.008^\circ$C.

In the case of the $R_0$ measurement on the 70 Ni-30 Cu alloy at liquid-air
temperature, temperature stability requirements were no worse than in Ni
at room temperature. Therefore, error due to temperature instability is
small, since temperature can be held to better than $0.05^\circ$C at liquid-air
temperature.

We point out one other large source of error in the determination of $R_0$.
In Section 2-2D we have indicated that error will occur in the measurement of
$R_0$ because $M$ is not constant at high fields. In the case of polycrystalline
samples, in the region of fields used in the $R_0$ measurements, we write Eq.(2.32)

$$M = M_s \left(1 - \frac{a}{H} - \frac{8K^2}{105M_s^2(H + \frac{4\pi M_s}{3})^2} + K_0H \right) \quad \text{(A.8)}$$

since the work of Holstein and Primakoff [31] and Néel [28] indicates that $H$
should be replaced by $H + \frac{4\pi M}{3}$ in the second-order term. As previously indicated, $a$ is due to nonmagnetic cavities and inclusions in the sample, and $K$ is the first-order anisotropy constant. In calculating the change of $M$ with $H$ in Ni we have used a value of $a = 1/3$ suggested by Bozorth [12, p. 487]. Since $a$ was not measured, and since it can vary from sample to sample, the choice of this value requires some justification. The $V_H$, $H$ curve of Fig. 4-1 shows the approach to saturation, since the Hall voltage is proportional to $M$ at low fields. The approach to saturation in this curve can be reasonably fitted by the second-order term in $H$ with a value of $K = -59000 \text{ ergs/cm}^3$. It can also be fitted with the first-order term and a value of $a = 20$. Such a value of $a$ is unlikely in the Ni sample used in this measurement, and it is probably reasonable to assume that the curvature in the vicinity of 7000 oersteds [Fig. 4-1] is due to anisotropy and perhaps to some strain, unrelieved by annealing. If $a = 20$, then this effect would result in an additional 8 per cent error at room temperature. If $a = 1/3$, then the important contribution to error comes from the $K_o$ term and is estimated to be about 3 per cent. In the case of $\text{Fe}_3\text{O}_4$, this error may be significantly large and is treated in Appendix B.

In the case of the $R_o$ measurements on Ni above room temperature, the $K_o$ term increases with increase of temperature and renders the measurement indeterminate in the vicinity of the Curie temperature. This effect is seen in the data of Fig. 4-2. At 140°C, the $K_o$ term may introduce an error as large as 5 per cent. An estimated value of $K_o$ at 200°C indicates that an error as large as 10 per cent may be introduced at this temperature.

In the case of the other measurements, these effects are estimated to cause reasonably small error.

A.2 Errors in the Measurement of $R_1$

The analysis of error of Section A. 1, above, is used to determine the error in the measurement of $R_1$. The error voltage introduced by mis-setting the magnetic field during the field reversal, in the $R_1$ measurement, is compared with the voltage $2R_1M_sI/t$, rather than with the voltage $2R_oI/\tau(H_2-H_1)$, from which $R_o$ is deduced. However, at room temperature, the extraordinary Hall voltage is 25 times larger than the ordinary Hall voltage in the case of Ni, and 150 times larger in the case of $\text{Fe}_3\text{O}_4$. 
negligible error in the determination of \( R_1 \) therefore arises from missetting the magnetic field. Even though the contribution from the magnetoresistance term to the error voltage increases with decrease of temperature, in the case of Ni, while the extraordinary Hall voltage decreases, the error in the determination of \( R_1 \) is much less than 1.0 per cent between liquid-air temperature and room temperature. Above room temperature, the contribution from the second term of Eq. (A. 3) increases, but in the region between room temperature and 50°C below the Curie temperature, the total uncertainty in \( R_1 \) from these sources is less than 1.0 per cent.

In the case of the ferrites, the error in \( R_1 \) at room temperature and above, from this source, is also very small except in the vicinity of \( R_1 = 0 \). However, the uncertainties in \( R_1 \) at these temperatures are averaged out by the values measured at temperatures above and below. At temperatures below room temperature, the magnetoresistance effect may contribute as much as 3.0 per cent error in \( R_1 \) of Fe\(_3\)O\(_4\) at -143°C, and probably about the same error in (NiO)\(_{0.75}\)(FeO)\(_{0.25}\)(Fe\(_{0.3}\)) at -100°C.

With respect to thermal contributions to error in the measurement of \( R_1 \), we estimate negligibly small error in both the metals and the ferrites. The error voltages deduced from Eq. (A. 7) are compared with the much larger extraordinary Hall voltage and hence the thermal stability requirement in the measurement of \( R_1 \) is much less than in the case of the \( R_0 \) measurements. Furthermore, measurements of \( R_1 \) required only a single field reversal which was made in a time very short compared to the time elapsed in the measurement of \( R_0 \). Therefore, not only at room temperature, but also over the temperature range observed, temperature variation is estimated to have caused negligible error in all of the metal measurements. For example, in the measurement of 499 Alloy which had the lowest value of \( R_1 \) observed at liquid-air temperature, the requirement for this temperature was 0.3°C stability for a 1.0 per cent error in \( R_1 \). At the highest temperature at which \( R_1 \) was observed in this material, the temperature requirement was 2.0°C at 250°C. We also estimate the error in the \( R_1 \) measurements of the ferrites to be small at all temperatures except in the vicinity of \( R_1 = 0 \). For example, at the lowest temperature at which measurements were made
on $\text{Fe}_3\text{O}_4$, the stability requirement was $0.05^\circ\text{C}$ at $-143^\circ\text{C}$. At the highest temperature, the stability requirement was $1.0^\circ\text{C}$ at $500^\circ\text{C}$. Such temperature stabilities were achieved by the techniques outlined in Chapter III.

One significant source of error in the determination of $R_1$ occurs from the failure to measure $M_s$, in the samples used. In the case of Ni, $M_o$, the saturation magnetization at $0^\circ\text{K}$ is accurately known and therefore the value estimated for both the Grade A Ni and 499 Alloy is in error by less than 1.0 per cent. The value of $M_s$ at other temperatures was deduced from a universal curve of $M_s/M_o$ vs $T/T_c$ which was obtained from Jan's [11] data. A very conservative estimate of error over the range of temperature below $T = 0.9 T_c$, including the error in absolute value of $M_o$, is 1.0 per cent. Above $T = 0.9 T_c$, the determination of $M_s$ is most difficult because of its strong field dependence.

In the case of the values used for the R-63 Alloy (95 Ni, 4 Mn, 1 Si) the uncertainty is somewhat larger. A value of $4\pi M_s$ at room temperature was deduced from the saturation value of applied field in the plot of $V_H$ as a function of applied field for this material. Using the universal curve of $M_s/M_o$ vs $T/T_c$ for Ni, a value of $M_o = 552$ gauss was deduced, or a value about 10 per cent higher than $M_o$ for Ni. Bozorth [see 12, p. 317] indicates that $M_o$ increases linearly for small concentration of Mn in Ni, and at 4 per cent Mn a value about 10 per cent higher than the value for Ni is indicated. Therefore, the value deduced above is probably within 2 per cent of the correct value over the temperature range.

In the case of the 80 per cent Ni - Fe alloys, the value of $M_s$ at room temperature was obtained from the source of the material, probably no better than 5 per cent. Since the curve of $M_s/M_o$ vs $T/T_c$ for Fe lies within 1 per cent of the curve for Ni, over the range of temperature employed, values deduced from the Ni curve probably add no more than 1 per cent to the error in the absolute value of $M_s$. However, we are primarily concerned with the temperature dependence of $R_1$, and error in this determination occurs only
through the error in the temperature dependence of $M_s$ which we estimate to be about 1 per cent.

In the case of $\text{Fe}_3\text{O}_4$, the value of $M_o$ was obtained from the Bohr magneton number given by Pauthenet [77] and the density of the sample. The variation with temperature was obtained from Pauthenet's data, and $M_s$ is estimated to have no more than 2 per cent error over the temperature range.

In the case of $(\text{NiO})_{0.75}(\text{FeO})_{0.25}(\text{Fe}_2\text{O}_3)$, the value of $M_o$ was calculated from 1/4 of the known value of $M_o$ in $\text{Fe}_3\text{O}_4$ and from 3/4 of a calculated value of $M_o$ in $\text{Ni}_0\text{Fe}_2\text{O}_3$. This value agreed within 1.5 per cent of a calculation assuming a composite value of Bohr magneton number and the measured density of $(\text{NiO})_{0.75}(\text{FeO})_{0.25}(\text{Fe}_2\text{O}_3)$. The values used were $M_o(\text{Fe}_3\text{O}_4) = 510$ gauss and $M_o(\text{Ni}_0\text{Fe}_2\text{O}_3) = 281$ gauss, resulting in a value for $(\text{NiO})_{0.75}(\text{FeO})_{0.25}(\text{Fe}_2\text{O}_3)$ of $M_o = 338$ gauss. The temperature dependence of $M_s$ was similarly obtained by calculating a value of $M_s$ at each temperature from Pauthenet's data for $\text{Fe}_3\text{O}_4$ and $\text{Ni}_0\text{Fe}_2\text{O}_3$. Since $\text{Ni}_0\text{Fe}_2\text{O}_3$ and $\text{Fe}_3\text{O}_4$ do not have the same temperature dependence, the value of $M_s$ at temperatures different from $0^\circ$K may have a large but unestimatable error.

Another source of error in the determination of $R_1$ arises from the correction that must be taken into account to subtract out the effect of the internal field acting on the conduction electrons which is probably $H + 2\pi M$ instead of $H$. Some error also occurs due to the fact that the extraordinary Hall voltage is measured somewhat above the saturation bend of the $V_H, H$ curve and hence a small contribution from the ordinary Hall effect is present in the observed voltage. As pointed out in Eq. (1.7) we may write the expression for the Hall voltage as

$$V_H = \left\{ R_o [H + 2\pi(1 + p)M] + R_1 M \right\} I/t \quad (A. 9)$$

where $R_1$ has been calculated by Karplus and Luttinger [13], and $p$ has been estimated by Wannier to be very nearly equal to zero for most conduction electrons. Therefore, if we measure the Hall voltage where $M$ is saturated, and if we assume that saturation is achieved with $H \ll 2\pi M_s$, where $H$ is the field inside the material, then

$$V_H = \left[ R_o 2\pi M_s + R_1 M_s \right] I/t = R_1 M_s I/t \quad (A. 10)$$
and the error in considering $R' \approx R$ is $2\pi R_o/R$. Since this can be a reasonably large error in most of the samples measured, corrections have been applied. Also, as mentioned above, the extraordinary Hall voltage was measured at fields for which $H$ was not very much less than $2\pi M_s$. Therefore, corrections were also made to take this into account. Because of the uncertainty in $R_o$ in those cases where $R_o$ was not measured, because $p$ may be different from zero, and because of the uncertainty in the value of $H$ to be associated with the correction term, error occurs in these corrections. In the case of the 499 Alloy, for which the smallest value of $R_1$ at liquid air temperature was observed, we estimate about 3 per cent error in these corrections. In the case of those samples for which $R_o$ was not measured, estimated values of $R_o$ probably cause less than 3 per cent error.
APPENDIX B

The Change of Magnetization Above Technical Saturation in $\text{Fe}_3\text{O}_4$ And (NiO)$_{.75}$(Fe$\text{O})_{.25}$($\text{Fe}_2\text{O}_3$)

In this appendix, we show that the value of $R_o$ deduced from the ordinary Hall measurement of $\text{Fe}_3\text{O}_4$ may be incorrect. At least three sources can contribute to the change of magnetization above saturation and hence produce a voltage proportional to $R_1$, which is added to the ordinary Hall voltage.

In Eq. (2.32), we have given the expression for the approach to saturation.

$$M = M_s(1 - \frac{a}{H} - \frac{b}{H^2} \ldots) + K_0H$$  \hspace{1cm} (B. 1)

It can be shown that the $K_0$ term is sufficiently small to cause small change of $M$ for fields of the order of 5000 oersteds. We can show that the $\frac{a}{H}$ term contributes a voltage which is probably much less than the observed voltage. However, because the $\frac{b}{H^2}$ term is dependent upon the orientation of external field with respect to the crystal axes, and because the sample used was not a single crystal, but was composed of several large grains, very little can be said about this term except that it may be large. In the following sections we examine the effects of each of the terms of Eq. (B. 1) in the region where the ordinary Hall voltage was measured.

B.1 The $K_0$ Term

The room temperature value of $K_0$ in Ni has been observed by Polley [85] to be $1.5 \times 10^{-4}$ gauss/oersted. A value of $K_0$ of this order of magnitude in $\text{Fe}_3\text{O}_4$ would result in a 25 per cent error in $R_o$.

The usual method of determining $M_s$, at the temperature $T$, is to extrapolate the value of $M$, measured with a magnetometer, and plotted as a function of $\frac{1}{H}$, to infinite fields. Such determinations assume that the first two terms of Eq. (B. 1) describe the material. If the term in $K_0$ is not insignificant, then at high fields we expect a departure from...
linearity. In Fig. B-1, the room temperature data of Weiss and Forrer [86] show this departure in the case of Ni, and indicate a value of $K_o$ in agreement with the value given above. On the other hand, the only high field data for $Fe_3O_4$ reported by Pauthenet [77], has been plotted on a scale which does not clearly show the behavior of $\sigma'$ in the region of high fields. These data are shown in Fig. B-2. However, if the total change of $\sigma'$ over the observed range were due to the $K_o$ term only, then $K_o$ for $Fe_3O_4$ would be about the same order of magnitude as $K_o$ for Ni. However, the term in $a$ probably accounts for much of the change in $\sigma'$ and therefore the magnitude of the effect is probably smaller in $Fe_3O_4$. Therefore, we estimate no more than 10 per cent uncertainty in $R_o$ due to this effect.

B.2 The $a$ Term

The term in $a$ is sample-dependent, and has been related to the number of cavities and nonmagnetic inclusions in the sample. In spite of this dependence, both Pauthenet [77] and Weiss and Forrer [86] have observed values of $a = 17$ for different natural crystals of $Fe_3O_4$. Since the sample used in this research was of much better grade than natural crystals, we expect a smaller value of $a$. To support this argument, we note that if $a = 17$, then the change of $M$ between 1000 and 6000 oersteds, would result in $\Delta M = 7$ gauss and a voltage due to $R_1 \Delta M$ roughly 2.4 times larger than the observed voltage. Hence we may conclude that $a \leq \frac{17}{2.4}$ in this sample. In order to keep the uncertainty in $R_o$ less than 10 per cent, we require that $a$ be less than 0.6.

Since measurements of $M$ involve rather complicated apparatus which was not available, we have resorted to an indirect measurement to establish a rough value of $a$. A transformer was wound on the cylindrical $Fe_3O_4$ sample and an alternating voltage $e_1$ was applied to the primary. The secondary voltage is given by,

$$e_2 = \frac{e_1 j\omega M' Z_2}{(Z_1 + j\omega L_1)(Z_2 + j\omega L_2) + \omega^2 M'^2}$$  \hspace{1cm} (B. 2)

where $Z_1$ is the impedance of the generator plus the resistance of the transformer primary, $Z_2$ is the impedance of the load plus the resistance
Fig. B-1 \( \sigma \) as a function of \( H^{-1} \) for Ni. Data of P. Weiss and R. Forrer.

Fig. B-2 \( \sigma \) as a function of \( H^{-1} \) for Fe\(_3\)O\(_4\). Data of R. Paukenet.
of the transformer secondary, \( L_1 \) and \( L_2 \) are primary and secondary induc-
tances, and \( M' \) is the mutual inductance. \( L_1 \), \( L_2 \), and \( M' \) are related
to the permeability, \( \mu \), by geometric factors. We are interested in
the permeability above technical saturation where \( \mu \) is very nearly
unity. Therefore, if we insert the transformer in a magnetic field applied
along the direction of the magnetic field due to the primary current, then a
change of applied field, \( \Delta H \), produces a change of secondary voltage \( \Delta e_2 \)
due to the change of \( \mu \). Since \( Z_1 \) and \( Z_2 \) have been chosen so that
\[
Z_1 \gg \omega L_1 \\
Z_2 \gg \omega L_2 \\
and \\
Z_1 Z_2 \gg \omega^2 M'^2
\]
the logarithmic derivative of Eq. (B.2) becomes
\[
\frac{1}{e^2} \frac{\Delta e_2}{\Delta H} = \frac{1}{M'} \frac{\Delta M'}{\Delta H} = \frac{1}{\mu} \frac{\Delta \mu}{\Delta H} = \frac{\Delta \mu}{\Delta H}
\]

The permeability, \( \mu \), is given by
\[
\mu = 1 + 4\pi \frac{\delta M}{\delta H}
\]
and
\[
\frac{\partial \mu}{\partial H} = 4\pi \frac{\partial^2 M}{\partial H^2} \approx \frac{\Delta \mu}{\Delta H}
\]
If we insert the second derivative of Eq. (B.1) into this expression, we
obtain
\[
\frac{\Delta \mu}{\Delta H} \sim -8\pi M_s \left( \frac{a}{H^3} + \frac{3b}{H^4} \right)
\]

Figure B-3 shows the observed values of \( \frac{\Delta \mu}{\Delta H} \) as a function of
applied magnetic field. The asymptotic increase of \( \frac{\Delta \mu}{\Delta H} \) at 750 oersteds
indicates that the field inside the material is approximately zero at this
value of applied field. The measurements were made at 1 kc and 3 kc in
order to show that the skin depth did not influence the results. While an
estimate of \( a \) may be obtained from these data, we cannot determine the
value of \( a \) exactly. First, we have not measured a true derivative, and in
fact, above 5000 oersteds, the increment of \( H \) was increased by a factor of
4 in order to observe an output voltage. Also, any departure from exact
alignment of sample axis with the applied field results in a larger value of $\frac{\Delta H}{H}$ because the permeability transverse to the magnetic field is larger than the permeability parallel to the magnetic field. The perpendicular component of the permeability falls off less rapidly than the parallel components and its presence is seen in the data above 2000 oersteds. Thus the value of $a$ may be deduced only between 750 and 1500 oersteds. These data indicate a value of $a \approx 0.2$. Thus the term in $a$ probably introduces less than 10 per cent uncertainty in $R_0$.

B.3 The $\frac{b}{H^2}$ Term

The term in $b$ has been measured for both single crystals and polycrystalline samples and found to be related to the anisotropy constant, $K$. In the case of single crystals,

$$b = \frac{f(\theta, \phi)K^2}{M_s^2} \quad (B.8)$$

where $f(\theta, \phi)$ is a function of the polar angles $\theta, \phi$, describing the direction of the magnetization vector, $M_s$. In the case of polycrystalline samples, the value of $b$ is obtained by averaging $f(\theta, \phi)$ over all possible orientations.

In order to develop the expression for $b$, we consider the anisotropy energy of a cubic crystal defined by a single anisotropy constant and the energy of the system due to the applied field. We exclude the effects of strain which may alter the energy of the system. The anisotropy energy, within an additive constant, is given by

$$E_k = K(a_1^2 a_2^2 + a_1^2 a_3^2 + a_2^2 a_3^2) \quad (B.9)$$

where $a_1, a_2, a_3$, are the direction cosines of the magnetization vector $M_s$ referred to the cube edges. The energy of the magnetization vector $M_s$ in the applied field $H$ is given by

$$E_H = -M_s H \cos \beta \quad (B.10)$$

where $\beta$ is the angle between $M_s$ and $H$. Thus, the total energy is given by

$$E_t = E_k - M_s H \cos \beta \quad (B.11)$$

The equilibrium position of the magnetization vector in the field $H$ is that position which minimizes the total energy. Differentiating Eq. (B.11)
FIG. B-3 $\frac{\Delta \mu}{\Delta H}$ AS A FUNCTION OF APPLIED MAGNETIC FIELD FOR Fe$_3$O$_4$
with respect to \( \beta \) we obtain

\[
\frac{\partial E_t}{\partial \beta} = \frac{\partial E_k}{\partial \beta} + M_s H \sin \beta = 0 \tag{B. 12}
\]

The component of magnetization along the direction of applied field is given by

\[
M = M_s \cos \beta \tag{B. 13}
\]

These expressions apply only for fields which are sufficiently large to insure that the magnetization vector lies initially along the direction of easy magnetization. As the field is increased, the magnetization vector is pulled away from the direction of easy magnetization toward the direction of the applied field. We consider the case where the field is sufficiently large so that the angle \( \beta \) between \( M_s \) and \( H \) is small and we approximate,

\[
\cos \beta \approx 1 - \frac{\beta^2}{2} \tag{B. 14}
\]

\[
\sin \beta \approx \beta
\]

For this condition

\[
M = M_s (1 - \frac{\beta^2}{2}) \tag{B. 15}
\]

and

\[
\sin \beta \approx \beta = \frac{-\frac{\partial E_k}{\partial \beta}}{M_s H} \tag{B. 16}
\]

Therefore,

\[
M = M_s \left( 1 - \frac{1}{2} \left[ \frac{\partial E_k}{\partial \beta} \right] \right)^2 \tag{B. 17}
\]

We thus observe, that in the general case where \( \frac{\partial E_k}{\partial \beta} \neq 0 \) we require an infinite field to completely saturate or to exactly align the magnetization vector parallel to the applied field. There are, however, certain crystal directions for which \( \frac{\partial E_k}{\partial \beta} = 0 \), and along these directions, fields of the order of \( \frac{2K}{M_s} \) are sufficient to saturate. This situation may be alternatively described in the following manner. The field energy, \( E_H \), is altered only to the second order \( (\beta^2) \) by having the magnetization vector slightly divergent from the direction of \( H \). On the other hand, for many crystal directions, the anisotropy energy is altered to the first order \( (\beta) \) by having the magnetization vector lie away from the field direction. Hence, the system can lower its energy by having the magnetization lie along a direction slightly different from
the field direction.

The expression for $E_k$ may be cast into polar coordinates as well as the $\cos \beta$ term. This has been done by Akulov [29] and Gans [30], who have then averaged the resulting expression for $\frac{\partial E_k}{\partial \beta}$ and obtained in the case of polycrystalline material

$$M = M_s \left( 1 - \frac{8K^2}{105M_s^2H^2} \right)$$

(B. 18)

If the $Fe_{30.4}$ sample had been polycrystalline, then the change of $M$ would have been of the order 1 gauss over the region of $H$ used in the measurement, and the resultant voltage would have been about 40 per cent of the total voltage observed. However, the sample cannot be considered polycrystalline because it was composed of several large crystals. This may be seen in Fig. 5-1, which shows a photograph of the sample after etching in HCl.

There are certain directions in the crystal along which the change of $M$, for the fields used, may be of the order of 10 gauss. However, the probability that all of the individual crystals are oriented along such directions is small, and there is undoubtedly some reduction in $\Delta M$ because of interaction between crystals. However, strains in the lattice might tend to worsen the situation. Therefore, there is no a priori reason for excluding a large voltage due to this effect. However, during each series of measurements of the ordinary Hall voltage, measurements were made between 4000 and 6500 oersteds and between 6500 and 9000 oersteds of applied field. These were made as a precaution against voltages due to vibration and voltages due to failure to saturate. However, because the signal-to-noise ratio was reduced by a factor of 2 and because of the spread of values, nothing very precise could be inferred from these observations. However, these observations do exclude the possibility that the voltage dropped to $1/10$ of the value observed between 4000 and 9000 oersteds, and thus, effectively exclude the possibility that the $\frac{a}{H}$ and/or the $\frac{b}{H^2}$ term provides the entire voltage observed. This may be seen by calculating the reduction in $\Delta M$. Since the demagnetizing factor was roughly $2\pi$, the internal field is given by the external field minus $2\pi M_s$, or
3000 gauss. Between 4000 and 9000 oersteds applied, the internal field ranges between 1000 and 6000 oersteds, thus

\[ \Delta M = a \left( \frac{1}{H_1} - \frac{1}{H_2} \right) + b \left( \frac{1}{H_1^2} - \frac{1}{H_2^2} \right) \]  
(B. 19)

\[ \Delta M = .83 a \times 10^{-3} + .97 b \times 10^{-6} \]  
(B. 20)

Between 3500 and 6000 oersteds,

\[ \Delta M = .012 a \times 10^{-3} + .055 b \times 10^{-6} \]  
(B. 21)

Therefore, if the total observed voltage were due to \( R_1 \Delta M \), a reduction by about 10 would have been observed when the field was reduced by a factor of 2. Since this was not observed, the value of \( R_0 \) deduced from the measurement is at least the right order of magnitude, but nothing more precise may be stated.

In the case of \((\text{NiO})_{.75}(\text{FeO})_{.25}(\text{Fe}_2\text{O}_3)\) it was possible to resolve the \( V_{H_1} H \) curve above saturation and thus obtain a fairly good test of the presence of nonlinear terms in \( H \). If the points lying above the curve [Fig. 5–3; at about 9000 oersteds are due to these effects, then the maximum error in \( R_0 \) is less than 20 per cent. However, it is also probable that some of this scatter at 9000 oersteds is due to thermal instability. In this respect we note that the temperature requirement for the \((\text{NiO})_{.75}(\text{FeO})_{.25}(\text{Fe}_2\text{O}_3)\) measurement was roughly the same as that for the \( \text{Fe}_3\text{O}_4 \) measurement.

Therefore, because of the good linearity of the average values both above and below these points, the error in these data due to the \( a \) and \( b \) terms is probably small. However, we cannot estimate the uncertainty in \( R_0 \) due to the \( K_0 \) term. Pauthenet's data suggest that \( K_0 \) for both \( \text{NiOFe}_2\text{O}_3 \) and \( \text{Fe}_3\text{O}_4 \) is probably smaller than \( K_0 \) for Ni. If \( K_0 \) for \((\text{NiO})_{.75}(\text{FeO})_{.25}(\text{Fe}_2\text{O}_3)\) is the same as \( K_0 \) for Ni, then there is about 16 per cent error in \( R_0 \).

However, if we may infer that \( K_0 \) for \((\text{NiO})_{.75}(\text{FeO})_{.25}(\text{Fe}_2\text{O}_3)\) is about the same order of magnitude as \( K_0 \) for \( \text{NiOFe}_2\text{O}_3 \) and \( \text{Fe}_3\text{O}_4 \), then the error is less than 10 per cent.
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Wright-Patterson Air Force Base, Ohio

Commanding General
Rome Air Development Center
Griffiss Air Force Base
Rome, New York

1
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1300 E Street, N. W.
Washington, D. C.

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Assistant Secretary of Defense
(Research and Development
Research and Development Board
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   Massachusetts Institute of Technology
   Cambridge, Massachusetts

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   Massachusetts Institute of Technology
   Document Room
   Research Laboratory of Electronics
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   Austin 12, Texas

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   Department of Electrical Engineering
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   Columbia University
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1 Dr. J. V. N. Granger
   Stanford Research Institute
   Stanford, California

1 Library
   Central Radio Propagation Laboratory
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Professor R. E. Norberg
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St. Louis, Missouri